Icy Dust Grains in the Interstellar Medium:
Their Properties and Impact

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Abstract

The behaviour of atoms and molecules on interstellar dust grain analogue surfaces has been probed with surface science techniques such as reflection-absorption infrared spectroscopy (RAIRS) and temperature programmed desorption (TPD). Chemical systems under investigation include O atoms, O$_2$, CO, H$_2$O and N$_2$O as deposited either on a silica (SiO$_2$) surface representative of an interstellar dust grain or on H$_2$O surfaces.

As H$_2$O is the dominant solid state chemical species in the interstellar medium (ISM) preliminary experiments have been conducted to investigate one of its formation pathways. Such experiments involved bombarding SiO$_2$ or H$_2$O surfaces with O atoms, producing O$_2$ and O$_3$ molecules as determined by RAIRS and TPD.

During the initial stages of H$_2$O growth on dust grains in the ISM, only small quantities will be found in the solid state. The de-wetting behaviour of such quantities was investigated by directly dosing H$_2$O onto the SiO$_2$ surface and observing the νOH vibrational band with time and temperature. Through such experiments, H$_2$O has been observed to de-wet even at cryogenic temperatures of 17 K with an activation energy of about 2 kJ mol$^{-1}$. The effect of this in the ISM is that bare dust grain surfaces will be left exposed for other molecules, such as CO, to interact with. Such interactions may be stronger than those of the molecules directly interacting with a water surface, meaning molecules will reside in the solid state for longer times.

As icy mantles develop throughout the lifetime of a molecular cloud, adsorbed CO becomes a large part of the icy mantle. Multilayers of CO were investigated and shown to exhibit a bulk potential. This charge is due to a spontaneous electric (spontelectric) field arising as certain dipolar molecules align in the solid state. To investigate the spontelectric effect in CO, N$_2$O was first examined and shows a correlation between IR features and the direct measurement of the spontelectric potential of N$_2$O. Such a link was found through the temperature dependent shifts in the LO-TO splitting of the N$_2$O. CO exhibits the same temperature dependence and spontelectric parameters have been extracted to show that a spontelectric potential of 6.7 mV per monolayer is created as multilayers adsorb on a surface. The effect of this in the ISM would be to reduce the gas-phase charge and ionisation fractions in molecular clouds of the ISM which in itself has the potential to have wide-reaching implications.
Acknowledgements

The work that has gone into this thesis, both experimental and written, could not have been done without the help, advice and guidance of many people. Firstly, I would like to express my sincere gratitude to Prof. Martin R. S. McCoustra for the opportunity to experience the world of scientific research. The years have been filled with joys and frustration when the experimental kit either worked perfectly or needed reparations. Whatever the state of the laboratory, Prof. McCoustra was always there with advice and encouragement.

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Table of Contents

Chapter 1 – The Interstellar Medium

1.1 Introduction ........................................................................................................ 2
1.2 Molecular Clouds ............................................................................................... 7
1.3 Sources of Energy .............................................................................................. 10
   1.3.1 Cosmic Rays ................................................................................................ 10
   1.3.2 Photons ........................................................................................................ 11
   1.3.3 Thermal Shocks ......................................................................................... 13
1.4 Astrochemistry .................................................................................................. 13
   1.4.1 Gas-Phase Chemistry ................................................................................ 13
   1.4.2 Dust Grain Core ........................................................................................ 17
   1.4.3 Grain Mantle ............................................................................................. 20
   1.4.4 Chemistry on Dust Grain Surfaces ............................................................. 24
1.5 Thesis Overview ................................................................................................. 26
1.6 References .......................................................................................................... 27

Chapter 2 – Experimental Theory, Equipment and Technique

2.1 Introduction ........................................................................................................ 37
2.2 Surface Science .................................................................................................. 37
2.3 Equipment .......................................................................................................... 40
   2.3.1 Instrumentation .......................................................................................... 40
   2.3.2 Cryostat and Sample ................................................................................. 42
   2.3.3 Silica Deposition ....................................................................................... 44
   2.3.4 Background Deposition ............................................................................ 47
   2.3.5 Atomic Beams ............................................................................................ 48
      2.3.5 (a) Introduction ....................................................................................... 48
      2.3.5 (b) Equipment ......................................................................................... 50
      2.3.5 (c) Beam Flux and Cracking .................................................................. 53
2.4 Experimental Technique ................................................................................... 60
   2.4.1 Temperature Programmed Desorption (TPD) ............................................. 60
2.4.2 Reflection-Absorption Infrared Spectroscopy (RAIRS).......................... 65
2.4.2 (a) Longitudinal Optical–Transverse Optical (LO–TO) Splitting .......... 67
2.5 The Spontaneous Effect........................................................................ 70
2.5 Kinetic Simulations.................................................................................. 74
2.6 References ............................................................................................... 75

Chapter 3 – Oxygen Atom Chemistry................................................................. 79
3.1 Introduction .................................................................................................. 80
3.2 Experimental .............................................................................................. 81
3.3 Results and Discussion............................................................................... 81
3.3.1 O₂ Molecular Beam Dosing ................................................................. 82
3.3.2 O Atoms on Silica................................................................................... 87
3.3.2 (a) Reflection-Absorption Infrared Spectroscopy............................. 87
3.3.2 (b) Temperature Programmed Desorption ......................................... 89
3.3.3 O Atoms on Porous Amorphous Solid Water................................... 92
3.3.3 (a) Reflection-Absorption Infrared Spectroscopy............................. 93
3.3.3 (b) Temperature Programmed Desorption ......................................... 95
3.3.4 O Atoms on Compact Amorphous Solid Water................................ 99
3.3.4 (a) Reflection-Absorption Infrared Spectroscopy............................. 100
3.3.4 (b) Temperature Programmed Desorption ......................................... 100
3.3.5 O Atoms on Crystalline Solid Water................................................ 103
3.3.5 (a) Reflection-Absorption Infrared Spectroscopy............................. 103
3.3.5 (b) Temperature Programmed Desorption ......................................... 104
3.3.6 O₃ Characterisation............................................................................... 105
3.3.7 O₃ Formation and Destruction ........................................................... 108
3.4 Conclusion .................................................................................................. 112
3.5 References ............................................................................................... 114

Chapter 4 – Towards a more Realistic Icy Grain Mantle Model ....................... 117
4.1 Introduction ............................................................................................... 118
4.2 Experimental ............................................................................................. 119
4.3 Results and Discussion ............................................................................. 120
<table>
<thead>
<tr>
<th>Section</th>
<th>Title</th>
<th>Page</th>
</tr>
</thead>
<tbody>
<tr>
<td>4.3.1</td>
<td>H$_2$O de-wetting</td>
<td>120</td>
</tr>
<tr>
<td>4.3.2</td>
<td>O Atom Bombardment of H$_2$O Films</td>
<td>130</td>
</tr>
<tr>
<td>4.4</td>
<td>Astrophysical Implications of H$_2$O De-Wetting</td>
<td>135</td>
</tr>
<tr>
<td>4.5</td>
<td>Conclusion</td>
<td>140</td>
</tr>
<tr>
<td>4.6</td>
<td>References</td>
<td>143</td>
</tr>
</tbody>
</table>

**Chapter 5 – The Spontelectric Effect**

<table>
<thead>
<tr>
<th>Section</th>
<th>Title</th>
<th>Page</th>
</tr>
</thead>
<tbody>
<tr>
<td>5.1</td>
<td>Introduction</td>
<td>148</td>
</tr>
<tr>
<td>5.1.1</td>
<td>The Spontelectric Effect</td>
<td>148</td>
</tr>
<tr>
<td>5.1.3</td>
<td>RAIRS and the Spontelectric Effect</td>
<td>150</td>
</tr>
<tr>
<td>5.2</td>
<td>Experimental</td>
<td>151</td>
</tr>
<tr>
<td>5.3</td>
<td>Results and Discussion</td>
<td>152</td>
</tr>
<tr>
<td>5.3.1</td>
<td>Multilayer N$_2$O Films</td>
<td>152</td>
</tr>
<tr>
<td>5.3.2</td>
<td>Spontelectric CO Films on SiO$_2$</td>
<td>160</td>
</tr>
<tr>
<td>5.3.3</td>
<td>Spontelectric CO on Films H$_2$O</td>
<td>167</td>
</tr>
<tr>
<td>5.4</td>
<td>Modeling RAIRS Data</td>
<td>171</td>
</tr>
<tr>
<td>5.4.1</td>
<td>LO and TO Modes with Dipole Orientation</td>
<td>179</td>
</tr>
<tr>
<td>5.4.2</td>
<td>LO and TO Modes with Temperature</td>
<td>181</td>
</tr>
<tr>
<td>5.4.3</td>
<td>Spontelectric CO Films</td>
<td>183</td>
</tr>
<tr>
<td>5.5</td>
<td>Astrophysical Implications of the Spontelectric Effect</td>
<td>192</td>
</tr>
<tr>
<td>5.6</td>
<td>Conclusion</td>
<td>198</td>
</tr>
<tr>
<td>5.7</td>
<td>References</td>
<td>201</td>
</tr>
</tbody>
</table>

**Chapter 6 – Concluding Remarks and Outlook**

<table>
<thead>
<tr>
<th>Section</th>
<th>Title</th>
<th>Page</th>
</tr>
</thead>
<tbody>
<tr>
<td>6.1</td>
<td>Introduction</td>
<td>206</td>
</tr>
<tr>
<td>6.2</td>
<td>Chapter 3</td>
<td>206</td>
</tr>
<tr>
<td>6.3</td>
<td>Chapter 4</td>
<td>210</td>
</tr>
<tr>
<td>6.4</td>
<td>Chapter 5</td>
<td>212</td>
</tr>
<tr>
<td>6.5</td>
<td>References</td>
<td>215</td>
</tr>
</tbody>
</table>
List of Table Captions

Chapter 1

1.1: The different regions of the ISM with their general temperatures in K, state of hydrogen and the ionization fraction of the atoms/molecules. The density as stated in molecules cm$^{-3}$ concerns the concentration of atomic hydrogen in the first four regions and molecular hydrogen in the mCNM. The last column, $A_V$, is the extinction of light as it travels through the different media. The question marks indicate that the exact value of the magnitude is unknown, but have been assumed to be zero due to the lack of molecules [11, 12].

1.2: This table illustrates the range of molecular complexity as observed in molecular clouds in the ISM. More than 190 different molecules have been observed until this point in time [13–15].

Chapter 2

2.1: Indicating the approximate times taken for a complete monolayer to be formed at a given pressure. In general, this indicates how long a surface remains clean at a certain pressure. The calculations have been done for N$_2$ and times will vary depending on the molecule of interest.

2.2: This table shows the values for the intercept, $\ln(P_0)$, and the gradient, $C_m$, as obtained from the pump–down curves from Figure 2.16.

2.3: O atom transitions with the corresponding emission peak from the spectrometer [16, 22]. The 777 nm transition is the strongest signal with the supplied energy as measured by the fiber optic cable linked to the spectrophotometer.

2.4: This table indicates the different gradients from Figure 2.20. The change in gradient indicates that an increase of about 58% O$_2$ desorption occurs when the plasma source is on and when every other experimental aspect, flux and time, is kept constant.

Chapter 3

3.1: This table shows the IR frequencies composing the O$_3$ band displayed in Figure 3.7 which have been compared to literature values.
3.2: This table shows the result of resolving the components of the O_3 band when fitted with Gaussians and their comparison with literature values.

3.3: This table shows the results of the different limits put onto the CKS model for investigating the O_2 and O_3 formations in columns two and four (labelled O_2:O_3) and O_3 destruction (labelled O_3:O_2) in columns three and five. As can be seen, a greater extent of O_3 is produced than observed in the TPD experiments with negligible destruction.

3.4: This table shows the TPD results of O_2 desorption. The first column of values is of O_2 desorption after having been beam dosed onto the bare SiO_2 sample. The other columns are of O_2 having been dosed with the atomic beam onto the different surfaces.

3.5: This table summarises all the values of the O_3 band from the different surfaces after they have been fitted with Gaussians as compared to the literature values [16].

Chapter 4

4.1: This table shows the areas of the νOH band after the spectra have been baseline corrected and smoothed. The correction of the A_∞ value comes as a result of Figure 4.6.

4.2: This table shows the next step in the analysis using Equation 3. The areas used come from smoothing of the spectra for the 24 K de–wetting experiment.

4.3: This table shows the individual values of the rate constant, k, with respect to its annealing temperature. Plotting the inverse temperature and the ln(k) will lead to the associated energy through Equation 4.

4.4: This table shows the gradients for the linear fits of Figure 4.8a and 4.8b.

4.5: This table reports the activation energy values associated with the de–wetting process of H_2O (rising edge) and the subsequent region (plateau) where isolated H_2O molecules have formed a greater bulk.

4.6: This table has been made to show the difference in the rate constant (k) as the coverage changes in p–ASW films and the film itself is changed to c–ASW and CSW.
Chapter 5

5.1: This table shows the peak positions and the difference in the LO–TO splitting for the annealing data (upper section) and the different deposition temperature data (lower part) from Figures 5.10 and 5.11. Only data at ≥48 K have been included due to the more clearly defined peaks.

5.2: This table produces a more clear sight of the peak shifts of CO as the deposition temperature changes. A contraction is observed which is indicative of a spontelectric material.

5.3: This table shows the peak positions with respect to deposition temperatures for CO on p–ASW, c–ASW and CSW. The data in this table can also be seen in Figure 5.24.

5.4: This table describes the different terms that the models use to relate the experimental RAIRS data to the surface potential measurements for N\textsubscript{2}O and to show the possible extent of the spontelectric effect of solid state CO.

5.5: This data is from the experiment where N\textsubscript{2}O is deposited at different temperatures [19]. The first four columns are the same as seen in the bottom part of Table 5.1.

5.6: This table shows the values as calculated from the model and compared to the observed RAIRS data for N\textsubscript{2}O. Explanations for each column can be found in the text [19].

5.7: This table shows the data used for the modelling of the CO RAIRS data. The first four columns are taken directly from the experiments with the last two being calculated from the experimental data [28].

5.8: This table illustrates the variety of Ω as the deposition temperatures change when calculated through Equation 25 [28].

5.9: This table shows how the values of \( E_S \) (upper and lower values) vary with the deposition temperature as calculated through Equation 24 [28].

5.10: This table shows the values of the degree of dipole orientation as the temperature and spontelectric field vary. The subscripts \( u \) and \( l \) refer to the upper and lower branch as calculated for \( E_S \) [28].

5.11: This table shows the overall result of the spontelectric parameters and the dipole orientation when CO multilayers are deposited onto different types of H\textsubscript{2}O while the deposition temperature is changed. The * marks where the deposition temperature is 21 K which is only the case for the c–ASW experiments [31].
5.12: This table summarises the results obtained through the analysis of the RAIRS data of N\textsubscript{2}O and CO. As can be seen for the CO data, peculiar results are obtained when the substrate is changed as already discussed in the text.

5.13: This table sums up the estimated timescales for a species (electron or proton) to encounter an interstellar dust grain as calculated through Equation 28 [31].

Chapter 6

6.1: This table shows the overall results of all the RAIR spectra of O\textsubscript{3} and the interactions leading to the IR spectra. These values can be compared to literature values as stated in the last column.

6.2: This table shows the full range of TPD results of O\textsubscript{2} desorption from the different surface investigated (SiO\textsubscript{2}, p–ASW, c–ASW and CSW). The main body of the results is of O atomic beam dosing with O\textsubscript{2} molecular beam dosing results shown as a comparison.

6.3: This table shows the calculated values of the spontelectric effect of CO when deposited onto SiO\textsubscript{2}, p–ASW, c–ASW and CSW.
Chapter 1

1.1: These pictures are of a molecular cloud named Barnard 68. The picture to the left shows the cloud as observed through optical based telescopes while the right picture is presented in false colour showing the IR background radiation from the stellar landscape behind the cloud.

1.2: These combined pictures show the life–cycle of an interstellar cloud from birth to destruction and rebirth as mentioned in the text.

1.3: This cartoon shows the ranges of energies as found in the ISM used for reactions. The various sources are highlighted here and discussed in the text. This cartoon is taken and adapted from [25].

1.4: This figure is of the ISRF of a molecular cloud. As can be seen, the flux and energy of UV photons decreases as the extinction factor, $A_v$, increases due to the presence of interstellar dust grains. This figure is taken from [43].

1.5: These two spectra are of interstellar dust grains. Panel (A) [70] shows the various core components of dust grains as being part SiO$_2$, part carbon–based and possible PAHs. Panel (B) [71] shows how the extinction of light due to dust grains change in differing environments, however the general contributions to the profile are still present. This means dust grains are generally made of the same components regardless of location in the ISM.

1.6: This diagram illustrates the formation routes of H$_2$O on a surface such as an interstellar dust grain. This figure is taken from [82].

1.7: This cartoon illustrates a typical interstellar dust grain in the core of a molecular cloud. A mantle of a variety of molecules have adsorbed or accreted onto the silica surface of which H$_2$O is the dominant species. Also illustrated are various energy sources available for reactions, adapted from [92].

1.8: This spectrum is of an icy mantle showing the variety of molecules present. This is a spectrum from the Short Wavelength Spectrometer (SWS) of NGC 7538 IRS9 adapted from [93].

1.9: The Langmuir–Hinshelwood mechanism, illustrating how atoms or molecules adsorb, diffuse, react and desorb on a surface. As can be seen, both species must be present in the surface.
1.10: The Eley–Rideal mechanism illustrating how one gas phase species only interacts with an adsorbed molecule to create a new species. The gas phase molecule does not come into contact with the surface at any point.

1.11: The Harris–Kasemo mechanism can be thought of as one part reverse E–R and one part L–H mechanisms. A molecule breaks apart on the surface creating one fragment with excess energy (B) which can diffuse on or in an ice lattice. This hot atom can then react with other molecules to produce (E).

Chapter 2

2.1: The Propst diagram shows what surface science processes are possible and studied in various fields of physical sciences. The main aspects of interest for this work are; electric fields, heat and neutral species.

2.2: A picture of the UHV rig used for this work and the main experimental aspects labelled with red arrows.

2.3: A detailed sketch of the UHV rig used for this work. The atomic beams have not been shown, but will be detailed later in 2.3.5. The sketch is not to scale.

2.4: A sketch of the entire manipulator with the closed–cycle He cryostat cooling the sample to a minimum base temperature observed for this work of 17 K. The sample has XYZ translations and a virtual 360° rotation.

2.5: The sample itself located at the end of the cryostat. The Cu block is coated with SiO₂ and a cartridge heater selectively heats only the sample block. Two KP–type thermocouples register the temperature throughout experimental work.

2.6: To the left is a schematic of the SiO₂ deposition chamber reaching base pressure of 10⁻⁶ mbar. To the right is a picture of the chamber as viewed from the left side of the rig. The SiO₂ is placed in the path of an electron beam which evaporates it, the sample is positioned directly above the SiO₂ and the rate of deposition is monitored by a QCM.

2.7: Two spectra showing the difference between a clean Cu sample, black, and one with SiO₂, red, deposited onto it. The 1241 cm⁻¹ feature is the LO mode and the 1065 cm⁻¹ is the TO optical mode of SiO₂.

2.8: This shows a simple test to verify if a layer of SiO₂ has been deposited, where droplets of H₂O appear to wet SiO₂ and clusters on Cu. The cloudy material on the
left side of the sample is SiO$_2$ which has not stuck properly to the sample and would not be used in the UHV rig, however for the H$_2$O test this will suffice.

2.9: A diagram showing the connection of the dosing lines to the leak valves of the UHV chamber. The lines are regularly evacuated and a small volume of gas or vapour containing the molecules of interest is expanded into the dosing bulbs for experimental use.

2.10: This graph shows the potential energy diagram of O$_2$ and what energy levels are needed to excite, dissociate and ionise O$_2$. The region labelled l with a red circle is the atoms of interest, O($^3\text{P}$), for this work.

2.11: Grotrian diagram for O showing all the electronic transitions possible. With the plasma source on, the $^5\text{P} \rightarrow ^5\text{S}^0$ transition, labelled as OI IR3 to the left of the diagram, is the strongest.

2.12: A general schematic of the atomic beam sources and their overall construction. The source to the left is for the production of O atoms while the right side is for H atoms (not used in this work). The UHV chamber is as follows from Figure 2.2.

2.13: To the left is a picture of the plasma tube during reconstruction. The white discs, made of alumina so as to minimise O atom recombination after cracking, hold in place the aperture disc. The 5-hole grid in the centre of the aperture disc allows for the O beam to pass. The right picture is of the fully assembled plasma tube.

2.14: A sketch of the entire O atom plasma source. The inductively coupled radio frequency source sparks the O$_2$ gas when enough power is supplied. The air capacitors are to contain and focus as much power as possible towards the molecular gas. A fiber optic cable records the plasma emission in real time by a spectrometer.

2.15: The pump–down curve used to assess the beam flux when for O atom experiments. The rise in the MS counts of m/z = 32 is due to the gate valve, separating the plasma chamber and the central UHV chamber, being opened. The count rate is allowed to stabilise and the red line shows the gate valve being closed and the O$_2$ pumped out of the central UHV chamber. The experiments were done with a room temperature cryostat.

2.16: The result of the pump down curves form Figure 2.15 when the MS counts have been converted to pressure, $P$, and each pumping curve has been set to zero to allow for individual and simple analysis.
2.17: The temperature programmed desorption of O\textsubscript{2} beam dosed onto the sample indicate ML formation between 5 – 10 minutes. The beam flux and nature of the surface have effects of the monolayer formation time.

2.18: This shows the generally obtained spectra of the O atom plasma as monitored through the fiber optic cable linked to the manual tuning unit (see Figure 2.14). The minor peaks correspond to various transitions of O atoms, with a slight contamination of OH, but the strongest signal is observed at 777 nm, corresponding to the \((3p \, ^5P) \rightarrow (3s \, ^5S)\) transition in the O atom.

2.19: The traces here initially indicate only a background of O, m/z = 16, the red trace, and O\textsubscript{2}, m/z = 32, the black trace. As the gate valve between the plasma chamber and the central chamber is opened, a sharp rise in the counts happens. As this plateaus an initial measurement of the fragments monitored by the QMS is made (the blue vertical line). The plasma source is then turned on which cracks O\textsubscript{2} into O (the green vertical line). The source is left to stabilise and reach optimum operational conditions and the cracking fraction of the plasma source can be estimated (the brown vertical line).

2.20: This figure shows the integrated and normalised areas of O\textsubscript{2} TPD traces when dosing the O\textsubscript{2} molecular beam (black data set) and atomic O beam (blue data set) for 1, 2, 5 and 10 minutes. The areas have been normalised through integrated area of the 1 minute TPD traces for the O atom beam and the O\textsubscript{2} molecular beam to allow for comparison between the different experiments. The insert shows the difference in the TPD traces when the atomic beam is off or on.

2.21: This figure show the formation of a TPD trace. Initially molecules are deposited onto a surface of a certain quantity, \(\theta_s\), before the sample is heated. As the sample and the film heat up the coverage decreases as the rate constant, \(k_d\) increases. The point where the two curve intersect is the peak of desorption and the area under this newly created curve, \(\nu_{des}\), is proportional to the amount of species deposited.

2.22: The traces above indicate the ideal desorption behaviours of chemical films deposited onto a surface. The top graph shows zero order kinetics where the leading edges align and a bulk material desorbs. The second graph is of 1\textsuperscript{st} order where all the peaks line up to the same peak temperature of desorption which is expected for sub–monolayer desorption. The bottom graph is of 2\textsuperscript{nd} order desorption where the trailing edges align indicative of recombination of molecules on the surface during desorption.
2.23: A schematic of the electric field vectors on a surface from parallel polarised light (to the left) and perpendicular polarised light (on the right). As can be seen, the electric field is cancelled in the left diagram and enhanced in the right.

2.24: This graph shows how the phase changes as polarised light perpendicular (a) and parallel polarised (b) is incident on a metal surface at a given angle. As can be seen, (b) has a greater phase change as the angle of incidence changes. Figure is adapted from [29].

2.25: The MSSR is important when conducting IR experiments on a pure metal surface. As can be seen, the molecules oriented perpendicular to the surface will have an overall enhanced dipole moment due to the image dipole arising in the metal surface. This effect is cancelled out when the molecules are aligned parallel to the surface.

2.26: RAIRS spectra of the νNN mode of 14 ML N₂O on Cu, blue, 200 nm SiO₂, red, and 300 nm SiO₂, black. As can be seen the TO mode of N₂O is silent when deposited directly on Cu. This mode then activates as it is physically removed from the surface of the Cu by SiO₂ spacers.

2.27: A similar diagram to that describing the MSSR in Figure 2.25. However, a SiO₂ layer has been placed between the metal and the adsorbed dipolar molecular film illustrating how the roughness can circumvent the MSSR.

2.28: This cartoon shows how the LO and TO modes behave in a solid. The LO mode arises as the phonons in the solid interact longitudinally, or along, the electric field when the IR beam hits the surface of the Cu substrate. The TO mode behaves oppositely and interacts transversely with the electric field.

2.29: This figure illustrates the experimental setup in Aarhus for measuring the surface potential of spontelectric molecules. Photo–ionisation of argon gas (S1–3) produces near–zero kinetic energy electrons which are focussed (L1–4) onto the sample [37].

Chapter 3

3.1: This figure indicates a variety of routes of H₂O in the solid phase on interstellar dust grains. The focus point of this chapter will be in the top line where O atoms lead to O₂ which can lead to O₃. This figure is taken from [3].

3.2: This figure shows the results of the TPD experiments of molecular oxygen beam dosed onto SiO₂ for 1, 2, 5, 10, 20 and 50 minutes. A clear change can be seen
between 5 and 10 minute dosing, this is due to the change from sub–monolayer to multilayers of O$_2$. This change is more clearly shown in the insert of 1, 2, 5 and 10 minute dosages.

3.3: This figure shows the results of the leading edge analysis of the pure O$_2$ molecular beam dosing TPD experiment. Two separate regions can be distinguished where the lower three points relate to the coverages of 1, 2 and 5 minute beam dosing and the latter three points are of the 10, 20 and 50 minute dosing. These two regions are the sub–monolayer and multilayer respectively.

3.4: This figure shows the Arrhenius plot of the TPD trace after the molecular oxygen beam has dosed the bare SiO$_2$ surface for 50 minutes. The black dots correspond to the experimental data and the red dots highlight the leading edge of the TPD profile from the same 50 minute TPD trace in Figure 3.2.

3.5: This figure shows the TPD results of 50 min molecular oxygen dosing onto SiO$_2$ (black scatter) with the CKS model as a red solid line.

3.6: As can be seen in this figure, O$_3$ is produced as the O atom beam bombards the bare SiO$_2$. As the dosing time is increased a peak at about 1045 cm$^{-1}$ is seen to grow as dosing time is increased.

3.7: This figure shows the fit between the RAIRS data (black) and the fit (red) which is made by three Gaussians in blue. The result of the fit has been listed in Table 3.1. Further to this, the top of the figure shows the residuals from the experimental data and the overall fit.

3.8: This figure shows the results when the O atomic beam is dosed onto SiO$_2$ for a duration of 50 minutes. The O$_2$ TPD trace, measured through m/z = 32 shows two main peaks, the low temperature peak corresponds to sample desorption while at higher temperatures O$_2$ is released from the cold finger. The insert shows O$_3$ desorption, m/z = 48, as measured simultaneously with O$_2$ cold–finger desorption.

3.9: This is the Arrhenius plot of the desorption profile from the TPD trace in Figure 3.8. The black scatter is representative of the inverted TPD trace after the atomic beam has bombarded the bare SiO$_2$ for 50 minutes with the red points being the leading edge of the TPD trace.

3.10: This figure shows the comparison between the experimental data (black scatter) and the CKS model (red solid line). This fit has been created with an $E_{des}$ of 6.7 kJ mol$^{-1}$ and $5 \times 10^{27}$ molecules cm$^{-2}$ s$^{-1}$. 
3.11: This figure shows the formation of O$_3$ when the O atom beam bombards 20 ML p–ASW. As can be seen, the shape and character of the feature is similar to when O atoms probe the bare SiO$_2$ surface.

3.12: This figure shows the three regions of interest in the IR spectrum. These are difference spectra showing the difference of the p–ASW film (A$_{p-ASW}$) after O atom bombardment (A$_{O\text{ atoms}}$). The red boxes indicate the specific regions where H$_2$O$_2$ features are expected if formed, however no such features are observed.

3.13: This figure is of the 20 ML p–ASW film after 50 minute O atom bombardment as it desorbs. The species of interest in this figure is O$_3$ as it leaves the surface, the shape and temperature at which it leaves the surface is due to the porosity of H$_2$O. The insert is an Arrhenius plot where the red dots (the leading edge of desorption) are used to extract the kinetic information of the desorption process.

3.14: This figure shows the comparison between the experimental data (black) of O$_2$ desorption from 20 ML p–ASW and the model (red).

3.15: This figure shows the desorption of O$_3$ after 20 ML p–ASW has been bombarded by O atoms for 50 minutes. A change is observed in the temperature region above 62 K as O$_3$ begins to leave the surface.

3.16: The two panels in this figure illustrate the lack of H$_2$O$_2$ during the experiments. Panel (A) shows the desorption of O$_2$ which (B) is of H$_2$O as followed through different mass fragments. The two spectra are expected to be more similar in the high time end if H$_2$O$_2$ is desorbed.

3.17: This figure shows the O$_3$ peak after the O atom beam has bombarded a multilayer surface of c–ASW for 50 minutes. There are no other observed differences in the IR spectrum.

3.18: This figure illustrates what happens after the O atoms have bombarded a multilayer surface of c–ASW for 50 minutes. Desorption is seen to initiate at about 25 K and a more clear peak is observed as compared to a similar amounts of O$_2$ desorbing from p–ASW. The insert shows the Arrhenius plot of the desorption from which kinetic parameters can be extracted.

3.19: This figure shows the attempt at fitting O$_2$ desorption from c–ASW (black scatter) with a CKS model (red solid line). The O atoms beam is believed to alter the morphology of the molecular film leading to the experimental data appearing as presented.
3.20: This figure shows the result, when looking at O₃, when a 20 ML CSW film has been bombarded with O atoms for 50 minutes. No other change in the 800 – 4000 cm⁻¹ region was observed.

3.21: The figure illustrates the shape as O₂ is desorbed from SiO₂ after a 50 minute atomic beam dose. The reason for the long trailing edge of this multilayer desorption spectra is believed to be due to the O atom beam affecting the morphology of the CSW surface. The insert sheds light on the desorption kinetics through linear analysis of the red points.

3.22: This figure shows the similarity in the leading edge of the experimental data and the CKS model of O₂ desorption from CSW after 50 minute O atoms beam dosing.

3.23: This figure shows the result of adding all the TPD spectra into one graph. A clearly defined peak is observed which can be used for further analysis.

3.24: This inverted figure leads to the desorption energy through the gradient of the red line while the intercept gives an indication of the pre-exponential factor.

3.25: This figure shows the correlation between the experimental data (black scatter) and the model (red solid line) of O₃ desorption.

3.26: This figure shows the results as gathered from the CKS model and presented in Table 3.3. Formation of O₃ (A) occurs as expected, however to a greater extent than shown in the experimental TPD data. O₃ destruction (B) has also been shown in this figure and is considered not to be the cause for the lack of O₃ signal during desorption in the TPD experiments.

Chapter 4

4.1: Temperature programmed RAIRS of 0.5 ML H₂O on SiO₂ showing an increasing intensity of the νOH band as the temperature increases. The magenta band shows a 20 ML spectrum of H₂O, as can be seen, the annealed appear similar to the multilayer. The sharp features are due to gas-phase water in the optics boxes on the air side of the UHV apparatus. This figure is taken from [2] and [8].

4.2: This plot shows the correlation between pressure in mbar and counts of m/z = 18 as monitored by the QMS. This linear relationship between pressure and counts was used throughout to note the background H₂O pressure during an experiment.
4.3: These spectra show the deposition of 0.5 ML H$_2$O (black) on SiO$_2$ followed by TPD of that film. After the partial pressure of H$_2$O has decreased to $<2 \times 10^{-10}$ mbar the sample was cooled and another spectrum was taken (red). Re-adsorption of H$_2$O on the timescale of the experiment is not significant due to the low H$_2$O partial pressure.

4.4: The result of depositing 0.5 ML H$_2$O onto SiO$_2$ at 18 K. The time between each RAIR spectrum was one hour as this was determined to be the average time between scans when H$_2$O is annealed at the other temperatures investigated. The sharp peaks are due to gas–phase H$_2$O in the optics boxes on the air side of the UHV apparatus.

4.5: The result of depositing 0.5 ML H$_2$O onto SiO$_2$ at 100 K for a total of 500 sec before annealing to the $A_{\infty}$ times, $A_{\infty}$, factor. The sharp peaks at 3500 – 3600 cm$^{-1}$ are due to gas–phase H$_2$O in the optics boxes on the air side of the UHV rig.

4.6: These spectra show the change when depositing 0.5 ML H$_2$O at 17 K before annealing to 100 K for 20 minutes and again for 120 minutes.

4.7: This figure shows the linear relationship of Equation 3. The slope is the rate constant, $k$, for the isolated H$_2$O to a bulk process. The values for this figure are obtained from Table 4.2.

4.8: This figure shows the Arrhenius plot where two regimes can be observed. The first regime, a), illustrates a rising edge while b) indicates a plateau. A series of fits have been done to estimate an average gradient for each a) and b) in order to obtain an activation energy, however a clear change is apparent as the temperature increases. The figures have been shown in two parts for clarity with matching colours for the linear fits.

4.9: This figure shows the final step after analysis with an indication of the best linear fits to the two data regions in the experimental results.

4.10: This figure shows the effect of O atom bombardment on 0.5 ML H$_2$O. The large sharp peaks are due to gas phase H$_2$O in the optics boxes outside of the UHV chamber.

4.11: This figure is of 1 ML p–ASW as O atoms bombard the sample for a total of 50 minutes. The same trend is seen here, however to a greater extent, as is seen in Figure 4.10.

4.12: As can be seen in this figure, 1 ML of c–ASW does not behave as the p–ASW films. Throughout O atom irradiation for 50 minutes, the band is invariant, however has the same shape as the p–ASW spectra presented in this work.
4.13: This figure shows the effect of O atoms bombarding a 1 ML CSW film. The atomic beam was dosed in steps for a total of 50 minutes. The bump seen in the 1 ML CSW spectrum (red spectra) at about 3350 cm$^{-1}$ disappears during O atom bombardment.

4.14: This figure shows the H$_2$O as isolated (i) converting into clusters (c) with time through a heating rate of 1 K century$^{-1}$ (a) and the corresponding temperature for the cluster formation (b). The simulation has been done for 0.5 ML H$_2$O with an $E_{act}$ of 1.8 kJ mol$^{-1}$ and a pre–exponential factor of $10^{12}$ s$^{-1}$.

4.15: This figure shows what happens as H$_2$O adsorbs onto an interstellar dust grain as during cloud collapse and freeze–out as the temperature falls from 110 K to 10 K. Gas phase molecules (g) will either adsorb as isolated or clustered H$_2$O. As the temperature is above the energy needed for de–wetting, isolated molecules instantly become crystalline or clustered depending on temperature. The simulation has been done for 0.5 ML H$_2$O with an $E_{act}$ for de–wetting of 1.8 kJ mol$^{-1}$ and a pre–exponential factor of $10^{12}$ s$^{-1}$ with a cooling rate of 1 K century$^{-1}$.

4.16: This figure shows the behaviour of CO as it adsorbs onto an interstellar dust grain with H$_2$O already present. Assuming an equal probability of CO initially adsorbing onto H$_2$O or SiO$_2$, CO then migrates to the preferred SiO$_2$ sites until all SiO$_2$ sites are inhabited leaving H$_2$O sites open for interactions as compared to the less favoured CO multilayer formation.

4.17: This cartoon represents the onset of H$_2$O cluster formation and the de–wetting process even at temperatures of 10 K on dust grains, brown substrate, in the cores of molecular clouds. The red circles are representative of O atoms, black circles are H atoms, blue ovals are H$_2$O molecules and green ovals are molecules of CO. This figure draws inspiration from [8].

Chapter 5

5.1: This figure shows how the surface potential varies proportionately with amount of N$_2$O. A decrease in the potential is observed as the deposition temperature rises. At temperatures above 65 K, N$_2$O does not stick effectively to the gold surface under UHV conditions and no measurements are made [1].

5.2: This cartoon illustrates the thermodynamically most favoured structure for a dipolar molecular solid (A) and the likely molecular orientation in the spontelectric phase (B).
5.3: This figure shows the TPD results of depositing various amounts of N\textsubscript{2}O onto SiO\textsubscript{2} and desorption of the molecular films. N\textsubscript{2}O detected as m/z = 44 is recorded as a function of temperature of the substrate. As can be seen, a clear change is observed between 6 L and 7 L which is the change between the sub–monolayer and the multilayer regimes as explained in Chapter 2.

5.4: This figure shows the full range of the spectrum obtained when having deposited 14 ML N\textsubscript{2}O onto SiO\textsubscript{2} at 50 K. The peaks of interest at about 2250 cm\textsuperscript{-1} have been highlighted in the insert [19].

5.5: This figure indicates that changing the amount of N\textsubscript{2}O from 1.4 ML to 28 ML has little bearing on the peak positions. The N\textsubscript{2}O films were deposited at 50 K to ensure the sharp features of the LO–TO splitting. The dashed lines are a guide to the eye to show peak shifts as compared to the centre of the peak of the 14 ML N\textsubscript{2}O spectrum.

5.6: This figure shows 14 ML N\textsubscript{2}O on SiO\textsubscript{2} being annealed from base temperature. The red arrows indicate the movement of the peaks as they shift with increasing temperature. N\textsubscript{2}O deposited at 18 K is believed to be amorphous and the higher temperature spectra (>48 K) are crystalline. When the film is annealed to 48 K characteristics of both structural states can be observed.

5.7: This figure shows the effect of changing the deposition temperature of 14 ML of N\textsubscript{2}O. A greater contraction of the LO–TO splitting is observed as compared to Figure 5.6. To make the figure easier to read, only five experiments have been shown instead of the full range [19].

5.8: This figure shows the comparison between the experimental data (open circles), and the Gaussian fits (solid red line) to the LO–TO splitting of N\textsubscript{2}O with the residuals shown in the box above the graph.

5.9: This figure shows the result of plotting the data outlined in Table 5.1 where squares and dots correspond to the LO and TO peaks, respectively. Further to this, the black and red represent the annealing and deposition temperature experiments, respectively. As can be seen, a contraction occurs with increasing temperature, and greater so when the deposition temperature is increased [19].

5.10: This figure shows the change in the inhomogeneous broadening of the LO–TO splitting of N\textsubscript{2}O from the annealing experiment (black squares) and the different deposition experiments (red dots) [19]. The data points were calculated by measuring the intensity at 2150 cm\textsuperscript{-1} and normalising the data from Figures 5.6 and 5.7.
5.11: This figure shows the desorption of different CO coverages from SiO$_2$. As can be seen, a clear change in behaviour is observed between 15 L and 20 L indicating that this is the completion of the first monolayer.

5.12: This figure shows the whole spectrum when depositing 5 ML of CO onto SiO$_2$ at 20 K. The feature of interest, the CO stretch, at about 2140 cm$^{-1}$ has been highlighted in the insert to show the LO–TO splitting. The sharp bands at >3500 cm$^{-1}$ and in the 1250–2000 cm$^{-1}$ range are of gas–phase H$_2$O with the negative bands at about 2300 cm$^{-1}$ being gas–phase CO$_2$ in the optics boxes outside of the UHV chamber [28].

5.13: This data shows that as the amount of CO is increased from 2.5 ML to 10 ML a slight change above the spectrometer resolution is observed when the film thickness is doubled. However, considering the general uncertainty of background dosing being about 20%, the amount of molecules on the surface can be said to have no impact of the LO–TO peak positions.

5.14: This shows the LO–TO splitting as the 5 ML CO film is annealed from 20 K to 26 K. Observing shifts of the peaks over the resolution of the spectrometer is impossible.

5.15: This figure shows the results of depositing 5 ML CO onto SiO$_2$ at different temperatures. A slight shift in the LO–TO splitting of the νCO band is now observed which is greater than the resolution of the spectrometer (0.1 cm$^{-1}$) [28].

5.16: This figure shows the comparison between the experimental RAIRS data of the νCO band of 5 ML CO on SiO$_2$ at 20 K and the fit with Gaussians with the residuals shown above the data and fit.

5.17: This figure shows the position of the LO and TO modes of the νCO band of 5 ML CO on SiO$_2$ as the deposition temperature changes from 20 K through to 26 K [28].

5.18: This figure shows another way of looking at the order of dipoles in the 5 ML CO film as the temperature of deposition is increased from 20 K through to 26 K [28].

5.19: This figure shows all the RAIRS data collected when 20 ML CO is deposited onto multilayers of p–ASW (A), c–ASW (B) and CSW (C) at the indicated temperatures in the 20 K to 24 K range. A shift in the LO–TO splitting of νCO is observed as the temperature increases [31].

5.20: This figure displays the data from Table 5.3 of the LO (squares) and TO (circles) modes of the νCO band contracting with increasing deposition temperature. As can be seen, a greater splitting is observed at 20 K for p–ASW (blue) as compared to the other c–ASW (black) and CSW (red) [31].
5.21: This figure shows the inhomogeneous broadening as measured at 2141 cm\(^{-1}\) between the LO and TO modes of the \(\nu\)CO band of 20 ML CO on H\(_2\)O ice. The blue data points are from CO on p–ASW, black is c–ASW and red is CSW. The linear regressions of the points give an idea of the similarity of environments of CO on H\(_2\)O surfaces [31].

5.22: This figure shows the relationship with the spontelectric contribution to the LO–TO splitting and the dipole alignment for N\(_2\)O. A linear relationship exists as expected except for the 66 K data point due to the decrease in the sticking coefficient when the temperatures approaches the desorption temperature of N\(_2\)O [19].

5.23: This figure shows the final result comparing the observed RAIRS data (black scatter) with the modelled data (red solid line). The dashed red lines indicate the level of uncertainty in the modelled data (± 0.8 cm\(^{-1}\)) [19].

5.24: This figure shows the linear relationship between the value of the LO–TO splitting of CO on SiO\(_2\) with respect to the inverse temperature. The intercept with the y–axis leads to an approximation for the intrinsic component of the LO–TO splitting of CO [28].

5.25: The two graphs show the depletion of CO from the gas phase (A) as the molecules condense onto the cold interstellar dust grain (B) with time. Both graphs have been done with typical astronomical conditions as found in the core of B68 [31].

5.26: This figure shows how CO initially aggregates onto a dust grain. The spontelectric effect in CO starts when a multilayer is formed thereby creating a positively charged surface. This attracts electrons, which in turn attracts cations and together they can recombine leading to the cycle starting over.

Chapter 6

6.1: This figure shows the surface potential measurements of methyl formate as the temperature increases. As can be seen, methyl formate behaves as a typical spontelectric material initially before changing behaviour at about 70 – 80 K. Above this temperature the surface potential increases along with the temperature until the Curie point is reached at about 90 K [21, 22].
<table>
<thead>
<tr>
<th>Abbreviation</th>
<th>Description</th>
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<tbody>
<tr>
<td>aCNM</td>
<td>Atomic Cold Neutral Medium</td>
</tr>
<tr>
<td>(p, c)-ASW</td>
<td>(porous, compact)-Amorphous Solid Water</td>
</tr>
<tr>
<td>CSW</td>
<td>Crystalline Solid Water</td>
</tr>
<tr>
<td>E-R</td>
<td>Eley-Rideal</td>
</tr>
<tr>
<td>FTIR</td>
<td>Fourier Transform Infrared</td>
</tr>
<tr>
<td>FWHM</td>
<td>Full Width at Half the Maximum</td>
</tr>
<tr>
<td>GMC</td>
<td>Giant Molecular Cloud</td>
</tr>
<tr>
<td>H-K (H-A)</td>
<td>Harris-Kasemo (Hot Atom)</td>
</tr>
<tr>
<td>HIM</td>
<td>Hot Ionised Medium</td>
</tr>
<tr>
<td>HOPG</td>
<td>Highly Oriented Pyrolitic Graphite</td>
</tr>
<tr>
<td>IR</td>
<td>Infrared</td>
</tr>
<tr>
<td>ISM</td>
<td>Interstellar Medium</td>
</tr>
<tr>
<td>ISO</td>
<td>Infrared Space Observatory</td>
</tr>
<tr>
<td>ISRF</td>
<td>Interstellar Radiation Field</td>
</tr>
<tr>
<td>L-H</td>
<td>Langmuir-Hinshelwood</td>
</tr>
<tr>
<td>LO</td>
<td>Longitudinal Optical</td>
</tr>
<tr>
<td>mCNM</td>
<td>Atomic Cold Neutral Medium</td>
</tr>
<tr>
<td>MCT</td>
<td>Mercury Cadmium Telluride</td>
</tr>
<tr>
<td>MS</td>
<td>Mass Spectrometry</td>
</tr>
<tr>
<td>MSSR</td>
<td>Metal Surface Selection Rule</td>
</tr>
<tr>
<td>NASA</td>
<td>National Aeronautics and Space Administration</td>
</tr>
<tr>
<td>OFHC</td>
<td>Oxygen Free High Conductivity</td>
</tr>
<tr>
<td>PAH</td>
<td>Polycyclic Aromatic Hydrocarbon</td>
</tr>
<tr>
<td>QMS</td>
<td>Quadrupole Mass Spectrometer</td>
</tr>
<tr>
<td>RAIRS</td>
<td>Reflection-Absorption Infrared Spectroscopy</td>
</tr>
<tr>
<td>SN</td>
<td>Supernova</td>
</tr>
</tbody>
</table>
SWS  Short Wavelength Spectrometer
TO   Transverse Optical
TPD  Temperature Programmed Desorption
UHV  Ultrahigh Vacuum
VSE  Vibrational Stark Effect
(V)UV (Vacuum) Ultraviolet
WIM  Warm Ionised Medium
WNM  Warm Neutral Medium
List of Publications and Conference Presentations

Publications


Wetting and De-wetting Behaviour on Model Interstellar Dust Grains

$\text{H}_2\text{O}$ behaviour on Interstellar Dust Grains: A Closer Examination: A. Rosu-Finsen, D. Marchione and M.R.S McCoustra, In Preparation


O atom Chemistry: A. Rosu-Finsen and M.R.S. McCoustra, In Preparation

Conference Presentations

Spontelectric Effect in Solid Nitrous Oxide (N$_2$O): A RAIRS Study of Dipole Alignment: Poster presented at the 11$^{th}$ European Conference on Atoms, Molecules and Photons, Aarhus University, Aarhus, Denmark, 24$^{th}$ – 28$^{th}$ of June, 2013


Poster presented Faraday Discussions 168: Astrochemistry of Dust, Ice and Gas; NH Conference Centre, Leiden, NL, 7$^{th}$ – 9$^{th}$ of April, 2014.

Probing Model Interstellar Grain Surfaces with Small Molecules: Talk presented at the Joint Royal Society of Chemistry/Royal Astronomical Society, Milton Keynes, United Kingdom, 15$^{th}$ – 16$^{th}$ of January, 2015
Chapter 1

The Interstellar Medium

Contents of this chapter

1.1 Introduction .......................................................... 2
1.2 Molecular Clouds .................................................. 7
1.3 Sources of Energy ................................................. 10
  1.3.1 Cosmic Rays .................................................. 10
  1.3.2 Photons .......................................................... 11
  1.3.3 Thermal Shocks ............................................. 13
1.4 Astrochemistry ..................................................... 13
  1.4.1 Gas-Phase Chemistry ................................... 13
  1.4.2 Dust Grain Core ........................................... 17
  1.4.3 Grain Mantle ................................................ 20
  1.4.4 Chemistry on Dust Grain Surfaces ..................... 24
1.5 Thesis Overview .................................................. 26
1.6 References ........................................................ 27
1.1 Introduction

In all its expanding glory, the 13.8 billion years old Universe can be divided into two types of regions. The first of these categories encompasses all stellar systems with possible orbiting planets and satellites and the second category is the regions between these systems called the interstellar medium (ISM). Various fields of study have been formed dedicated to understanding the different processes and phenomena observed in the Universe; astrophysics, astrochemistry and astrobiology. Astrophysics focuses on the physical laws that formed and control the Universe through theoretical studies, laboratory experiments and observations. At present, it is believed that baryons (baryonic matter is the ‘normal’ matter composing the visible Universe, as opposed to dark matter and dark energy) make up about 4% of the mass of the Universe, while 23% is believed to be dark matter and 73% being dark energy [1–3]. Baryons define matter composed of protons, neutrons and electrons, and can therefore be detected by methods such as infrared (IR), ultraviolet (UV), radio, microwave and rotational spectroscopy. Dark matter was first mentioned by Fritz Zwicky in 1933 who referred to it as ‘dunkle Materie’ (dark matter) [4] and is only inferred by its gravitational effects [5, 6]. Dark energy was first introduced in 1998 by Michael Turner [4] and is believed to cause the acceleration of the Universe’s expansion [6]. Both dark matter and energy are not seen in the electromagnetic spectrum, however with the discovery of gravitational waves, more can possibly be learned in the future.

Astrochemistry is, as the name suggests, the study of chemistry both in our Solar system and outside it. The general challenge in this field is to obtain a unified model for the chemical reactions occurring, both gas–phase and surface chemistry, to explain the observations of molecules and their abundances as surveyed by ground– and space–based observatories such as the Atacama Large Milimeter/submillimeter Array (ALMA) and telescopes such as the Hubble or James Webb telescopes. The latter, and youngest, field of astroscience, astrobiology has recently gained a lot of attention since many exoplanets have been discovered orbiting stars [7]. Some of these exoplanets can be found in the ‘Goldilocks’ zone, which is the distance from a star where the temperature can support the presence of liquid water on their surface. While it has been difficult to determine the composition of exoplanetary atmospheres due to ‘flat’ signals meaning specific molecular features cannot be distinguished, recent progress has been made. The exoplanet of 55 Cancri e is not in the ‘Goldilocks’ zone and has a surface temperature of
about 2000 K, however observations have shown that the atmosphere of this celestial body contains large amounts of H and He, this is the first detection of an exoplanet’s atmosphere [8]. This observation was done with the Hubble Space Telescope, one telescope of many investigating and observing the farthest reaches of the Universe. One of the most famous examples of astrophysical observation of dark clouds is of the well–known Barnard 68 as seen in Figure 1.1 [9].

![Figure 1.1](image)

**Figure 1.1:** These pictures are of a molecular cloud named Barnard 68. The picture to the left shows the cloud as observed through optical based telescopes while the right picture is presented in false colour showing the IR background radiation from the stellar landscape behind the cloud.

The pictures in Figure 1.1 show various regions of the ISM, the lack of colour in the left being from interstellar clouds obscuring visible light from passing through due to a greater concentration of gas and dust. This lack of gas and dust in the regions around the cloud means that the stellar landscape can be observed. To contrast the stark change in molecular cloud and stellar landscape in the picture to the left, the right hand side shows the same regions as seen in the near–IR. The dust and gas in the molecular cloud does not absorb and scatter all manners of radiation leaving the astronomers who captured this picture as calling it ‘Seeing the light through the dark’ [10]. This picture illustrates the point that the ISM cannot be wholly empty and that different regions must exist.

The ISM can be divided into five regions according to their physical and chemical properties: the hot ionized medium (HIM), the warm ionized medium (WIM), the warm neutral medium (WNM), the atomic cold neutral medium (aCNM), and the molecular cold neutral medium (mCNM). These regions of space do not have specific boundaries
with each other, but are blended together. **Table 1.1** shows the typical traits associated each region [11, 12].

<table>
<thead>
<tr>
<th>ISM Region</th>
<th>Common Name(s)</th>
<th>Temperature / K</th>
<th>Density / molecules cm(^{-3})</th>
<th>State of Hydrogen</th>
<th>Ionization Fraction</th>
<th>(A_V) / mag</th>
</tr>
</thead>
<tbody>
<tr>
<td>Hot Ionized Medium (HIM)</td>
<td>Coronal Gas</td>
<td>(10^6)</td>
<td>0.003</td>
<td>(\text{H}^+)</td>
<td>1</td>
<td>?</td>
</tr>
<tr>
<td>Warm Ionized Medium (WIM)</td>
<td>Diffuse Ionized Gas (DIG)</td>
<td>(10^4)</td>
<td>(\geq10)</td>
<td>(\text{H}^+)</td>
<td>1</td>
<td>?</td>
</tr>
<tr>
<td>Warm Neutral Medium (WNM)</td>
<td>Intercloud (\text{H}_1) ((^1\text{H}))</td>
<td>(8 \times 10^3)(- 10^4)</td>
<td>0.1</td>
<td>(\text{H})</td>
<td>0.1</td>
<td>~0.5</td>
</tr>
<tr>
<td>Atomic Cold Neutral Medium (aCNM)</td>
<td>Diffuse Cloud</td>
<td>100</td>
<td>10–100</td>
<td>(\text{H} / \text{H}_2)</td>
<td>(10^{\text{-}3})</td>
<td>0.5–1</td>
</tr>
<tr>
<td>Molecular Cold Neutral Medium (mCNM)</td>
<td>Molecular Cloud</td>
<td>1–50</td>
<td>(10^4)–(10^5)</td>
<td>(\text{H}_2)</td>
<td>(10^{\text{-}7})–(10^{\text{-}8})</td>
<td>~5</td>
</tr>
</tbody>
</table>

**Table 1.1:** The different regions of the ISM with their general temperatures in K, state of hydrogen and the ionization fraction of the atoms/molecules. The density as stated in molecules cm\(^{-3}\) concerns the concentration of atomic hydrogen in the first four regions and molecular hydrogen in the mCNM. The last column, \(A_V\), is the extinction of light as it travels through the different media. The question marks indicate that the exact value of the magnitude is unknown, but have been assumed to be zero due to the lack of molecules [11, 12].
As can be seen in **Table 1.1**, the density in the HIM is the lowest of all five parts and the temperature is extremely high. The HIM is created after supernova (SN) explosions [11] when stars scatter their atoms farther than the boundaries of their previous stellar system, leading to the low density and high temperature observed. The WIM are the regions beyond the HIM, the aftermath of the prior SN events, where temperatures have fallen and pressures have risen slightly. The amount of radiation is still enormous, leading to a similar ionization fraction and thereby state of $H^+$ as seen in **Table 1.1**. Regions where the radiation is less, but the temperature is still high are the WNM. Here the radiation mostly leads to atoms recombining or keeping their electrons, thereby remaining neutral. When gravitational forces increase, gas and dust grains form regions such as the atomic cold neutral medium (aCNM also called diffuse clouds). Here the pressures are greater and temperatures lower (about 100 K) than other regions of the ISM due to shielding caused by the dust and gas. Gas phase chemistry is responsible for reactions leading to small amounts of molecules such as $H_2$ along with lesser parts of HCN, NH$_3$, CO and H$_2$CO in these clouds [11, 12]. The low density of molecules is a part of the reason for the lack of chemical diversity in the aCNM, however such clouds are still vulnerable to external vacuum UV (VUV) radiation which is the dominant reason for the atomic nature of diffuse clouds. This harsh VUV field causes photodissociation leading to molecular destruction. These diffuse clouds are seen to envelope dense clouds leading to a density and temperature gradient from the outer reaches to the cold core [11]. An intermediate stage in this cloud envelope is termed translucent clouds; this regime bridges the gap in density, temperature, ionisation fraction and extinction of **Table 1.1**. This means such clouds typically have temperatures ranging from 50 – 100 K, densities between $10^2$ – $10^3$ molecules cm$^{-3}$ and $A_V$ of 1 – 5 mag. The state of hydrogen changes from H towards dominance of $H_2$ [12].

As the gravitational forces continue to pull on the diffuse cloud, the density increases further leading to a greater UV shielding effect which therefore means a lower temperature is found in the cores of the molecular cold neutral medium (mCNM also called dark or dense clouds). This temperature can approach absolute zero and so these are some of the coldest regions known. These dense clouds, are the focus of this thesis due to the variety of molecules observed, over 190 so far as listed in **Table 1.2** [13–15]. Referring back to **Figure 1.1(A)**, it can be seen that bright stars and at the border of B68 fewer stars are observed along with greater darkness. This is the diffuse cloud regime leading to the total darkness in the center of the figure which is the dense cloud. While
Table 1.2: This table illustrates the range of molecular complexity as observed in molecular clouds in the ISM. More than 190 different molecules have been observed until this point in time [13–15].
the different cloud regions have been described as separate environments, they can be considered as co–existing and mingled together. Still, the definitions simplify explanations when describing the ISM. The last column in Table 1.1 refers to the extinction of light from stellar sources behind a region being studied. This has briefly been mentioned as changing as the environment of the ISM changes. When observing a dense molecular cloud, the light transmitted from a star behind the cloud is absorbed and scattered as it travels through the cloud where the decrease in emission is referred to as the extinction, $A_v$, [16]. It is based on a logarithmic scale (Equation 1) where $A_v = 5$ (dense cloud) means that the flux of photons from a stellar source ($F^0_\lambda$) is 100 times less after the light has passed through a region ($F_\lambda$).

$$A_v = 2.5\log \left( \frac{F^0_\lambda}{F_\lambda} \right)$$  \hspace{1cm} \text{Equation 1}

1.2 Molecular Clouds

Molecular clouds are considered as organic syntheses factories and as seen in Table 1.2, a huge variety of molecules are observed. This is the reason for this region being of importance and interest in this work. The life cycle of a typical cloud is pictured below in Figure 1.2 as going from diffuse to dense, protostellar to stellar system and a supernova (SN) event resets the cycle. If a stellar system does not reach a SN event, the chemical richness of the system can still be released back into the gas–phase to a certain extent as the star ages. As this happens, the star will expand and vaporise most of the material in its system.

![Figure 1.2: These combined pictures show the life–cycle of an interstellar cloud from birth to destruction and rebirth as mentioned in the text.](image)
A dense cloud can be thought of as a diffuse cloud succumbing to gravitational pressure, leading to the highest densities observed in the ISM. As seen in Table 1.1, the density can range between \(10^3 \text{ – } 10^5\) molecules cm\(^{-3}\) (corresponding to \(10^{-13} \text{ – } 10^{-15}\) mbar as calculated with the ideal gas law and a temperature of 10 K) in molecular cloud cores which increases the efficiency of suitable gas–phase reactions. This is the dominant process, as in diffuse clouds, with a minor contribution from chemistry on surfaces leading to the overall observations of molecules as listed in Table 1.2 [13–15]. The surface reactions happen on dust grains covered by an icy mantle of various molecules, this will be discussed in greater detail later. As stated in Table 1.1 molecular clouds are very low in temperature, have a high density dominated by H\(_2\) and a low ionization fraction due to the high extinction factor. The parameters above are linked together through the presence of dust particles found in greater concentration in molecular clouds than in any other region of the ISM. The grains shield the molecular cloud core from UV radiation [11]. This lack of external UV radiation leads to lower temperatures, approaching 10 K [22], as compared to the other regions in the ISM. The dust grains also play a pivotal role in the formation of small hydrides leading to the dominance of H\(_2\) versus H in diffuse clouds; this will be discussed in more detail in a later chapter.

Most molecular clouds have a mass of about \(10^4\) M\(_\odot\) (M\(_\odot\) = Solar mass) or less [11], but immense clouds have been observed with estimated masses of \(10^5 \text{ – } 10^6\) M\(_\odot\) [23, 24]. Such clouds are called giant molecular clouds (GMC), and range in size from \(10^1 \text{ – } 10^2\) light–years across [24]. It was previously mentioned that 4% of the mass of the ISM is baryonic material, and of this 1% is gaseous [25]. GMCs contain most of that percentage of gas even though the volume they occupy is only about 1 – 2% of a galaxy [11]. Regular molecular clouds account for most of the volume of the ISM; they are turbulent systems where the varied chemistry accounting for the numerous chemical species reported in Table 1.2 can be found. As mentioned, these clouds are considered to be organic molecular factories, and besides giving birth to stars and planets, could also potentially contain the molecules needed for the birth of life. The origins of life are an aspect which generally falls into two distinct categories; endogenous formation or exogenous delivery of molecules necessary for life to appear on Earth.

The endogenous theory involves the very basic elements and molecules being present on a planet after its formation, and through various reactions create bigger and more
complex organic molecules eventually leading to simple and complex life. This thought and approach to the origins of life was revitalised in the scientific community with the Miller–Urey experiments in the 1950’s [26, 27]. These experiments are of great importance as they show the possibility of creating over 20 different amino acids, for example glycine and alanine, and several other organic compounds, such as urea, formic acid and lactic acid, from simple starting reagents such as H₂, NH₃, CH₄ and H₂O in conditions believed to be relevant to the early Earth. However, early Earth’s atmosphere contained less methane and more carbon monoxide making it less reducing. Another factor concerning the Miller–Urey experiments and the origins of life is that the experiment produced a racemic mixture of amino acids. However, amino acids and sugars contained in human bodies are chiral, where most amino acids are left-handed (or levorotary/sinister) and most sugars are right-handed (or dextrorotary/rectus). Even though the Miller–Urey experiments have some drawbacks, the experimental results are still of great importance as amino acids were created out of simple starting materials.

The other theory is the exogenous delivery of all the starting reagents where the precursors to life are synthesised in molecular clouds and transported to planets via comets and meteorites [28]. Amino acids are the building blocks of proteins and contain the necessary elements incorporated in nucleobases. None of these molecules have been unambiguously observed in the ISM, but the necessary elements to form them are present in clouds. Some credence to the exogenous theory has been given due to the detection of chiral amino acids in meteorites and asteroids. The Murchison meteorite which landed in Australia contained various amino acids including glycine and alanine [29, 30] where the L-enantiomer of amino acids has been found to be in excess [30]. The origin of the organic material found in this meteorite has been under debate, the possibility of the meteorite having been contaminated with organic compounds from Earth being the central point of conflict. The conclusion that the organic material found on the Murchison meteorite was of an extraterrestrial origins was determined due to a substantially higher isotopic abundance of ¹⁵N than found on Earth [30]. Another meteorite that landed in Antarctica was found to contain similar amino acids to the Murchison meteorite, including glycine and alanine [31]; the organic matter from this meteorite is not under dispute due to the inhospitable Antarctic environment. Various simple organic species, potential precursors of amino acids, such as isocyanic acid and acetonitrile have also been detected to contain in the Hale–Bopp asteroid [32]. Renewed interest with comets and molecules present on them was sparked when the Philae lander
touched down on the 67P / Churyumov–Gerasimenko comet 515 million kilometres from Earth through the Rosetta mission [33]. Measurements on the surface have shown signs of water [34] and organic molecules [35] such as methyl isocyanate, acetone, propionaldehyde, and acetamide which have previously not been noted as being part of comets [36].

For molecules such as HNCO and CH$_3$CN to be formed, chemical reactions must occur in the ISM. With temperatures approaching absolute zero, and UV radiation not being able to penetrate the cloud cores, only energetically barrierless reactions would have to occur to keep chemistry alive. Barrierless reactions do occur in the ISM between two neutral molecules (more about this in a later section). An energy source is required to create ions and radicals to react with similar or neutrals species, or to bring energy to overcome a potential reaction barrier.

### 1.3 Sources of Energy

Energy is needed to create species that can undergo barrierless reactions, and it can be used for other reactions to overcome small possible reaction barriers. All of the energy sources can be considered as having their origins from stellar objects. The energy sources discussed in this section can be seen in Figure 1.3 and their approximate energy in the electromagnetic spectrum [25].

![Figure 1.3](image.png)

**Figure 1.3**: This cartoon shows the ranges of energies as found in the ISM used for reactions. The various sources are highlighted here and discussed in the text. This cartoon is taken and adapted from [25].

#### 1.3.1. Cosmic Rays

Cosmic rays can be created in different ways, one is with the release of a stellar wind. These winds are also known as coronal mass discharge, and in our Solar system lead on
to the well known natural phenomenon of aurora. A second way for cosmic rays to be produced is through the violent and widely known event of supernova (SN) explosions [37]. Cosmic rays are composed of different kinds of particles, the most common and abundant is the proton (about 84%) [38]. The helium nucleus is also present but less common, about 14% [39]. The remaining 2% are consistent of many different particles such as electrons, but all of these rays are energetically powerful, as much as 1 GeV [37]. They pass through matter with ease; breaking bonds, ionising or exciting molecules, and the cosmic rays will continue to have energy for further reactions [39]. In this way, a cosmic ray leaves a trail of reactive molecules, ions, electrons or excited molecules, which can react readily. The electrons created are a secondary effect, and a new energy source is created by the cosmic ray referred to as secondary electrons [40, 41] which can lead to chemical reactions or electron promoted desorption. Also, since the cosmic rays have a physical presence, sputtering can occur as they bombard an icy mantle of a dust grain leading to collision–induced desorption.

1.3.2. Photons

Photochemistry is an important factor in the chemistry occurring in the ISM. Photons come in a variety of energies, but the most typical is the Lyman α photon at about 10.2 eV. This photon is emitted when the electron of the hydrogen atom relaxes from the second orbital (n = 2, where n refers to the principle quantum number) back to the first orbital (n = 1) [42].

The UV radiation available for chemical reactions can arise from different sources with stellar UV sources being the most abundant. These photons are used, not only for reactions, but also for the astronomical observations and determination of extinction of light as it goes through different regions in the ISM. The effect the environments (extinction) have on the energy of UV photons can be seen in Figure 1.4 [43] which is of the interstellar radiation field (ISRF) in a giant molecular cloud.

As has been mentioned earlier, a molecular cloud has a typical extinction factor, $A_v$, of about 5. From Figure 1.4, a drop is observed as $A_v$ changes from 0 through to 200 indicating the difficulty of UV photons to penetrate the cores of dark clouds. Mathis et al. concluded that the initial 0.1 – 8 μm of the ISRF traces arise from stellar heating while the remaining 8 – 1000 μm of field comes from re–emitted radiation from the
present dust grains. As these dust grains absorb and scatter UV photons a decrease in photon abundance follows which has been estimated as a $10^4$ photon cm$^{-2}$ s$^{-1}$ reduction at $A_v = 5$ as compared to $A_v = 0$ [44].

**Figure 1.4:** This figure is of the ISRF of a molecular cloud. As can be seen, the flux and energy of UV photons decreases as the extinction factor, $A_v$, increases due to the presence of interstellar dust grains. This figure is taken from [43].

Another type of stellar–based UV radiation is when a star dies. During the SN event when the core of the star collapses, the shockwave created converts the thermal energy of the star’s remnants into radiation [45]. Also occurring from a SN event are the cosmic rays mentioned earlier and by their extension the secondary electrons. The electrons can partake in reactions as described above, the products created need to relax back to a ground state and one method for this is by emission of a photon. When this happens an internal UV field is created in molecular clouds; such an internal field can also be created by protostars in a molecular cloud [46].
IR radiation is also a present photon energy source. When a protostar is in the early stages of evolution the main emissions lie in the IR wavelengths and are emitted from the core of the protostar. After about $10^6$ years, as the protostar grows, the core becomes optically opaque which prevents the IR radiation from escaping. This typically happens when the protostellar object has reached temperatures of $1500 – 2000 \text{ K}$ [39].

Another form of a photon energy source is X–ray radiation which is high in energy. Observations of the galaxy Centaurus A indicated that most of the X–ray emission was below $10^3 \text{ eV}$. They are emitted by young stars and by shockwaves [47], but energies can reach up to $10^4 \text{ eV}$ and higher [48].

1.3.3. Thermal Shocks

The same shockwaves described above can also cause a temperature increase when it strikes a gas cloud [1, 49], at the shock front of the cloud the temperature can reach as much as $2000 \text{ K}$ [25]. Another source of thermal energy is a protostellar core inside a molecular cloud. The temperature of the protostar depends on the stage of evolution, but it can range from typical molecular cloud temperatures to $10^6 \text{ K}$ [39]. As the temperature increases in the vicinity of icy dust grains, the sublimation temperature can be reached releasing molecules into the gas–phase.

1.4 Astrochemistry

Much is known about the chemistry in the ISM, but even more is still to be discovered. In the previous sections, a description of what is present in the astrophysical environment and the different energy sources responsible for the chemical diversity observed in Table 1.2 has been given. Knowing the above, this section will describe the reactions through which molecules can be created. Only two general types of chemistry exist in the ISM, gas–phase chemistry and surface and solid state chemistry.

1.4.1 Gas–Phase Chemistry

Gas–phase chemistry is the dominant pathway for new molecules to be created in the ISM. It is the dominant process due to gas making up about 99% of baryonic matter in the ISM [50], and under the influence of the various energy sources, e.g. UV–photons, cosmic rays and electrons, products listed in Table 1.2 can arise. Although the
conditions in the ISM are hostile, as explained earlier, gas–phase chemistry still persists through neutral–ion reactions due their barrierless character. These reactions take place between two bodies, while three–body reactions are rare due to the low density even in cold molecular cores [50]. A recent theory concerning desorption from solid surfaces speculates that the icy mantle coating the dust grains in dense clouds could “explode” due to energy being released after the formation of H$_2$ in the bulk of the ice [51, 52]. The instant after the explosion, the gas–phase density would be similar to the density of the solid ice, which could mean that three–body reactions may be more common than initially thought.

Gas–phase reactions generally happen through one of three pathways; formation of new molecules, bond–rearrangement and destruction of a species [25, 50, 53]. The reactions are reversible, so the opposite of formation reactions can be thought of as destructive mechanisms.

The formation pathways are concerned with the synthesis of larger molecules from smaller starting materials (hereafter denoted as A and B). There are different types of reactions for the formation of molecules:

- Radiative Association:
  
  $\text{A} + \text{B} \rightarrow \text{AB} + \text{h}\nu$  \hspace{1cm} Equation 2 (A)

- Three–Body Reactions (M is the third body):
  
  $\text{A} + \text{B} + \text{M} \rightarrow \text{AB} + \text{M}$  \hspace{1cm} (B)

- Negative Ion Reactions:
  
  $\text{A} + \text{A}^- \rightarrow \text{A}_2 + \text{e}^-$  \hspace{1cm} (C)
  
  $\text{A} + \text{B}^- \rightarrow \text{AB} + \text{e}^-$  \hspace{1cm} (D)

An example of a bond formation reaction is for H$_2$ formation as seen in Equation 3 through the negative ion reaction pathway (as seen in the generalised Equation 2(C)).

$$\text{H}^- + \text{H} \rightarrow \text{H}_2 + \text{e}^-$$  \hspace{1cm} Equation 3

This reaction is believed to be one of the primary sources of H$_2$ in the early stages of the Universe, where H$^-$ forms through radiative association with an electron (reaction Equation 8(C) later) [53, 54].
The bond–rearrangement pathways happen between already formed molecules and atoms or other molecules. Below are the general characteristics of such reactions:

- Neutral Exchanges:
  \[ AB + D \rightarrow A + BD \] \textit{Equation 4 (A)}

- Ion–Molecule Reaction:
  \[ AB + D^+ \rightarrow A + BD^+ \text{ or } A + B^+ + D \] \textit{(B)}
  \[ AB + D^+ \rightarrow AB^- + D \text{ (charge transfer)} \] \textit{(C)}

An example of a bond re–arrangement reaction can again be displayed through the use of H2 as in \textit{Equation 5}.

\[ H_2^+ + H_2 \rightarrow H_3^+ + H \] \textit{Equation 5}

The H2+ ion in reaction \textit{Equation 5} can be formed from cosmic ray interaction with H2. The resulting H3+ cation is very important as it reacts with neutral molecules (E) to form hydrogenated molecular cations (EH+) and molecular hydrogen [50] as displayed in reaction \textit{Equation 6}:

\[ H_3^+ + E \rightarrow EH^+ + H_2 \] \textit{Equation 6}

The last of the three pathways, destruction, is a reaction route where molecules splinter into smaller fragments. Generic examples are written in the reaction equations below;

- Photodissociation:
  \[ AB + h\nu \rightarrow A + B \] \textit{Equation 7 (A)}

- Collisional Dissociation:
  \[ AB + M \rightarrow A + B + M \] \textit{(B)}

- Dissociative Recombination:
  \[ AB + e^- \rightarrow A + B^- \] \textit{(C)}
  \[ AB^+ + e^- \rightarrow A + B \] \textit{(D)}

From the H3+ created in \textit{Equation 5}, an electron can be added to create one part H2 and one part H. This would produce the effect of a dissociative recombination reaction as seen for \textit{Equation 7(D)}.
Another reaction pathway also occurs which is important for the formation of the ions used in the above examples or yielding neutral products and radiation. These reactions usually involve electrons, the source of which can come from cosmic rays;

- Radiative Recombination:
  \[ A^+ + e^- \rightarrow A + h\nu \]  
  \text{Equation 8 (A)}

- Radiative Association:
  \[ A + M + e^- \rightarrow A^- + M + h\nu \] \hspace{1cm} (B)
  \[ A + e^- \rightarrow A^- + h\nu \] \hspace{1cm} (C)

From \textbf{Equation 8}, the released radiation (hv) can be the formation of the internal UV field present in molecular clouds. There is considerable potential for chemistry \textit{via} these general reactions involving A and B of the above equation when considering the atoms and molecules present in the ISM. Molecular hydrogen is the most abundant molecule in the Universe and has been discussed in the equations above, however larger and unsaturated molecules are also produced through gas–phase chemistry when smaller molecules come together. Generalised examples of the formation of carbon and carbon–nitrogen chain molecules are shown below [55];

\[ C_2H + C_mH_n \rightarrow C_{m+2}H_{n+} + H \] \hspace{1cm} \text{Equation 9 (A)}
\[ C_bH_2 + C_aN \rightarrow HC_{a+b}N + H \] \hspace{1cm} \text{(B)}

where m, n, b and a can have values as leading to the molecules listed in \textit{Table 1.2}.

Many examples of these reactions have been studied in the laboratory and databases have been developed over the years to compile the known gas–phase chemistry, such as the UMIST (University of Manchester Institute of Science and Technology) database for astrochemistry (UDfA) [56–60]. Presently, this database contains 6173 gas–phase reactions involving 467 molecules (this includes ions and isotopes) taking into account varying reaction rates in different environments, from dense clouds to stellar regions. Other databases include the OSU (Ohio State University) database [61, 62] and KIDA (Kinetic Database for Astrochemistry) [63]. The input data for these databases are generally the same experimental and theoretical results, however differences between the databases exist due to their individual approach to solving problems and questions. The variations can come in approximating temperature dependence of reactions (if there is one), chosen input values if more than one exists in the literature and if no values
exist (such as rate coefficients) then variations can be seen in how the database has estimated such values.

Many reactions are possible with a pure gas–phase chemistry, and most molecules are made through the pathways introduced. However, when considering all the models and production pathways of small hydrides (H₂, H₂O, NH₃ etc.), one finds that the calculated abundances do not match the significantly greater values of abundance observed in the ISM. This leads to the conclusion that other formation mechanisms must be present. This is where heterogeneous chemistry occurring at the surface of interstellar dust grains plays its key role in filling in the gap for the models to account for the observed abundances.

1.4.2 Dust Grain Core

Before an explanation of the heterogeneous chemistry begins, a description of what dust grains and their icy mantle in dense clouds are made of will be given. Observations of dust dates back a long time, and for a long time the grains were considered an irritant as they obscured starlight. From this, the first facts about dust grains can be made; they absorb and scatter certain types of radiation, e.g. UV light, and are therefore why molecular clouds appear as black spots in the sky in the UV range [64].

While humankind does not yet have direct access to the ISM and its dust grains, more than 50 particles from comet 81P/Wild 2 were identified by the NASA Stardust Interstellar Dust Collector whereof seven of these are believed to have an interstellar origin [65]. More interstellar dust grains are naturally needed to create a full characterisation of their composition, but for now the exact composition of the dust grains core is not known. Analysis of these collected dust grains revealed that the main component was amorphous silica (SiO₂). This analysis corroborates the spectroscopic data of interstellar dust grains showing strong features in the mid–IR region (1300 cm⁻¹ and 500 cm⁻¹) characteristic of the Si–O stretching vibration and O–Si–O bending vibration. However, all interstellar dust grains are likely not mainly made of SiO₂, as the IR frequencies of SiO₂ disappear when observations are turned towards carbon–rich stars. Also the destruction rate of SiO₂ is greater than all interstellar sourced SiO₂ formation rates by about an order of a magnitude [66–68]. Considering this, a general consensus has been agreed upon leading to two kinds of grain cores; one mainly made
of silicate, mostly amorphous, and the other mainly of carbon–containing material of which some is believed to be mainly amorphous [69]. Figure 1.5 (A) below shows the contributions of the core material due to the extinction of light by dust grains.

As can be seen in Figure 1.5 (A), SiO$_2$ (core grain material as shown in the figure), carbonaceous and polycyclic aromatic hydrocarbon (PAH) material are believed to be

![Figure 1.5](image)

**Figure 1.5**: These two spectra are of interstellar dust grains. Panel (A) [70] shows the various core components of dust grains as being part SiO$_2$, part carbon–based and possible PAHs. Panel (B) [71] shows how the extinction of light due to dust grains change in differing environments, however the general contributions to the profile are still present. This means dust grains are generally made of the same components regardless of location in the ISM.

the main components of interstellar dust grains. This general trend of extinction increasing with the wavelength along with the feature at about 4.6 µm$^{-1}$ are seen throughout the ISM in differing environments as shown in panel (B). The various features highlighted in panel (B) in the lower wavelength section are thought to be due to aromatic carbon complexes and H$_2$O at about 3 µm$^{-1}$ marked as ‘u’. The ‘bump’ at about 4.6 µm$^{-1}$ is thought to be due to carbonaceous material.

Various concentrations of silicate and carbonaceous material along with different metals can be found in the grains. Of the heavier elements present in these cores, one finds iron and magnesium in the greatest abundances [16, 64, 70–72]. Iron metal centres are thought to initially be in the cationic form and as a result of space weathering become iron nanoparticles [73]. With the presence of these metal centres, the chemical structure
of the grains will change. Exact compositions will vary depending on the location, space weathering and environment of the SiO$_2$ dust grain, however two separate families, orthosilicates and metasilicates are generally accepted. The family classified as Mg$_{2x}$Fe$_{2(1-x)}$SiO$_4$ are the orthosilicates can be further characterised as Fayalite (x = 0), Olivine (0 < x < 1) and Forsterite (x = 1). For the metasilicate family, the general chemical formula is Mg$_x$Fe$_{(1-x)}$SiO$_3$ with further characterisations of Ferrosilite (x = 0), Orthopyroxene (0 < x < 1) and Enstatite (x = 1). Different compounds of PAH are also found as part of dust grains, however these and the orthosilicates and metasilicates families are not studied in this thesis, further details can be found in reference [74]. All in all, the chemically varying components make grains of various sizes, the largest ones being about 0.1 μm [70]. However, recently there has been a pull to re–think the size distribution of dust grains in order to include bigger grains [75,76]. The size and shape of the dust grains have been inferred from observational data as light passes through a dust cloud. An extinction curve can be modelled from the data of absorbed and scattered light as a function of wavelength by incorporating a grain size distribution. Also, considering how star light is not polarised, however becoming polarised as it travels through a molecular cloud gives an idea of the general ellipsoidal shape of dust grains [77].

The lifetime of the grains is not definitely known and varies depending on grain location and environment. Grains in molecular clouds near protostellar regions can be incorporated into the forming star. When a star dies and explodes, i.e. during SN events, the shockwave destroys anything within reach. Comet formation is believed to start with dust grains, and is another way dust grains are removed from molecular clouds and the remaining ISM. One estimate of grains’ lifetime reaches 5 billion years, spread over a specific cycle each lasting 100 million years. This cycle [70] is described below;

1) In the aCNM (diffuse clouds) the gas and dust grains are thinly dispersed. The dust is composed of a mix of SiO$_2$, carbonaceous and PAH species.
2) mCNM (dense clouds) is where atoms and molecules adsorb onto the dust grains forming an icy mantle. Dust grains can also clump together to form greater dust grain cores.
3) More complex organic molecules can be synthesised through energetic processing of the icy mantle.
4) As the dense cloud forms a protostar, most of the dust grains are scattered, however some can also form comet nuclei.

5) The dispersed dust grains re–enter the diffuse cloud media. This means more harsh radiation destroys the icy mantle.

6) Following stellar expansion as a star ages or a SN event, dust grains can be shattered along with any remaining organic molecules.

Further to this, dust grain in stellar systems are positively charged through processes including strong stellar UV fields, plasma charging and secondary electron emission of the dust grains [78, 79]. In the interstellar medium, dust grains can either be positively or negatively charged depending on environment. One factor in dust grain charging is the photoelectric emission of an electron as caused by energetic photons can excite electrons in the near–surface forcing them into the gas phase. This could be a process occurring in diffuse clouds due to the presence of VUV radiation and will leave the dust grain positively charged. In denser regions and without the presence of VUV radiation dust grains can become negatively charged due to bombardment of free electrons in the gas phase [77, 80].

1.4.3 Icy Mantle

As stated in the second step of the grain cycle above, an ice mantle is present on grains in the dense clouds of the ISM. These mantles are the second part of describing dust grain composition. The ice is thought mainly to be compact amorphous solid water (c–ASW) [81], and the mechanism for its formation is shown on Figure 1.6 [82] of which the first line comprising the pure O chemistry will be introduced in Chapter 3.

Figure 1.6 shows a great variety and method for the production of H₂O, all of which are possible in the ISM when considering the simple starting materials and energy sources. Various groups have studied the different aspects of this diagram such as O₃ formation [83–86] where hydrogenation leads to H₂O [87]. Direct hydrogenation of O atoms has also been studied going through stages of OH and H₂O₂ [88] of which the formation of H₂O₂ itself has also been investigated [89].
Figure 1.6: This diagram illustrates the formation routes of H$_2$O on a surface such as an interstellar dust grain. This figure is taken from [82].

No matter the formation pathway, when H$_2$O forms on interstellar dust grains, a typical ‘hit–and–stick’ ballistic deposition model is assumed leading to an unstructured network of H–bonds; an amorphous solid. The amorphous structure of ice in the ISM leads to changes in porosity, permeability, surface area and surface chemical activity as compared to crystalline solid water (CSW) [90]; porosity and permeability can be considered to be related as permeability changes with porosity. Temperature–Programmed Desorption (TPD) and Reflection–Absorption Infrared Spectroscopy (RAIRS) laboratory experiments looking at desorption of small molecules, acetone, ether, acetonitrile, chloroform and others, from ASW and CSW have been done. The results lead to the understanding that porosity, permeability and surface area do not have a major effect on adsorbate reactions, but the surface chemical difference plays a role. The reason for this is that H–bond capability decreases by a factor of six as the H$_2$O changes from ASW to CSW [90, 91].

The icy mantle of the dust grains in the ISM is “dirty” and the many other molecules coating the grains are made on the surfaces or stick to the surfaces from the gas phase. A diagram of a possible “dirty” ice covering a grain of dust can be seen on Figure 1.7 [92].
Figure 1.7: This cartoon illustrates a typical interstellar dust grain in the core of a molecular cloud. A mantle of a variety of molecules have adsorbed or accreted onto the silica surface of which H$_2$O is the dominant species. Also illustrated are various energy sources available for reactions, adapted from [92].

CH$_3$OH, CO$_2$, CO and CH$_4$ are some of the molecules known to be present in the ice coating the dust grains in the ISM, as shown in Figure 1.8 [93].

Figure 1.8: This spectrum is of an icy mantle showing the variety of molecules present. This is a spectrum from the Short Wavelength Spectrometer (SWS) of NGC 7538 IRS9 adapted from [93].
As can be seen in Figure 1.8, only dominant species and species with very distinct spectral features will be detected in an icy mantle. Also, IR inactive molecules such as O\textsubscript{2} and N\textsubscript{2} which are expected to be found in great concentrations in the ISM [94] cannot be observed in such spectra. Exact number densities of molecules are difficult to determine due to modes overlapping. Ultimately, the composition of the ice is impossible to determine through observational IR spectroscopy alone.

As the Voyager spacecrafts have just left the Solar system, scientists and researchers have naturally not been able to study the composition of dust grain and their mantle by any other means than telescopes. This means that only estimates of the relative abundances of molecules in an icy mantle have been made, but not how molecules are organised. The Onion model has been introduced as a way of visualising how an interstellar dust grain in a dense cloud is composed [95, 96]. This model refers to the bare dust grain being covered in a polar layer which itself is covered by an apolar layer. The terms polar and apolar in this case refer to the H–bond capability meaning that the polar layer is rich in H–bonds (such as H\textsubscript{2}O) and the apolar layer is poor (such as CO). Therefore, the Onion model proposes a pure layer of H\textsubscript{2}O covering the entire grain surface and molecules such as CO interacting with the surface of H\textsubscript{2}O, however not with the grain surface. This idea is understandable considering H\textsubscript{2}O being the dominant solid state species in the interstellar grain mantles. However, questions arise when considering the astronomical observations of Pontoppidan et al. [97] with a report of three CO features; two for bulk CO and a feature at 2136.5 cm\textsuperscript{-1} which was left unassigned. The work of Collings et al. [98] later noted that this feature matched experimental data for CO physisorbed on a SiO\textsubscript{2} surface. The same 2136.5 cm\textsuperscript{-1} feature could also be CO mixed with CH\textsubscript{3}OH [99] as this is the final product after hydrogenations reaction. Further experiments with a sub–monolayer of H\textsubscript{2}O on SiO\textsubscript{2} have shown that H\textsubscript{2}O seems to move from isolated molecules to clustered groups at similar cryogenic temperature as found in dense clouds [98, 100]. The idea of this Onion model will be further investigated in Chapter 4.

As seen in the life–cycle of a dust grain in a dense cloud, a multilayer of ice will naturally be formed coating this grain core. Dust grain charges have been mentioned previously and the icy mantle can be charged when excited by one of the energy sources also mentioned. However, the molecular layers of specific species can possibly also produce a noticeable surface charge in the dense regions of the ISM. This can occur
through a spontaneous electric field created as certain dipolar molecules [101–109] such as CO are deposited onto the dust grain [110–112]. This will be discussed in more detail in Chapter 5.

1.4.4 Surface Chemistry

As stated earlier, the amount of chemical reactions on surfaces in the ISM is minor compared to gas phase chemistry, but their role is crucial. The importance of dust has been known for a long time [11], but all reaction processes are not known. General reaction pathways are known for model systems and as are possible desorption mechanisms of molecular species after formation. Studying specific reactions will allow for an understanding of chemical processes in molecular clouds, explaining abundances of molecules and possibly clarifying the origins of unknown spectroscopic features observed in the ISM.

In general three different pathways are considered when referring to dust grain surface chemistry: these are the Langmuir–Hinshelwood (L–H), the Eley–Rideal (E–R) and the Harris–Kasemo (H–K) mechanisms which is also known as the Hot Atom mechanism [113].

The L–H mechanism concerns molecules (A and B) firstly adsorbing onto the surface. When the reagents (A and B) diffuse and meet, a bimolecular reaction occurs and the product (C) can desorb from the surface if enough energy is present [72], as represented schematically on Figure 1.9. Naturally, the atoms or molecules adsorbing onto the surface might not meet and if they do, they might not react, also A and B might desorb again if they possess enough energy to overcome the adsorption barrier.

![Figure 1.9](image) The Langmuir–Hinshelwood mechanism, illustrating how atoms or molecules adsorb, diffuse, react and desorb on a surface. As can be seen, both species must be present in the surface.
The E–R mechanism depicted in **Figure 1.10** revolves around one chemisorbed or physisorbed atom or molecule already being present on the surface (B). A second atom or molecule (A) in the gas phase reacts with B, while A never interacts with the surface [72].

![Figure 1.10](image)

**Figure 1.10**: The Eley–Rideal mechanism, illustrating how one gas phase species only interacts with an adsorbed molecule to create a new species. The gas phase molecule does not come into contact with the surface at any point.

Both processes above (L–H and E–R) are reversible, possibly leading back to dissociation of molecules into atoms or molecular fragments. When considering the reverse of these reactions, a third mechanism is possible. This process is the H–K mechanism and starts with molecular dissociation. The reverse of the L–H process leads to two species both adsorbed on the surface before molecular formation. The reverse of the E–R mechanism is a molecule breaking into two species where one is adsorbed and the other is in the gas phase. This gas–phase molecule can be high in energy and is now termed a ‘hot atom’ which might not be released into the general gaseous environment, but can be trapped and can easily diffuse in the ice lattice [114]. This hot atom can now take part in a traditional L–H or E–R mechanism. A general diagram of the H–A mechanism is shown below, **Figure 1.11**.

![Figure 1.11](image)

**Figure 1.11**: The Harris–Kasemo mechanism can be thought of as one part reverse E–R and one part L–H mechanisms. A molecule breaks apart on the surface creating one fragment with excess energy (B) which can diffuse on or in an ice lattice. This hot atom can then react with other molecules to produce (E).
1.5 Thesis Overview

Throughout this chapter, references to later chapters have been introduced. These chapters span three regions of the dust grain cycle from bare dust grains to icy films. Preliminary results about one of the H$_2$O formation pathways will be discussed, then how small quantities of H$_2$O behave on a model interstellar grain surface before studying bulk films as found on the dust grain surfaces. A more detailed account of this has been listed below:

- **Chapter 2** will only focus on the experimental theory, equipment and techniques used to obtain results presented in the later chapters.

- **Chapter 3** is the chapter to start a more detailed discussion of how H$_2$O is formed on a SiO$_2$ surface at about 20 K which acts as a model interstellar dust grain. These results are currently preliminary, however initial results have shown the formation of O$_2$ and O$_3$ from an atomic O beam. To investigate these reactions temperature programmed desorption (TPD) and reflection–absorption infrared spectroscopy (RAIRS) were utilised.

- **Chapter 4** discusses the next step in the grain cycle. Now H$_2$O has begun to form on the surface and this chapter will investigate the movement of a sub–monolayer coverage H$_2$O on a SiO$_2$ surface. The Onion model suggests that H$_2$O covers the grain surface, however experimental results indicate that the barrier for H$_2$O to de–wet on a silica surface are negligible. This means H$_2$O forms islands even in the coldest parts of a molecular cloud leaving bare dust grain surfaces exposed for other molecules to bind and interact with. The results of these experiments were obtained by use of RAIRS.

- **Chapter 5** investigates the multilayers of interstellar dust grains. Multilayers amounts of CO on SiO$_2$ and a variety of H$_2$O are studied through RAIRS, however before this N$_2$O is studied to set a precedent. N$_2$O has already been shown to harbour a surface potential which in this chapter is studied indirectly through observations of the longitudinal optical and transverse optical splitting as it changes with temperature. Multilayers of CO are then studied with the same technique and view–point to determine the extent and implications of a possible surface potential in such films on interstellar dust grains.

- **Chapter 6** will only look at the conclusions from Chapters 3, 4 and 5 while also discussing various and possible future experiment.
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Chapter 2

Experimental Theory, Equipment and Techniques

Contents of this chapter

2.1 Introduction ........................................................................................................... 37
2.2 Surface Science ..................................................................................................... 37
2.3 Equipment ............................................................................................................. 40
   2.3.1 Instrumentation .............................................................................................. 40
   2.3.2 Cryostat and Sample ...................................................................................... 42
   2.3.3 Silica Deposition ............................................................................................. 44
   2.3.4 Background Deposition .................................................................................. 47
   2.3.5 Atomic Beams ................................................................................................. 48
      2.3.5 (a) Introduction ............................................................................................ 48
      2.3.5 (b) Equipment ............................................................................................. 50
      2.3.5 (c) Beam Flux and Cracking ....................................................................... 53
2.4 Experimental Technique ....................................................................................... 60
   2.4.1 Temperature Programmed Desorption (TPD) ................................................. 60
   2.4.2 Reflection-Absorption Infrared Spectroscopy (RAIRS) ................................. 65
      2.4.2 (a) Longitudinal Optical–Transverse Optical (LO–TO) Splitting .......... 67
2.5 The Spontelectric Effect ....................................................................................... 70
2.5 Kinetic Simulations ............................................................................................... 74
2.6 References ........................................................................................................... 75
2.1 Introduction

Following observations from the astronomical community, models have been built to interpret and reproduce the observed abundances of atoms and molecules. The multitude of equations describing the chemistry and physics occurring throughout the Universe, such as those used in UMIST database (University of Manchester Institute of Science and Technology) [1], are only as reliable as the kinetic information fed into them. These values can, to some extent, be supplied from laboratory experiments. The focus in Chapter 1 was mostly on dark molecular clouds where pressures are higher and temperatures are lower as compared to the diffuse interstellar medium. These surfaces, as explained, play a crucial role with regards to the formation of molecules such as H₂, H₂O, NH₃ etc. [2, 3] and for that reason the experiments conducted in this thesis are of a surface science nature using interstellar dust grain analogues as the substrate surface.

2.2 Surface Science

In essence, surface science can be summarised by Figure 2.1.

Figure 2.1: The Propst diagram shows what surface science processes are possible and studied in various fields of physical sciences. The main aspects of interest for this work are; electric fields, heat and neutral species.

Figure 2.1 shows a Propst diagram which indicates the fields of interest when conducting experiments on any chosen surface. Chemical species, be they atoms, molecules or radicals, neutral or charged, can be deposited onto a surface. On the surface, the species can be analysed, probed and perturbed before being released to the gas phase. For the sake of this work, the only focus will be on deposition of neutral molecules and atoms, interactions with an electromagnetic field as they are analysed through infrared spectroscopy and thermally heating the species until they desorb where a quadrupole mass spectrometer will detect them in the gas phase above the surface.
In general, surface science experiments are aimed at determining what processes happen on a surface (e.g. adsorption mechanisms, reactions, diffusion etc.). Analysing the adsorbed molecules can be complemented by the information gathered when molecules desorb in the gas phase due to the microscopic reversibility principle.

Initially, a gas phase species hits a surface where it can either be reflected or accommodated. The rate at which gas phase species collide with a surface, the wall collision rate, $Z_w$, is given by \textbf{Equation 1}.

$$Z_w = \frac{P}{\sqrt{2\pi mk_BT}}$$

where $P$ is the total pressure of the gas, $m$ is the molecular mass of the chemical species, $k_B$ is Boltzmann’s constant and $T$ is the absolute temperature of the gas. With \textbf{Equation 1}, the time it takes for a complete monolayer equalling $10^{15}$ molecules cm$^{-2}$ \cite{4} to form covering the entire 6 cm$^2$ sample surface can be calculated with the results presented in \textbf{Table 2.1}. This calculation has been done with N$_2$ as this is the greatest component of air and by assuming that the temperature of the surface is low enough to allow all incident molecules to stick.

<table>
<thead>
<tr>
<th>Pressure / mbar</th>
<th>Approximate Time / s</th>
</tr>
</thead>
<tbody>
<tr>
<td>$10^{-3}$</td>
<td>$3.5 \times 10^{-3}$</td>
</tr>
<tr>
<td>$10^{-7}$</td>
<td>35</td>
</tr>
<tr>
<td>$10^{-10}$</td>
<td>$3.5 \times 10^4$</td>
</tr>
<tr>
<td>(Experimental Conditions)</td>
<td>($\sim 10$ Hrs)</td>
</tr>
<tr>
<td>$10^{-12}$</td>
<td>$3.5 \times 10^6$ ($\sim 1000$ Hrs)</td>
</tr>
</tbody>
</table>

\textbf{Table 2.1}: Indicating the approximate times taken for a complete monolayer to be formed at a given pressure. In general, it indicates how long a surface remains clean at a certain pressure. The calculations have been done for N$_2$ and times will vary depending on the molecule of interest.

The astrochemical surface science experiments that will be described later were done in the ultrahigh vacuum, UHV, region at a base pressure of $1 - 5 \times 10^{-10}$ mbar. \textbf{Table 2.1} presents a time of about 10 hours for one ML of N$_2$ to form on the surface, stressing the importance of using UHV pressures to keep the surface clean throughout an experiment.
The values in Table 2.1 were calculated with N\textsubscript{2} as this is one of the main contaminants in an ultrahigh vacuum system. H\textsubscript{2} is the most abundant molecule in a UHV due to outgassing from stainless steel surfaces, but as the temperature of the surface is too high for H\textsubscript{2} to stick to it, and as H\textsubscript{2} does not react with the surfaces used or molecules introduced, contamination of H\textsubscript{2} can be disregarded.

The values calculated from Equation 1 and presented in Table 2.1 were obtained with an assumed sticking coefficient of unity, meaning that every molecule striking the surface will adsorb on it; however this is not always the case. The sticking coefficient, \( S \), can be defined in different ways, one way is as in Equation 2 and where \( S_0 \) is the initial sticking probability of the species incident on a surface and \( \theta \) is the molecular coverage;

\[
S = S_0(1 - \theta).
\]  

Equation 2

Measuring the sticking coefficient of molecules can be done by the classic King and Wells experiment [5]. These experiments involve directing a beam of gas–phase species towards a surface, obstructing the beam path to the surface is a flag. This flag prevents molecules from sticking to the surface leading to a background pressure of the given molecule which can be measured with a mass spectrometer. When the flag is removed the molecules will bombard the surface onto which they can possibly stick, leading to a drop in the mass spectrometer counting rate. The drop allows the determination of \( S \).

Another way of thinking about \( S \) is one that relates to the rate of adsorption (\( v_{ads} \)) and the rate of collision and can be describe as below in Equations 3 and 4:

\[
S = \frac{v_{ads}}{Z_w};
\]  

Equation 3

\[
v_{ads} = \frac{k_t}{1 + \frac{k_d}{k_a}}.
\]  

Equation 4

The variables \( k_t \), \( k_d \) and \( k_a \) are rate constants for trapping, desorption and adsorption respectively. Trapping refers to the intermediate state of a molecule between the gas phase, desorbed, and being adsorbed to the surface.
Another factor to consider when mentioning molecules adsorbing to a surface is the accommodation coefficient ($\alpha$). $\alpha$ is concerned with the ability of atoms and molecules effectively transferring their thermal energy to the surface. If the transfer is efficient, the species will not have enough energy to be reflected from the surface, but will instead be adsorbed. The thermal accommodation coefficient is defined as seen in Equation 5:

$$\alpha = \frac{T_f - T_i}{T_s - T_i}$$

where $T_i$ is the initial temperature or energy of a molecule before a collision with the surface while $T_f$ is the temperature of the molecule after a surface collision. $T_s$ is the temperature of the surface on which the gas-phase molecules collide. When $\alpha = 1$, all species are accommodated onto the surface and are adsorbed, whereas when $\alpha = 0$, no species are accommodated.

Now that molecules have stuck and been accommodated on the surface, two processes with regards to the interaction of the molecule to the surface can happen, chemisorption or physisorption. The two can broadly be regarded as extreme forms of adsorption. Chemisorption is associated with strong, typically in the hundreds of kJ mol$^{-1}$ [6], short range interactions where electrons are shared between adsorbate and surface. In chemisorbed systems, a bond between the surface and adsorbate can be thought to exist as a traditional covalent bond where the electrons are shared between atoms in a molecule. The bond can also be an ionic bond where an electron has been transferred from one molecule to the other. Physisorption does not involve electron sharing or transference between the adsorbate and surface, the interactions are of a van der Waals nature with typical values in the tens of kJ mol$^{-1}$ [6]. Physisorbed species are the types of systems of interest in this work.

2.3 Experimental Equipment

2.3.1 Instrumentation

This section discusses how the theory is put into action to simulate the environment found in a molecular cloud and the surface used as an analogue of interstellar dust grain. Literature regarding of the UHV rig can also be read elsewhere [7, 8]. Figure 2.2 shows a general picture of the UHV rig and Figure 2.3 shows the schematic.
In general, the requirements for surface science in a UHV system are few; a chamber is needed with pumps to create the vacuum, a sample is necessary to deposit the desired molecules onto in order to investigate and analyse the surface processes through whichever desired technique.

The central component of the UHV setup is a 30 cm diameter stainless steel chamber (Instrument Technology Ltd.). To evacuate the chamber, three different kinds of pumps are used; A mechanical rotary pump (Edwards High Vacuum International, E2M18) which backs a liquid nitrogen trapped 6” diffusion pump (Edwards High Vacuum International, E06), additionally a liquid nitrogen trapped titanium sublimation pump (AML, TSP2) is used to reduce the residual oxygen–containing species in the gas phase. A gate valve separates the diffusion and sublimation pumps. A nude hot cathode ionization gauge (Instrument Technology Ltd.) with thoria filaments calibrated to $\text{N}_2$, is used to measure the pressure inside the chamber. The operational pressure range of this ion gauge is $10^{-4} – 10^{-11}$ mbar.
Figure 2.3: A detailed sketch of the UHV rig used for this work. The atomic beams have not been shown, but will be detailed later in 2.3.5. The sketch is not to scale.

2.3.2 Cryostat and Sample

The sample used until this point in time is a copper substrate coated with a layer of silica. The sample is fixed at the end of a cold finger manipulator with XYZ translations and a virtual rotation of 360° about the Z axis, Figure 2.4. The cold finger itself is a 1 m long stainless steel tube connected and cooling the sample through a closed–cycle helium cryostat (APD Cryogenics, HC–2). The cold finger is surrounded by a 1 m long gold coated oxygen free high conductivity copper tube acting as a cryoshield (this is only cooled through the first stage of the cryostat). The reason for the cryoshield is to create a cryogenic microenvironment around the cold finger and sample mount lessening radiative thermal gain from the surrounding environment. The sample, Figure 2.5, is regularly cooled to below 20 K. Inside the copper sample block, a cartridge heater (Heatwave Labs Inc., TB–175) is placed which is used to heat the sample surface. To measure the temperature two KP–type thermocouples are used. A KP–type thermocouple is made of two wires, gold and chromel (90% Ni and 10% Cr), with the connecting junction where the temperature needs to be measured. One KP thermocouple is located directly on the sample and the other at the bottom of the cold finger. The reason for the KP thermocouple on the cold finger is to monitor when the sample mount
and cold finger are heated enough to allow desorption which could interfere with the species of interest desorbing from the sample.

Figure 2.4: A sketch of the entire manipulator with the closed–cycle He cryostat cooling the sample to a minimum base temperature observed for this work of 17 K. The sample has XYZ translations and a virtual 360° rotation.

Figure 2.5: The sample itself located at the end of the cryostat. The Cu block is coated with SiO₂ and a cartridge heater selectively heats only the sample block. Two KP-type thermocouples register the temperature throughout experimental work.

2.3.3 Silica Deposition
As will be explained later in this chapter, using a bare metal surface will mean that the metal surface selection rule (MSSR) is in full effect. For this reason, the TO mode of the LO–TO splitting will not be observed; as will also be explained later. Therefore a film of SiO$_2$ is deposited onto the Cu surface to lessen the MSSR, another reason is for the surface to mimic a bare interstellar dust grain.

Before SiO$_2$ deposition, the sample has to be cleaned from potential contaminants. This was done by roughly polishing the surface with a 1 μm grain size water/oil emulsion diamond paste (1–KD–C1, Kemet International Ltd.) on a polishing pad, before another 1 μm grain size water based diamond paste was used (1–W–C2, Kemet International Ltd.) on a different polishing pad of the same grain size. At the end of this procedure a mirror finish to the Cu was obtained. Electron beam evaporation of SiO$_2$ straight onto clean Cu was attempted, however a controlled amount of SiO$_2$ was difficult to obtain. SiO$_2$ deposition on stainless steel surfaces is possible and has been done previously in this research group [9–11]. Expecting a stronger interaction with Cu if the surface was not clean, but rather oxidised, meant the clean, polished Cu surface was oxidised with a 1:1 ratio 2 mol dm$^{-3}$ HNO$_3$ and distilled H$_2$O. A filter paper was slightly wetted (a couple of drops from a glass pipette) with the mixed solution and the polished Cu surface was placed onto the moist filter paper. This changed the mirror finished Cu surface to an oxidised matt surface. The sample block was then transferred to a different vacuum chamber for the electron beam evaporation of SiO$_2$ onto the oxidised Cu. A schematic and picture of the chamber can be seen in Figure 2.6.

The chamber consists of a liquid nitrogen cooled 6” diffusion pump (Edwards High Vacuum International, E06) backed by a rotary pump (Edwards High Vacuum International, E2M18) capable of pumping down the chamber to a high vacuum of about 10$^{-6}$ mbar as measured with an ion gauge. The chamber is not baked between transferring samples inside, leaving a background contamination of H$_2$O. This meant that the surface of the sample is further changed from pure SiO$_2$ to having a coating surface of silanol, SiOH, groups. Inside the chamber an ingot of SiO$_2$ quartz was placed in a receptacle with the oxidised Cu surface placed directly above it, a picture of this can be seen in Figure 2.6.
Figure 2.6: To the left is a schematic of the SiO$_2$ deposition chamber reaching base pressure of $10^{-6}$ mbar. To the right is a picture of the chamber as viewed from the left side of the rig. The SiO$_2$ is placed in the path of an electron beam which evaporates it, the sample is positioned directly above the SiO$_2$ and the rate of deposition is monitored by a QCM.

After reaching a base pressure in the $10^{-6}$ mbar range, the quartz crystal microbalance, measuring deposition rate, was configured for SiO$_2$ quartz. Configurations in terms of an impedance factor of 8.25 and a density of 2.2 g cm$^{-3}$ [12] were set before the electron beam evaporation was started. The QCM was placed in close proximity to the sample to ensure a simultaneous and similar growth rate of SiO$_2$ on both surfaces. Using a mA current, the layer thickness was monitored and a thickness of 300 nm SiO$_2$ was obtained on the QCM and therefore also on the surface of the oxidised Cu.

The newly coated sample blocks were then transferred to the UHV system described earlier where a RAIRS scan was done in an attempt to observe the longitudinal optical and transverse optical (LO–TO) splitting of SiO$_2$ (a more detailed description of the LO–TO splitting will follow in Chapter 5). The results of this have been shown in Figure 2.7 where a clear change is observed in the SiO$_2$ νSiO stretching mode peak position at 1241 cm$^{-1}$ [13] as compared to the spectra of pure Cu (experiments here were done with a resolution of 1 cm$^{-1}$).

The deposition procedure allows for two samples to be coated with SiO$_2$ at a time. A simple method to check whether SiO$_2$ has been deposited onto Cu can be done without
Figure 2.7: Two background spectra showing the difference between a clean Cu sample, black, and one with SiO$_2$, red, deposited onto it. The 1241 cm$^{-1}$ feature is the LO mode and the 1065 cm$^{-1}$ is the TO optical mode of SiO$_2$.

the use of an analytical technique such as IR spectroscopy. Droplets of liquid H$_2$O on SiO$_2$ will wet the surface, whereas it will form clusters on Cu. The results of this can be seen in Figure 2.8 where the e$^{-}$ beam evaporation of SiO$_2$ onto Cu only managed to coat part of the surface.

Figure 2.8: This shows a simple test to verify if a layer of SiO$_2$ has been deposited, where droplets of H$_2$O appear to wet SiO$_2$ and clusters on Cu. The cloudy material on the left side of the sample is SiO$_2$ which has not stuck properly to the sample and would not be used in the UHV rig, however for the H$_2$O test this will suffice.
As can be seen, the gray patch is SiO$_2$ where the H$_2$O is barely visible as it has spread over the surface in contrast to the right side of the picture where clusters have formed. This is due to the hydrophilic and hydrophobic nature of SiO$_2$ and Cu, respectively, with respect to liquid H$_2$O. This is the macroscopic behaviour of H$_2$O on Cu and SiO$_2$, however the microscopic viewpoint of solid H$_2$O on SiO$_2$ will be discussed in Chapter 4.

2.3.4 Background Deposition

To introduce the desired chemical species into the UHV chamber, two fine–control leak valves (VG Ltd.) are used. Reagents are in glass bulbs or vials linked to the leak valves through a glass gas handling line under rough vacuum, picture in Figure 2.9.

![Figure 2.9: A diagram showing the connection of the dosing lines to the leak valves of the UHV chamber. The lines are regularly evacuated and a small volume of gas or vapour containing the molecules of interest is expanded into the dosing bulbs for experimental use.](image)

A general clean of the gas lines is done daily with the species to be used for experiments by expanding a small volume of gas or vapour into the gas handling line before pumping it out again. This procedure is repeated in triplicate. If the compound used is a
liquid, such as H$_2$O, several freeze–pump–thaw, FPT, cycles may be done prior to the gas clean. FPT cycles are done by freezing the liquid with liquid nitrogen, then opening up for the pump to pump directly on the newly formed solid. As the solid thaws, the pressure slowly increases and more volatile contaminants are pumped away. The solid is then isolated from the pump and left to thaw until becoming a liquid again, this process is also done thrice.

The dosing bulb(s) is(are) then filled with the desired chemical species and deposition can be done through the leak valve(s). When dosing a certain species, the exposure of the surface to the gas needs to be controlled. In surface science, the exposure of a surface to an adsorbant is measured in Langmuir, L. The definition of 1 L is a pressure of $1.33 \times 10^{-6}$ mbar ($10^{-6}$ Torr) for a period of 1 second. The ionisation coefficient ($\gamma_i$) is important when dosing a gas. The ionisation coefficient is the amount of ionised fractions of one molecule of the gas species after it has been ionised by the electrons emitted by the filament of an ion gauge. $\gamma_i$ has been accounted for in all experiments through the work of Bartmess and Georgiadis [14] and the coverages used are representative of true Langmuir units. Through experimental measurements the exposure in L can be reported in terms of monolayers, ML.

2.3.5 Atomic beams

2.3.5 (a) Introduction

Any molecule can be broken down into its atoms if enough energy is supplied. The easier a molecule is to ionise and the lower the bond dissociation enthalpy is, the lower the energy needed to break it down will be. O$_2$, as used for the atomic beam in this work, is relatively easy to form even though it has a bond dissociation enthalpy of 497 kJ mol$^{-1}$ [15] due to the double bond. Forming an O atom plasma can not only be done through radio frequency, RF, sources as in this work, but microwave, MW, sources can also be used and a carrier gas, such as He or Ar, can be used if desired [16]. The dissociation fraction of O$_2$ in MW sources can range from 8 – 12% [17] to 45 – 80% [18] depending on O$_2$ pressure and power of the source. RF sources can produce a dissociation fraction of O atoms of the order of 25% [19] which is similar to the previously determined cracking fraction of the RF sources used in this thesis (32% ±
As stated earlier, energy is needed to make the desired atomic fragments from a molecule. **Figure 2.10** shows the potential energy diagram of O₂ and its dissociation.

Looking at **Figure 2.10** above, different excited states can be seen, all originating from the ground state O₂, X³Σ⁻, and rising through the shaded area [20]. The aim of this work is to obtain ground state O atoms, ³P, through the RF sources with minimal contamination with other species, the region where O(³P) is formed is labelled I and is marked with a red circle in **Figure 2.10**. The simple solution would be to supply a gas of O₂ with 5.16 eV (497 kJ mol⁻¹) of energy to simply split the molecule, however, this transition is spin forbidden. For this reason O₂ firstly needs to be promoted to the high energy level of the excited state, c¹Σ⁺, *via* a 6 eV transition, the system can then relax to the dissociation limit yielding the desired O(³P). A Grotrian diagram of the electronic
transitions in the O atom [21] can be set up to show all the transitions and the transition observed in this work, Figure 2.11.

![Figure 2.11: Grotrian diagram for O showing all the electronic transitions possible. With the plasma source on, the $^3P \rightarrow ^3S^0$ transition, labelled as OI IR3 to the left of the diagram, is the strongest.](image)

The x–axis shows the various states of the O atom with the ground state being the $^3P$. The transition from $^1D$ to $^3P$ is forbidden (marked as [OI] in red), but no evidence of $^1D$ being formed was observed so this can be disregarded. The other red line, OI IR3, is the transition from $^5P$ to $^5S^0$ which is the main observed transition with the RF sources used in this work.

### 2.3.5 (b) Equipment

The plasma source used for this work, radio frequency, RF, plasma source (RF OSPrey, Oxford Scientific, now SPECS) are powered by units (Cesar 136, Dressler) capable of working at an operational frequency of 13.56 MHz and a maximum power of 600 W. A plasma source for H atoms has also been fitted to the UHV rig, however this source was not used for this work and will therefore not be discussed. Figure 2.12 shows how both beam systems are attached to the rest of the UHV rig.
Figure 2.12: A general schematic of the atomic beam sources and their overall construction. The source to the left is for the production of O atoms while the right side is for H atoms (not used in this work). The UHV chamber is as follows from Figure 2.2.

Pictures of the plasma tube can be seen in Figure 2.13 and a closer look at the O atom plasma source itself with the manual tuning unit is shown in Figure 2.14.

Figure 2.13: To the left is a picture of the plasma tube during reconstruction. The white discs, made of alumina so as to minimise O atom recombination after cracking, hold in place the aperture disc. The 5-hole grid in the centre of the aperture disc allows for the O beam to pass. The right picture is of the fully assembled plasma tube.
Figure 2.14: A sketch of the entire O atom plasma source. The inductively coupled radio frequency source sparks the O$_2$ gas when enough power is supplied. The air capacitors are to contain and focus as much power as possible towards the molecular gas. A fiber optic cable records the plasma emission in real time by a spectrometer.

The white rings in Figure 2.13 are an alumina ceramic and the inside of the plasma tube and chamber has been coated in a similar material to minimise O atom reactions or recombination with surfaces.

The beam is effusive and thermal as there is no adiabatic expansion of the gas or plasma, for that reason the temperature of the gas is believed to be 300 K. The air capacitors in the manual tuning unit in Figure 2.14 are rotatable by 360°. They are adjusted to reach a minimum of reflected power leading to a desired real power level to spark and maintain the atomic plasma through the inductively coupled RF coil. This in turn means using less “forward” power to obtain a “real” wattage and so reducing the risk of overheating or shorting of the system. A setting of 315° and 90° for the left and right air capacitor, respectively, was found to be optimal. With the real power set to 105 – 110 W, O$_2$ was leaked into the plasma chamber to a pressure of 1.0 – 1.1 × 10$^{-5}$ mbar as measured by an ion gauge (Edwards High Vacuum International). At this point a gate valve is the only separation between the plasma chamber and the central chamber with the sample in line of sight with the effusive beam. When the gate valve is fully open a certain amount of gas will flow into the main chamber due to the pressure
gradient, the pressure being $10^{-5}$ mbar in the plasma chamber compared to $10^{-10}$ mbar in the main chamber.

### 2.3.5 (c) Beam Flux and Cracking

The flux of the atomic beam can be calculated by pump–down curves. These experiments were conducted at normal experimental pressure conditions with the cryostat at room temperature to cancel the effect of cryopumping. The gate valve was opened for about 30 seconds, then closed and the process was repeated five times with the QMS running continuously monitoring m/z = 32. Figure 2.15 shows the QMS trace with time.

**Figure 2.15:** The pump–down curve used to assess the beam flux when for O atom experiments. The rise in the MS counts of m/z = 32 is due to the gate valve, separating the plasma chamber and the central UHV chamber, being opened. The count rate is allowed to stabilise and the red line shows the gate valve being closed and the O$_2$ pumped out of the central UHV chamber. The experiments were done with a room temperature cryostat.

The counts were converted to pressure which was done by background leaking O$_2$ into the chamber at fixed pressures of $1 \times 10^{-8}$, $5 \times 10^{-8}$, $1 \times 10^{-7}$, $5 \times 10^{-7}$ and $1 \times 10^{-6}$ mbar with the QMS monitoring the signal. A linear relationship between pressure and QMS signal leads to a simple conversion of use for the next step in the calculations. Looking at the individual pumping steps, marked in red in Figure 2.15 above, and setting them to a time of zero leads to Figure 2.16 (now with pressure instead of MS counts) where
the decrease in signal is due to the gate valve having been shut and molecules evacuated from the chamber by the diffusion pump.

Figure 2.16: The result of the pump down curves form Figure 2.15 when the MS counts have been converted to pressure, \( P \), and each pumping curve has been set to zero to allow for individual and simple analysis.

The linear analysis of the experimental pump down curves is done using Equation 7:

\[
\ln(P) = -C_m t + \ln(P_0)
\]

where \( P \) is the pressure, \( C_m \) is the pumping coefficient and \( t \) is the time. Table 2.2 has been set up with the values of \( \ln(P_0) \) and \( C_m \).

<table>
<thead>
<tr>
<th>Run number</th>
<th>( \ln(P_0) )</th>
<th>( C_m / \text{s}^{-1} )</th>
</tr>
</thead>
<tbody>
<tr>
<td>First</td>
<td>(-12.26 \pm 0.05)</td>
<td>(-1.28 \pm 0.02)</td>
</tr>
<tr>
<td>Second</td>
<td>(-12.23 \pm 0.04)</td>
<td>(-1.29 \pm 0.02)</td>
</tr>
<tr>
<td>Third</td>
<td>(-12.11 \pm 0.05)</td>
<td>(-1.23 \pm 0.02)</td>
</tr>
<tr>
<td>Fourth</td>
<td>(-12.28 \pm 0.04)</td>
<td>(-1.22 \pm 0.02)</td>
</tr>
<tr>
<td>Fifth</td>
<td>(-12.03 \pm 0.04)</td>
<td>(-1.24 \pm 0.02)</td>
</tr>
<tr>
<td>Average</td>
<td>(-12.18 \pm 0.04)</td>
<td>(-1.25 \pm 0.02)</td>
</tr>
</tbody>
</table>

Table 2.2: This table shows the values for the intercept, \( \ln(P_0) \), and the gradient, \( C_m \), as obtained from the pump-down curves from Figure 2.16.
Using the average values of $P$ and $C_m$ (and considering $C_m$ as being positive due to Equation 7), Equation 8 can be used to calculate the beam flux, $F_{Beam}$.

\[
F_{Beam} = \frac{VC_mP_0}{k_BT_{A\text{beam}}}
\]

where the volume of the chamber, $V$, is estimated to be 0.075 m$^3$ and the area of the beam, $A_{beam}$, is $2 \times 10^{-5}$ m$^2$ [8], $k_B$ is the Boltzmann constant and the temperature, $T$, as explained earlier is assumed to be 300 K. The flux of the beam is thereby calculated to be about $5.8 \pm 0.4 \times 10^{14}$ molecules cm$^{-2}$ s$^{-1}$.

From here, the ML formation time can be found by conducting temperature programmed desorption, TPD, experiments as discussed in detail in section 2.4.1. An average heating rate of 0.20 K s$^{-1}$ indicates that dosing the molecular oxygen beam for 5 – 10 minutes on a SiO$_2$ surface held at 17 K yields one ML.

![Figure 2.17](image)

**Figure 2.17**: The temperature programmed desorption of O$_2$ beam dosed onto the sample indicate ML formation between 5 – 10 minutes. The beam flux and nature of the surface have effects on the monolayer formation time.

What Figure 2.17 above shows, as will be detailed later, is that the sub–monolayer grows into a monolayer with increasing coverage as can be seen by the different desorption behaviour when comparing the black trace to the other three traces. The typical behaviour of multilayer desorption can be seen in the 10, 14 and 20 minute
traces where the leading edges begin to align. This is indicative of zero order desorption which is associated with multilayer desorption.

Turning the power units on to 105 – 110 W cracks a certain fraction of the molecular oxygen into the atoms where the main band at 777 nm, Figure 2.18, was monitored in real–time by a fiber optic cable linked to a spectrophotometer (USB4000, Ocean Optics) and monitored with SpectraSuite (Ocean Optics). The power and pressure were set as they were to obtain an intensity of the O\(^3\)P of 5.5 – 6.0 \times 10^4 counts as seen in Figure 2.18, counts above this value approach the saturation limit of the spectrophotometer.

![Graph showing spectra of the O atom plasma](image)

**Figure 2.18:** This shows the generally obtained spectra of the O atom plasma as monitored through the fiber optic cable linked to the manual tuning unit (see Figure 2.14). The minor peaks correspond to various transitions of O atoms, with a slight contamination of OH, but the strongest signal is observed at 777 nm, corresponding to the (3p \(^5\)P) \rightarrow (3s \(^5\)S) transition in the O atom.

The peaks observed in the spectrum above, Figure 2.18, can be correlated with the Grotrian diagram, Figure 2.11, and the transitions with their wavelength have been summarised in Table 2.3. As can be seen, an OH transition is observed indicating a form of contamination with a source of H, possibly H\(_2\)O. The fraction of impurity was considered minimal when compared to the main transition observed at 777 nm.

This level of counts, pressures and power is consistent with the high brightness mode of O plasma [23].
### Table 2.3: O atom transitions with the corresponding emission peak from the spectrometer [16, 22]. The 777 nm transition is the strongest signal with the supplied energy as measured by the fiber optic cable linked to the spectrophotometer.

<table>
<thead>
<tr>
<th>O atom transition</th>
<th>Emission Peak / nm (± 1)</th>
</tr>
</thead>
<tbody>
<tr>
<td>OH transitions (OH(A₂Σ⁺ → X₂Π))</td>
<td>309</td>
</tr>
<tr>
<td>(4p superscript 3P) → (3p superscript 5P)</td>
<td>437</td>
</tr>
<tr>
<td>(5d superscript 5D) → (3p superscript 5P)</td>
<td>532</td>
</tr>
<tr>
<td>(4d superscript 5D) → (3p superscript 5P)</td>
<td>615</td>
</tr>
<tr>
<td>(5s superscript 3S) → (3p superscript 5P)</td>
<td>645</td>
</tr>
<tr>
<td>(3p superscript 5P) → (3s superscript 5S)</td>
<td>777</td>
</tr>
<tr>
<td>(3p superscript 3P) → (3s superscript 5S)</td>
<td>845</td>
</tr>
</tbody>
</table>

The simplest way to determine the cracking fraction of O₂ into O is by having the QMS in line–of–sight with the beam. This was done when the sources were first installed where a cracking fraction of 32% ± 9% [8] was reached, since then the plasma source has been repaired following a breakdown. Experiments to verify that the cracking fraction is the same were done by a two–fold check; one where the O beam was simply dosed into the chamber to monitor the fraction of O:O₂ and another experiment where O₂ and O beams were separately dosed onto the sample.

Looking at the first experiments where the beam was dosed into the chamber; comparing the QMS counts for m/z = 16 and 32 when the O atoms beam on and off, **Figure 2.19**, we get a preliminary cracking fraction of about 20% O to O₂.

As can be seen in **Figure 2.19**, the initial increase in the QMS counts is due to the gate valve being opened. At this stage, indicated by the blue vertical line, the fraction between m/z = 16 and 32 is about 36%. This is the natural cracking pattern for this mass spectrometer with the set multiplier value of 2500 V. The pressure and therefore QMS counts are allowed to stabilize, plateau, before the plasma source is turned on, at which stage the QMS counts increase due to the sudden increase in energy supplied to the O₂ molecules. At this stage, marked with a green vertical line, the percentage has changed to 43%. This means that the plasma source has created what amounts to 7% pure O atoms. As the source warms up and reaches operational conditions after two to three
hours, the percentage has changed to 56%, meaning about 20% of the O₂ molecules have been cracked into O atoms. The decrease observed for both curves of molecular and atomic O is due to adsorption onto cold surfaces and pumping by the diffusion pump.

![Graph showing MS counts over time.](image)

**Figure 2.19**: The traces here initially indicate only a background of O, m/z = 16, the red trace, and O₂, m/z = 32, the black trace. As the gate valve between the plasma chamber and the central chamber is opened, a sharp rise in the counts happens. As this plateaus an initial measurement of the fragments monitored by the QMS is made (the blue vertical line). The plasma source is then turned on which cracks O₂ into O (the green vertical line). The source is left to stabilise and reach optimum operational conditions and the cracking fraction of the plasma source can be estimated (the brown vertical line).

Looking at the reaction experiments, O and O₂ are monitored during the RAIRS and TPD experiment. From experiments with pure O₂ beams a, so–called, 100% ratio can be estimated. Any change from the 100% in the O₂ count is due to the O atom reactions. Considering the minimal change in the O₃ counts, this can be discounted as a destruction pathway of O₂, purely when considering the cracking fraction and this method of calculating it.

Dosing O₂ and repeating the experiments with O atom dosing will give an idea of the cracking fraction by looking at the creation of O₂ through two O atoms. Dosing both beams for a time of 1, 2, 5 and 10 minutes and looking at the areas under the TPD traces yields **Figure 2.20**.
In Figure 2.20, the blue line and symbols are the result of O₂ TPD experiments after the sample has been dosed with the O/O₂ beam, the plasma source was on. The black line and symbols are when pure O₂ is beam dosed and the red lines are linear fits forced through (0,0). The insert is an example TPD trace of the 10 min exposure to show the difference in QMS counts. Table 2.4 shows the results of the linear regressions.

Table 2.4: This table indicates the different gradients from Figure 2.20. The change in gradient indicates that an increase of about 58% O₂ desorption occurs when the plasma source is on and when every other experimental aspect, flux and time, is kept constant.

<table>
<thead>
<tr>
<th>Beam Dosing Method</th>
<th>Gradient</th>
<th>Uncertainty (+/–)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Molecular, O₂</td>
<td>1.26</td>
<td>0.10</td>
</tr>
<tr>
<td>Atomic, O</td>
<td>2.18</td>
<td>0.21</td>
</tr>
</tbody>
</table>

Using the initial idea that the pure O₂ experiments are the 100% experiments and any increase being due to formation of O₂ through O + O, leads to an increase in the gradient of about 58%. This percentage also includes the normal fragmentation of O₂ as it is detected by the QMS. As seen in Figure 2.19 the regular fragmentation pattern of O₂ is about 36%. Accounting for this, the cracking fraction of the plasma source when
comparing TPD experiments from O and O\textsubscript{2} becomes 22\% ± 11\%. This is similar to the cracking fraction of about 20\% when looking at the O\textsubscript{2} beam before turning on the plasma source and letting it warm up. However, the best method for determining the cracking fraction would be to have the QMS in line–of–sight and measuring the fraction directly, which will be done in the future for a more accurate idea of the cracking fraction.

2.4 Experimental Techniques

2.4.1 Temperature programmed desorption (TPD)

Temperature programmed desorption (TPD) is an analytical method which can be used to determine the binding energy between molecules adsorbed onto a surface or bulk molecular interactions, in other words the desorption kinetics. It is one of the fundamental tools in describing surface kinetic processes \[24, 25\]. The basic idea revolves around heating a surface coated with molecules and observing what desorbs while monitoring the temperature of the surface. As can be understood by the technique’s name, it is a destructive analytical method since the originally solid sample is analysed after desorption to the gas phase. To be able to obtain useful information from a TPD experiment certain requirements to the basic idea must be implemented to interpret the data in a simple fashion.

The sample or surface and the chemicals adsorbed must be heated in a controlled fashion. This is done by applying a linear heating rate localised to the sample. With a linear heating ramp one can determine the temperature at various instances through

\[
T(t) = T_0 + \beta t \tag{Equation 9}
\]

where \(T(t)\) is the temperature of the sample as a function of time \((t)\), \(T_0\) is the initial temperature and \(\beta\) is the heating ramp, which are both known experimentally.

As the sample heats up, so will the sample mount and cold finger. Analysing the experimental data allows one to determine the desorption of molecules from the sample versus non–sample surfaces when relaying the temperature of the sample and the cold finger against the QMS signal.
When the temperature is sufficiently high, the chemical species has received enough thermal energy to break whatever interaction is holding it and desorption takes place. The rate at which molecules and atoms desorb is a function of the surface coverage, this means the desorption rate constant \( (k_d) \) is also dependent on the coverage \( (\theta_s) \). The rate of desorption \( (\nu_d) \) is defined as in \textbf{Equation 10}:

\[
\nu_d = k_d \theta_s^m
\]

\textbf{Equation 10}

where \( m \) is the order of reaction. Desorption of molecules from a surface is activated through heating the sample and follows an Arrhenius law leading to the rate constant \( (k_d) \) increasing exponentially as the temperature increases:

\[
k_d = \nu \exp \left( \frac{-E_d}{RT} \right)
\]

\textbf{Equation 11}

where \( \nu \) is the pre–exponential factor, \( E_d \) is the desorption energy, \( R \) is the ideal gas constant and \( T \) is the absolute temperature of the surface. As the temperature is increased, the surface coverage decreases. From the exponential increase of the rate constant and the decrease of surface coverage, a graph (\textbf{Figure 2.21}) can be made which yields a prototypical TPD trace.

\textbf{Figure 2.21}: This figure show the formation of a TPD trace. Initially molecules are deposited onto a surface of a certain quantity, \( \theta_s \), before the sample is heated. As the sample and the film heat up the coverage decreases as the rate constant, \( k_d \) increases. The point where the two curve intersect is the peak of desorption and the area under this newly created curve, \( \nu_{\text{des}} \), is proportional to the amount of species deposited.
The point where the surface coverage and rate constant curves meet marks the maximum rate of desorption and the area under the desorption trace will ideally indicate the surface coverage, but contributions from other surfaces or species can prevent this [25].

From a typical rate of desorption trace as in Figure 2.21 above one can calculate the desorption energy. With the rate constant of desorption, the number of adsorbed molecules, \(N\), and the order of the reaction, \(\text{Equation 12}\) can be set up:

\[
-d\frac{dN}{dt} = k_d N^m. \tag{Equation 12}
\]

This equation shows how the molecules desorb with respect to time, but the temperature, \(T\), is needed to arrive at an expression that matches the experimental procedure and can be introduced as below, \(\text{Equation 13}\):

\[
\frac{dN}{dt} = \frac{dN}{dT} \times \frac{dT}{dt} = \beta \frac{dN}{dT}. \tag{Equation 13}
\]

The latter part of the equation, \(dT/dt\), indicates how the temperature changes with time which is another way of describing the heating rate, \(\beta\), from \(\text{Equation 9}\) above. At this stage we can combine \(\text{Equations 12 and 13}\) to get \(\text{Equation 14}\):

\[
\frac{-dN}{dT} = N^m k_d \beta. \tag{Equation 14}
\]

By expanding the rate constant from \(\text{Equation 11}\) one obtains:

\[
\frac{-dN}{dT} = \frac{v N^m}{\beta} \exp\left(-\frac{E_d}{RT}\right). \tag{Equation 15}
\]

To obtain the temperature at the maximum of desorption, differentiating \(\text{Equation 15}\) and setting it to zero for \(m \neq 0\) leads to the general expression of \(\text{Equation 16}\):

\[
\frac{E_d}{RT^2} = \frac{v}{\beta} m N^{m-1} \exp\left(-\frac{E_d}{RT}\right). \tag{Equation 16}
\]
From this equation the desorption energy can be determined since the heating rate is set experimentally, the temperature is monitored and the ideal gas constant, \( R \), is known. The pre–exponential factor, \( \nu \), can be found through analysis of the experimental data, but can be assumed to be of the magnitude of molecular vibrational frequencies, around \( 10^{13} \text{ s}^{-1} \) for \( m = 1 \) [25]. The order of reaction, \( m \), can be determined from experimental data through the analysis of the leading edges of the TPD traces.

Reaction orders are important in determining the desorption energy as seen in Equation 16. The typical families of desorption are zero, first and second order reactions. To determine the order of desorption one has to conduct several experiments on the same species with different initial surface coverages. When enough traces have been made a trend should be visible. Figure 2.22 shows examples of TPD traces, and the observable difference after the experimental data has been analysed.

Figure 2.22: The traces above indicate the ideal desorption behaviours of chemical films deposited onto a surface. The top graph shows zero order kinetics where the leading edges align and a bulk material desorbs. The second graph is of 1st order where all the peaks line up to the same peak temperature of desorption which is expected for sub–monolayer desorption. The bottom graph is of 2nd order desorption where the trailing edges align indicative of recombination of molecules on the surface during desorption.
As can be seen in Figure 2.22, enough TPD traces lead to different observed tendencies of the peaks and edges. The first graph, zero order, with coincident leading edges is typical of a large coverage leading to multiple molecular or atomic layers, *i.e.* multilayers. The reason for the coincident leading edges is because the main interactions are adsorbate–adsorbate and because $m$ is set to zero in **Equation 15**. These interactions are similar throughout a bulk, but the desorption temperature change slightly with coverage purely because the desorption rate increases exponentially as seen in **Figure 2.21**. The second graph, first order desorption, has the peaks lining up at the same desorption temperature which is typical of low coverages when monolayers or sub–monolayers desorb from a surface as seen in **Equation 16**. This is because the main interactions are surface–adsorbate which is constant for the specific molecules adsorbed on a pristine and flat surface. When changing from monolayer to multilayer the desorption kinetics between the surface and adsorbate changes. When low coverages are dosed the molecules can possibly diffuse, depending on the surface temperature, and find the optimal binding sites which leads to slightly higher amounts of energy needed to break the interaction and make the molecule desorb. As more molecules are dosed the interaction between adsorbate–adsorbate interactions become dominant for the desorption kinetics as compared to the lower percentage of molecules involved in the adsorbate–surface interactions. The last graph has coincident trailing edges which is the regime of second order desorption reactions, this occurs when adsorbates recombine before desorption.

These are the ideal behaviours of desorbing molecular layers, but more complex interactions, such as fractional desorption orders and pseudo desorption orders also exist. Fractional desorption orders have been observed for TPD experiments of CH$_3$OH in various cases [26–28] as H–bonding becomes an important factor in desorbing such molecules. Pseudo–order desorption can be explained as being due to the surface. A surface such as amorphous SiO$_2$ surface is rough, as explained previously, which offers a wide range of binding sites for the sub–monolayer coverages of molecules. Depending on the temperature, molecules on SiO$_2$ diffuse and obtain their most energetically favoured binding site before forming a monolayer. This leads to a collection of TPD traces appearing more as second order as compared to the expected first order desorption, termed pseudo–first order. However, the molecules observed to undergo pseudo–first order desorption do not recombine on SiO$_2$ and, therefore second order desorption kinetics can be ruled out.
2.4.2 Reflection–Absorption Infrared Spectroscopy (RAIRS)

Unlike TPD, infrared spectroscopy is a non–destructive analytical tool that yields information about the various molecular vibration modes of the molecules present in the sample probed and their local environment. The type of IR spectroscopy used for this work is reflection-absorption infrared spectroscopy (RAIRS). This method was initially proposed by Greenler [29] for studying thin layers of adsorbates on metal substrates, and has the advantage of being very surface sensitive.

The technique needs the IR beam to be reflected by a substrate, which acts as a mirror, and then directed onto a detector. Adding an adsorbate to this substrate will change the reflectivity, $\Delta R$, of the substrate. This leads to a spectrum of $\Delta R/R$, where R is the total reflected IR beam from a clean surface. A UHV setup is, strictly speaking, not necessary to perform RAIRS, but this is required for other purposes already explained.

Conducting RAIRS experiments in the UHV chamber means the IR beam is directed into the UHV chamber firstly by paraboloidal and ellipsoidal mirrors located in an optics box. The beam then goes through a KBr window and onto the sample at a grazing incidence of 75° before being directed out through another KBr window. The use of KBr windows is due to their IR transparency in the detection range of the mercury cadmium telluride (MCT) detector [30]. From here the beam is then reverted and re–collimated by another paraboloidal mirror before it reaches the detector in a different optics box. The detector used in is a liquid nitrogen cooled MCT detector which has a detection range from 4000–800 cm$^{-1}$. Both optics boxes are in a dry air atmosphere to ensure minimal interference from gas phase H$_2$O and CO$_2$ from ambient air when conducting an experiment.

When IR radiation is reflected from a surface, the electric field of the incident electromagnetic wave can be considered to comprise two components; one component has the electric field vector parallel to the reflecting surface and the second has the electric field vector perpendicular to the surface. If the electric field of the IR beam is polarised parallel to the surface (i.e. in the plane of the surface) the point of reflection will show no reflected electric field. The reason for this is as the incoming beam strikes the surface, mirror electric field vectors are set up in the surface (similar to the concept of a standing wave). In the case of parallel–polarised light, these vectors cancel each
other as depicted on Figure 2.23. When the beam is polarised perpendicular to the surface, these same electric field vectors enhance each other [31].

Figure 2.23: A schematic of the electric field vectors on a surface from parallel polarised light (to the left) and perpendicular polarised light (on the right). As can be seen, the electric field is cancelled in the left diagram and enhanced in the right.

Another way of considering the effect of polarised light incident on a surface is shown in Figure 2.24. This figure illustrates the phase change of incident polarised light perpendicular (a) and parallel polarised light (b) to a surface. As can be seen in Figure 2.24, parallel polarised light has a phase change of about 180° at all angles of incident light as it is reflected from the surface. This, combined with the left part of Figure 2.23 leads to a negligible amount of expected absorbance when a molecular film is deposited onto the surface. Conversely, having a light source that is polarised perpendicular to the surface leads to a more gradual phase change as the incidence angle changes. When investigating thin molecular films, incidence angles of light polarised perpendicular to the surface of about 72° have previously been used [29] The grazing angle at these values can lead to an increase in the perpendicular component of the electric field and is enhanced nearly twice at a grazing angle of about 75°.

Figure 2.24: This graph shows how the phase changes as polarised light perpendicular (a) and parallel polarised (b) is incident on a metal surface at a given angle. As can be seen, (b) has a greater phase change as the angle of incidence changes. Figure is adapted from [29].
A further advantage of having a beam at grazing incidence is the elliptical spot produced on the surface of the sample. At normal incidence the beam would produce a circular spot which changes into an ellipsis as the incidence angle changes thereby changing the surface area covered by the IR beam. This, in turn, means more molecular oscillators are probed and interact with the radiation. When referring to IR spectroscopy on a metal surface, the metal surface selection rule (MSSR) [31] has to be mentioned and Figure 2.25 has been made to illustrate the origin of this rule.

![Image of molecular orientation](image.png)

**Figure 2.25**: The MSSR is important when conducting IR experiments on a pure metal surface. As can be seen, the molecules oriented perpendicular to the surface will have an overall enhanced dipole moment due to the image dipole arising in the metal surface. This effect is cancelled out when the molecules are aligned parallel to the surface.

The MSSR regulates what is observed with respect to the orientation of IR active molecules adsorbed on a surface, in order to maximise their IR absorption. An image dynamic dipole of the dynamic dipole is created in the metal substrate which is either enhanced or cancelled. This rule is very important when molecules are adsorbed directly onto a flat metal substrate, but the irregular and rough layer of silica covering the metal substrate leads to molecules adsorbed with random orientations with respect to the metallic mirror plane. This means the MSSR is effectively circumvented allowing modes that would be otherwise inactive in an orientated sample directly adsorbed on the metal surface to be observed. The inactive modes increase in intensity with respect to the distance they are from the pure metal surface due to the SiO\(_2\) spacer.

2.4.2 (a) **Longitudinal Optical – Transverse Optical (LO–TO) Splitting**

The effect of the SiO\(_2\) on the MSSR is crucial for the observation of the longitudinal optical–transverse optical (LO–TO) splitting. Without the SiO\(_2\) layer, the TO mode
would be silent as can be seen in Figure 2.26, as this mode arises from a collective vibration mode parallel to the metal surface.

![RAIRS spectra of the νNN mode of 14 ML N₂O on Cu, blue, 200 nm SiO₂, red, and 300 nm SiO₂, black. As can be seen the TO mode of N₂O is silent when deposited directly on Cu. This mode then activates as it is physically removed from the surface of the Cu by SiO₂ spacers.](image)

**Figure 2.26**: RAIRS spectra of the νNN mode of 14 ML N₂O on Cu, blue, 200 nm SiO₂, red, and 300 nm SiO₂, black. As can be seen the TO mode of N₂O is silent when deposited directly on Cu. This mode then activates as it is physically removed from the surface of the Cu by SiO₂ spacers.

The TO mode is silent on a flat metal surface and builds up as the increasing amount of SiO₂ physically removes it from the effect of the image dipole. The immediate effect of the above, Figure 2.26, tells us that the extremes of the LO–TO splitting means that the LO mode relates to vibrations perpendicular to the surface and the TO mode parallel to the surface, Figure 2.27.

![Diagram illustrating the MSSR](image)

**Figure 2.27**: A similar diagram to that describing the MSSR in Figure 2.25. However, a SiO₂ layer has been placed between the metal and the adsorbed dipolar molecular film illustrating how the roughness can circumvent the MSSR.
The MSSR still applies since there is a metal surface, however the rough SiO$_2$ spacing layer gives molecules extra possible binding sites leading to an ‘evasion’ of the MSSR.

An IR beam incident to the surface and through the molecular film will carry its inherent electric field. The LO–TO splitting occurs as phonons propagate throughout a dipolar film. A phonon is a unit of vibrational energy occurring when a molecular solid oscillates [32]. The TO mode phonons had long been known to interact with IR beams; indeed it was the work of Berreman [33–35] that showed how the LO mode could be investigated by changing the angle of incidence. According to the Berreman effect, the TO mode is visible and active when the incident IR beam, with electric field components both parallel and perpendicular to the normal of the surface, interacts with a deposited dipolar film if this film is considered infinite in the plane of the film. At this condition, only the TO mode is active. However, changing from an infinite film to a finite film will change what is observed dependent on what surface is used. For experiments like RAIRS, with a metal surface acting as a mirror, if the adsorbate was deposited directly on the metal, the MSSR would become dominant at low coverages and no IR signal would be seen at the frequency of TO modes. If, however, transmission IR spectroscopy was used, the TO mode would still be visible at low film coverages [36].

The LO mode activates as the thickness of the film approaches a comparable value of the wavelength of the IR beam and the angle of incidence changes. Increasing the film thickness brings around another way of thinking about the LO–TO splitting as a 3D network of molecules being essential. In such a 3D network, the neighbouring electrostatic effects needed for the LO mode becomes possible as a neighbouring counterpart appreciates the physical displacement. As this network builds up, the phonon propagation through a dipolar film leads to further displacement of charges, thereby leading to the split when an IR beam interrogates one, usually, degenerate vibrational component of a molecule. An additional effect impacting on the double–peaked nature of the LO–TO splitting is the Vibrational Stark Effect (VSE). This effect arises when degenerate vibrational energy levels are subjected to an external electric field which results in shifts in the vibrational features (such as LO–TO peaks) as the electric field changes [36]. In the case of this work, such an electric field comes from the spontaneous electric field present through the entirety of the molecular film. This field, as explained, changes with temperature and therefore should lead to changes in the LO–TO
splitting. Figure 2.28 has been created to visually show what happens as the IR beam investigates a film of N\textsubscript{2}O.

![Diagram of LO and TO modes](image)

**Figure 2.28**: This cartoon shows how the LO and TO modes behave in a solid. The LO mode arises as the phonons in the solid interact longitudinally, or along, the electric field when the IR beam hits the surface of the Cu substrate. The TO mode behaves oppositely and interacts transversely with the electric field.

### 2.5 The Spontelectric Effect

The introduction mentioned the spontelectric effect which will be investigated in detail in Chapter 5 through the use of RAIRS. However, RAIRS is an indirect method of investigation and a short description of what the spontelectric effect is and how it is directly measured will follow here, but can also be read about in references [37–44].

The term “spontelectric” effect is derived from the production of a spontaneous electric (spontelectric) field leading to a measurable surface potential during the deposition of certain dipolar molecules. The molecules exhibiting the spontelectric effect range from chlorofluorocarbons to nitrous oxide to methyl formate and many more [37]. For the time being, the only similarity between the studied molecules is that they all have a permanent dipole leading to a positive or negative surface potential depending on the how the molecules are oriented in the film.

The experiments directly measuring the surface potential have been conducted at Aarhus University in Denmark by David Field and his group. The equipment used by the group involves the use of a ultrahigh vacuum chamber (~10\textsuperscript{-10} mbar) with a cryostat
cooling a gold coated sample to 38 K connected to a femto–ammeter. Leak valves allow for gaseous molecules to be introduced and a mass spectrometer is used for temperature programmed desorption experiments to determine the monolayer (ML) coverage. A probe is necessary to determine whether the deposited dipolar molecules exhibit a spontelectric effect, and hence a surface potential. This probe comes in the form of synchrotron radiation (from the SGM2 beam line on the ASTRID storage ring) photo–ionising argon gas at a pressure of about $10^{-4}$ mbar (S1–3 in Figure 2.29) yielding near zero kinetic energy photoelectrons with an energy speed of 1.5 meV. The produced photoelectrons are focussed onto the sample surface by a series of electrostatic lenses (L1–4) and a further focussing element (VCC) where the current is measured by the ammeter. The electron source can be offset by a variable potential which can be zeroed with respect to the sample. The chamber also consists of a shield to prevent external magnetic fields from interfering with experimental results. A diagram of the experimental setup has been shown in Figure 2.29 [37].

Figure 2.29: This figure illustrates the experimental setup in Aarhus for measuring the surface potential of spontelectric molecules. Photo–ionisation of argon gas (S1–3) produces near–zero kinetic energy electrons which are focussed (L1–4) onto the sample [37].
When the potential at the electron source has been zeroed with respect to the Au sample, the electrons are just able to reach the sample. Introducing molecules into the chamber which deposit as a film will change the measured current. The sample can then be zeroed again by biasing, or correcting the sample potential, and this bias leads to the surface potential measurement of the molecular film as the surface potential arises through the entirety of the bulk molecular film. In essence, this means that as if a molecular film on the Au substrate lead to a +1 V surface potential, the sample would have to be corrected by –1 V for the electrons to just reach the sample to bring the measureable current of the sample back to a relative zero fA value, usually at about 2 – 3 fA. The accuracy with which the surface potential is measured is 2 – 3 meV while the electron beam current is measured at 100 – 200 fA. Such currents do not affect the surface potential measurement [37].

A model has been built by David Field which is fully described in reference [37] to explain experimental data collected from the apparatus as depicted in Figure 2.29. A brief description of the mean–field model will be explained here which has been used to successfully describe the surface potential experiments. The initial factor to consider is that the spontelectric effect is a bulk effect starting from the sample–film interface, running through the molecular film normal to the surface and ending at the film–vacuum interface. In other words it can be described as running along the z–axis, if x and y refer to the sample surface plane. The electric field along the z–axis ($E_z$) is composed of two parts, a local symmetrical part ($E_{sym}$) and an asymmetric part ($E_{asym}$).

The symmetrical part, $E_{sym}$, being local, refers to the interactions holding molecular layers together and determines the intermolecular force field. Dipole alignment causes a surface potential to be measured, so this part is said to contain a constant term and a dipole–dipole term. This dipole–dipole term is proportional to the $\langle \mu_2 \rangle / \mu^2$ and represents the average intermolecular dipole–dipole interaction where $\langle \mu_2 \rangle / \mu$ is the degree of dipole orientation as a ratio of dipoles oriented along the z–axis direction to the total dipole moment in a solid. The squaring of this term describing the dipole–dipole interaction is followed by all similar interaction involving dipole–image charge, extended dipoles and arrays of dipoles [45–47].

The second part describing $E_z$ is the asymmetrical part ($E_{asym}$). This non–local component travels through the film and describes long–range interactions. This is the
part of $E_z$ that leads to the observation of a surface potential as measured in the experiments. This model cannot be directly compared to the literature as it is a newly discovered phenomenon, however it is similar to the Weiss field in ferromagnetism [48]. The Weiss field (which in terms of spontelectrics can be thought of as the polarisation field) is proportional to the magnetisation (which in terms of spontelectrics can be thought of as dipole orientation). The long–range part of this term comes from the orientation of the dipoles leading to an overall polarisation felt by other dipoles throughout the spontelectric molecular film. This polarisation occurs spontaneously upon film deposition and acts in a fashion to oppose the local $E_{sym}$ term. The overall mathematical picture of the two opposing terms is shown through Equation 17:

$$E_z = E_{sym} \times \left(1 + \zeta \left(\frac{<\mu_z>/\mu}{2}\right)^2\right) - E_{asym} \times \frac{<\mu_z>}{\mu}$$

Equation 17

where the $\zeta(\mu_z/\mu)^2$ term can be thought of as a “locking” or frustration term, restricting angular movement of one molecule with respect to another. Mean field theory leads on to an expression for the $<\mu_z>/\mu$ term which can be described through the Langevin function as seen in Equation 18:

$$\frac{<\mu_z>}{\mu} = \coth \left(\frac{E_z\mu}{T}\right) - \left(\frac{E_z\mu}{T}\right)^{-1}$$

Equation 18

where $T$ is the deposition temperature of the molecular film. The dipole moment of molecules, as referred to through its orientation and alignment, will be different from gas–phase species and solid state species due to different and depolarising environments. Solid state dipole moments ($\mu$) can be calculated through Equation 19:

$$\mu = \frac{\mu_0}{1 + \frac{\alpha k}{s^3}}$$

Equation 19

where $\mu_0$ is the gas–phase dipole moment, $\alpha$ is the molecular polarisability, $k$ is the force constant and $s$ is the average spacing between molecular layers. If the model spontelectric molecule, N$_2$O, is considered, then a solid state dipole moment of 0.08 D is found by using a $\mu_0$ of 0.166 D [49], $\alpha$ of $3.0 \times 10^{-30}$ m$^3$, $k$ of 11.034 [50] and $s$ of 0.32 nm. For CO, the solid state dipole moment is found to be 0.076 D with $k = 11.034$ and $\alpha = 13.159$ au and $s = 0.34$ nm (or 6.425 au).
2.6 Kinetic Simulations

Low level and simple models can be built to compare the experimental results to the theoretical predictions. The software used in this work is the Chemical Kinetics Simulator (CKS) developed by IBM [51]. The theory behind the software is the probability theory which attempt to describe the probability of finding a system without obtaining a precise result. This can also be thought of as a stochastic method. Monte Carlo level simulations are commonly used for the probability theory which samples a system at random in order to balance a fundamental condition set by the simulation at each integration. In order for the integration to begin initial differential equations are given as input to describe the system of interest, \textit{i.e.} a TPD experiment and the associated chemical equations [52]. Besides the equations, other values are needed as input such as the initial concentration of a species and how it behaves with the described chemical equations of the system. The temperature can be fixed or varied as required for the specific simulation. When using CKS to simulate a TPD experiment these values have to be supplied to the software along with the energy of desorption and the associated pre–exponential factor. These two values can be extracted from the experimental results as an initial estimate of the values and then optimised to fit the experimental data.
2.6 References


[51] IBM Almaden Research Centre, CKS, IBM corporation, 1995

Chapter 3

**Oxygen Atom Chemistry**

Contents of this chapter

3.1 Introduction .......................................................................................................................... 80

3.2 Experimental ....................................................................................................................... 81

3.3 Results and Discussion ........................................................................................................ 81

3.3.1 O\textsubscript{2} Molecular Beam Dosing ......................................................................... 82

3.3.2 O Atoms on Silica ............................................................................................................. 87

3.3.2 (a) Reflection-Absorption Infrared Spectroscopy ......................................................... 87

3.3.2 (b) Temperature Programmed Desorption .................................................................... 89

3.3.3 O Atoms on Porous Amorphous Solid Water ................................................................. 92

3.3.3 (a) Reflection-Absorption Infrared Spectroscopy ......................................................... 93

3.3.3 (b) Temperature Programmed Desorption .................................................................... 95

3.3.4 O Atoms on Compact Amorphous Solid Water .............................................................. 99

3.3.4 (a) Reflection-Absorption Infrared Spectroscopy ......................................................... 100

3.3.4 (b) Temperature Programmed Desorption .................................................................... 100

3.3.5 O Atoms on Crystalline Solid Water ............................................................................... 103

3.3.5 (a) Reflection-Absorption Infrared Spectroscopy ......................................................... 103

3.3.5 (b) Temperature Programmed Desorption .................................................................... 104

3.3.6 O\textsubscript{3} Characterisation ......................................................................................... 105

3.3.7 O\textsubscript{3} Formation and Destruction .......................................................................... 108

3.4 Conclusion .......................................................................................................................... 112

3.5 References ......................................................................................................................... 114
3.1 Introduction

In Chapter 1, the importance of dust grains and formation routes of H$_2$O were introduced. As expressed, the main method of formation on dust grains is through reactive accretion which has been studied from different points of view by many research groups over the years; see for instance [1–4 and references therein].

In this chapter, the formation routes of H$_2$O as outlined in Figure 3.1 will be studied, with particular emphasis on the initial line of O leading to O$_2$ and on to O$_3$, i.e. the O atom chemistry. The initial steps of O atom chemistry, ultimately leading to H$_2$O have in particular been investigated by the groups of Vidali and Dulieu. Both groups use atomic O beams, but on differing surfaces. An important note to consider is that the results of this chapter are preliminary and will therefore, to a certain degree, lean on the work published by these research groups to show the application of the atomic beam sources as discussed in Chapter 2.

Figure 3.1: This figure indicates a variety of routes of H$_2$O in the solid phase on interstellar dust grains. The focus point of this chapter will be in the top line where O atoms lead to O$_2$ which can lead to O$_3$. This figure is taken from [3].
3.2 Experimental

The equipment and general method of working have been described in Chapter 2, but the specific steps taken in looking at the oxygen chemistry will be discussed here. Prior to an experiment the sample was heated to 220 K for 10 minutes to clean the sample and cold finger, then left to cool to a base temperature of 17 K while the separate gas dosing lines were purged with O$_2$ and H$_2$O. With a clean O$_2$ gas line, the plasma source was turned on to a power of 150 W before O$_2$ was leaked into the plasma chamber to a final value of $1.0 - 1.1 \times 10^{-5}$ mbar, the plasma chamber was then left to warm up. This pressure corresponds to a beam flux of $5 \times 10^{14}$ molecules cm$^{-2}$ when the gate valve between the plasma and main chamber is opened. After two to three hours the plasma source reached operational conditions and the power was turned down to 110 W. The plasma emission was monitored with the fiber optic cable linked to an Ocean Optics spectrophotometer leading to a typical intensity of $5.5 \times 10^4$ counts. At this value of counts the beam is composed of about 20% O atoms as explained in Chapter 2.5.

RAIRS backgrounds were taken after optimization of the IR spectrometer, 512 scans were taken per experiment with a resolution of 1 cm$^{-1}$. For the experiments involving H$_2$O an ionisation coefficient of unity was assumed in depositing 50 ML of p–ASW (at base temperature), of c–ASW (at 110 K) or of CSW (at 140 K). During the testing phase, the maximum time for atomic oxygen bombardment was determined to be 50 minutes. Beam dosing for a longer time will lead to greater desorption from the cold finger, thereby increasing the pressure to beyond the safe operational conditions of the QMS. TPD experiments were also conducted following the RAIR measurement with an average heating ramp of 0.24 K s$^{-1}$ for O$_2$ desorption and 0.17 K s$^{-1}$ for O$_3$ desorption.

3.3 Results and Discussion

In this section the results of the beam dosing experiments relevant to oxygen and water chemistry relevant to the interstellar medium will be presented. Initially, experiments with the molecular beam were done to be able to directly compare any differences when the plasma source was turned on. Reflection–absorption infrared spectroscopy (RAIRS) and temperature programmed desorption (TPD) are the analytical techniques that will be used to investigate any potential reactions occurring.
3.3.1 O$_2$ molecular beam dosing

Before the atomic oxygen experiments were conducted, molecular oxygen experiments were performed. This was done with a beam flux (as described in Chapter 2) of $5 \times 10^{14}$ molecules cm$^{-2}$ and dosing for 1, 2, 5, 10, 20 and 50 minutes. TPD experiments were conducted with m/z = 16 and 32 only as no O$_3$ is formed; RAIR spectra were not measured as O$_2$ is in principle IR inactive as it is electrically dipole forbidden, however IR bands of solid O$_2$ have been detected in the 1580 – 1630 cm$^{-1}$ region [5] which are not observed in this work.

The results of the TPD experiment can be seen in Figure 3.2. At higher temperature O$_2$ begins to desorb from the cold finger which has not be included in this figure.

![Figure 3.2](image)

Figure 3.2: This figure shows the results of the TPD experiments of molecular oxygen beam dosed onto SiO$_2$ for 1, 2, 5, 10, 20 and 50 minutes. A clear change can be seen between 5 and 10 minute dosing, this is due to the change from sub–monolayer to multilayers of O$_2$. This change is more clearly shown in the insert of 1, 2, 5 and 10 minute dosages.

As can be seen in Figure 3.2, the traces of 10, 20 and 50 minute dosing all have somewhat aligned leading edges which is indicative of multilayer desorption as explained in Chapter 2. A difference between the 10 minute and 20/50 minutes TPD traces can be seen in Figure 3.2. The heating rates are similar (only differing by 0.01 K s$^{-1}$) and are not expected to be the cause of the shift in this temperature range. The work
of Collings et al. [6] showed that a difference in O₂ TPD traces is observed between 2.5 and 3.7 ML when background dosing O₂ using the same experimental set-up. This shift in the TPD traces is possibly the α → β crystalline phase transition of O₂ as noted by Cairns and Pimentel [7] and Freimann and Jodl [8] and it could possibly be the same reason for the shift observed between the multilayer O₂ TPD traces of Figure 3.2. Dosing O₂ for shorter time leads to sub–monolayer quantities of O₂ where the desorption peaks move to lower temperatures as the exposure increase from 1 to 2 to 5 minutes. This is shown with the insert in Figure 3.2 which includes the 10 minutes trace for reference. Considering the change between the 5 and 10 minute dosing, one can estimate that 1 ML of O₂ is formed after 10 minutes, therefore the maximum dosing time of 50 minutes corresponds to about 5 ML of O₂.

Typical first order desorption, as is expected from sub–monolayer amounts of material, should show the same peak temperature as the coverage increases. This is not seen in the insert of Figure 3.2 for O₂ sub–monolayer desorption, however that is not unusual due to the array of binding sites rough surfaces such as an amorphous SiO₂ film offers [6, 9, 10].

With the context of atomic oxygen deposition onto various surfaces in this work, the longer the dosing time, the more O₂ and O₃ will be formed. Considering this, only the greatest exposure will be analysed, however an interesting trait can be seen between the multilayers when O₂ desorbs. Dosing times above 50 minutes leads to pressure increases too great for the QMS to handle, for that reason the remainder of the chapter will focus on these regions where about 5 ML of O₂ has been deposited after 50 minute dosing.

With this in mind, this thick layer corresponding to 5 ML O₂ desorbing from SiO₂ will be analysed and the kinetic parameters extracted. Firstly, a leading edge analysis (LEA) will be done to show that desorption is zero order as befitting the theory behind multilayer desorption where the leading edges are aligned. This is done by comparing the rate of desorption (r_{des}) with the number of molecules (N) leaving the surface at a specific temperature. The relationship between these variables can be described through Equation 1.

\[ r_{\text{des}} = N \times 6 \text{ cm}^2 \times 10^{15} \text{ molecules cm}^{-2} \]  

Equation 1
where \( N \) is calculated through the total number of molecules in the TPD spectrum minus the molecules in the gas phase at a chosen temperature with respect to the number of monolayer TPD trace. The value of 6 cm\(^2\) corresponds to the surface area of the sample used in this work and \( 10^{15} \) molecules cm\(^{-2}\) is the typical number of molecules found in a monolayer [11]. The results of this analysis can be seen in **Figure 3.3**.

![Figure 3.3](image)

**Figure 3.3**: This figure shows the results of the leading edge analysis of the pure \( \text{O}_2 \) molecular beam dosing TPD experiment. Two separate regions can be distinguished where the lower three points relate to the coverages of 1, 2 and 5 minute beam dosing and the latter three points are of the 10, 20 and 50 minute dosing. These two regions are the sub–monolayer and multilayer respectively.

As can be seen in **Figure 3.3**, two regions exist when desorbing \( \text{O}_2 \) dosed at a range of molecular thicknesses. The first three points lead to an average gradient of 0.49 ± 0.20 which is the desorption order for the low coverages of 1, 2 and 5 minute beam dosing. A value closer to unity was expected as this is considered the sub–monolayer regime for \( \text{O}_2 \) desorption, however with more data points the gradient is expected to change to approach a value of one. This can be seen when background dosing \( \text{O}_2 \) on SiO\(_2\) as in Collings *et al.* [6]. The plateau has an average gradient of 0.23 ± 0.21 and is the region of interest as multilayers will be studied in this chapter, and an order of zero is indicative of such layers. As can also be seen, the plateau is not completely zero, even when considering the uncertainty. A possible reason for this is linked to the difference in the leading edges of the TPD trace with the \( \alpha \rightarrow \beta \) phase transition explained earlier in this section. If more data points were studied, an ideal behaviour of two separate
regions with zero order desorption kinetics is expected. Zero order kinetics is therefore assumed to be involved in the desorption process when an amount of >10 minute O₂ beam dosing is desorbed. Considering that desorption of this molecular film follows zero order kinetics, Figure 3.2 can be inverted to shows Figure 3.4 which is the natural logarithm versus the inverted temperature of the molecules leaving the surface.

![Figure 3.4](image)

**Figure 3.4**: This figure shows the Arrhenius plot of the TPD trace after the molecular oxygen beam has dosed the bare SiO₂ surface for 50 minutes. The black dots correspond to the experimental data and the red dots highlight the leading edge of the TPD profile from the same 50 minute TPD trace in Figure 3.2.

The red line in Figure 3.4 corresponds to the leading edge as O₂ desorbs in Figure 3.2 which can be described by the Arrhenius equation (Equation 2) as mentioned in Chapter 2,

\[ \ln(k) = \ln(\nu) - \frac{E_a}{RT} \]  

Equation 2

where \( E_a \) is the activation energy for desorption which is determined through the gradient of the red line, \( R \) is the gas constant, \( T \) is the temperature on the sample, \( \nu \) is the pre–exponential factor which can be determined through the intercept with the Y–axis and \( k \) is the rate constant. As can be seen from Figure 3.4, and with the use of Equation 2, the desorption energy can initially be estimated as being 8.7 kJ mol⁻¹ and the pre–exponential factor can be estimated as being about \( 10^{32} \) molecules cm⁻² s⁻¹. These values, along with an estimated concentration of O₂ on the surface being \( 5 \times 10^{15} \)
molecules cm$^{-2}$, (as $10^{15}$ molecules cm$^{-2}$ is typically assumed as one ML [11]) leads to a simple CKS model being built. This model will only consider the multilayer desorption process following the model set up in **Equation 3**:

$$O_2 (s) \rightarrow O_2 (g) \quad \text{Equation 3 (A)}$$

$$O_2 (g) \rightarrow O_2 \text{(pump)} \quad \text{(B)}$$

where the bracketed terms refer to O$_2$ being in the solid form on the surface (s), in the gas phase (g) and as it is pumped away (pump). The rate constant for the last step where gas–phase O$_2$ is pumped away is temperature independent and has an associated rate constant of 0.03 s$^{-1}$ to model the pumping speed of the diffusion pump (this rate constant is not associated with the rate determining step meaning it has to be relatively high in value). The results of the model when compared to the experimental data can be seen in **Figure 3.5** where the solid line shows the model and scatter plot indicates the experimental data.

![Figure 3.5](image)

**Figure 3.5**: This figure shows the TPD results of 50 min molecular oxygen dosing onto SiO$_2$ (black scatter) with the CKS model as a red solid line.

From **Figure 3.5** and the CKS model used to fit the data, a closer approximation of the kinetic parameters can be extracted. For the desorption process of about 5 ML O$_2$ leaving the SiO$_2$ surface an associated energy is found to be $8.5 \pm 0.1$ kJ mol$^{-1}$ with a pre–exponential factor of $4 \times 10^{30 \pm 1}$. Background dosing of O$_2$ and its TPD spectrum has been studied to a great extent from such as the work from Collings et al. [6] where
O\textsubscript{2} was desorbed from the same surface as described in this thesis. In that work an $E_{des}$ of 7.5 ± 0.2 kJ mol$^{-1}$ and $v = 10^{28\pm1}$ molecules cm$^{-2}$ s$^{-1}$ was determined as being the kinetic parameters needed for O\textsubscript{2} to desorb. Another example is in the work on Acharyya et al. [12] and Fuchs et al. [13] where an $E_{des}$ of 7.6 ± 0.2 kJ mol$^{-1}$ was determined as required energy for multilayer desorption of O\textsubscript{2}. As can be seen, a discrepancy between the literature data and the data of this work exists. A possible reason for this could be in the deposition method. A TPD study regarding different deposition method of H\textsubscript{2}O, background dosing and beam dosing, by Kimmel et al. [14] has shown a similar difference as noted here. Background dosing, or background filling of the chamber leads to a slower deposition rate and a more inflated solid structure, possibly due to ‘hit–and–stick’ ballistic deposition. Beam dosing is more direct with a lower pressure in a UHV chamber, this leads to a more compact solid film. In other words, the morphology of molecular films changes depending on dosing technique.

### 3.3.2 O Atoms on Silica

Having categorised how beam dosed O\textsubscript{2} molecules behave on SiO\textsubscript{2}, the plasma sources can now be turned on and the O/O\textsubscript{2} beam can be studied on different surfaces. To be able to compare the results directly, the beam flux was kept constant at $5 \times 10^{14}$ molecules cm$^{-2}$ and a clean SiO\textsubscript{2} sample was initially used. The specific reaction steps involving oxygen chemistry that will be studied are shown in Equation 4.

\[
\text{Equation 4}
\]

This simple reaction scheme indicates the reactions that are possible when the O:O\textsubscript{2} beam is dosed onto bare SiO\textsubscript{2}. O\textsubscript{3} degradation with another oxygen atom leading to 2O\textsubscript{2} molecules is naturally also possible, but the extent to which this happens cannot be determined through these experiments. This sort of chemistry can be considered as the solid state version of the Chapman mechanism known in atmospheric chemistry [15].

### 3.3.2 (a) Reflection–Absorption Infrared Spectroscopy

Similar to the TPD experiments explained earlier, the maximum O atoms dosing time was set to 50 minutes. However, an experiment where the dosing time was increased as in the O\textsubscript{2} beam experiment was also done. The results of dosing O atoms onto SiO\textsubscript{2} for times of 1, 2, 5, 10, 20 and 50 minutes can be seen in Figure 3.6.
As is naturally expected, and as can be seen in Figure 3.6, the longer time the O atoms bombard the SiO₂ surface, the more O₃ is formed. Therefore, the limiting the discussion to the 50 minute O atom dosing time remains the focus of the chapter. A peak is seen to form at about 1045 cm⁻¹ which can be fitted with three Gaussians leading to Figure 3.7 for a better understanding of the band. The three Gaussians as shown in blue in Figure 3.7 were compiled to reduce the residual difference between the experimental data (red) and the overall fit as shown in red. This can be seen in the top of Figure 3.7 where the difference between the observed absorbance ($A_{obs}$) and the fitted abundance ($A_{fit}$) is shown over the region of the O₃ peak which indicates that the fit is appropriate considering the signal–to–noise level. The three Gaussians involved in creating the O₃ peak fit have been listed in Table 3.1.

<table>
<thead>
<tr>
<th>Wavenumber / cm⁻¹ (± 1)</th>
<th>Assignment</th>
<th>Literature / cm⁻¹ (± 2)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1031</td>
<td>[O₃...O]</td>
<td>1032</td>
</tr>
<tr>
<td>1036</td>
<td>O₃ ($v_3$) O–O asymmetric stretch</td>
<td>1037</td>
</tr>
<tr>
<td>1045</td>
<td>[O₃...O₃]</td>
<td>1042</td>
</tr>
</tbody>
</table>

Table 3.1: This table shows the IR frequencies composing the O₃ band displayed in Figure 3.7 which have been compared to literature values.
Figure 3.7: This figure shows the fit between the RAIRS data (black) and the fit (red) which is made by three Gaussians in blue. The result of the fit has been listed in Table 3.1. Further to this, the top of the figure shows the residuals from the experimental data and the overall fit.

As can be seen in Figure 3.7 and Table 3.1, O₃ features have been found after O atom bombardment of the bare SiO₂ sample. Other features of O₃ such as O–O symmetric stretching vibration at 1104 cm⁻¹ or the O–O–O bending vibration at 702 cm⁻¹ [16] were not detected in any of the experiments due to low signal or being outside of the MCT detection range [17].

3.3.2 (b) Temperature Programmed Desorption

The results of what happens in Equation 4 can be also seen through the TPD experiment subsequent to dosing the O₂O₂ beam onto SiO₂ for 50 minutes as illustrated in Figure 3.8.

In Figure 3.8 O₂ desorption is observed to begin at about 23.8 K and peak at about 29.1 K while O₃ shows no clear TPD trace, only a slightly higher count rate in the 50–60 K
range. As can be seen in Figure 3.8 between the main figure and the insert, O₃ desorption occurs in the same temperature range as O₂ desorption from the cold finger. Due to the larger quantity of O₂ sticking to the colder surfaces of the cold finger, distinction between regular O₂ and decomposed O₃ into O and O₂, does not follow a simple procedure. However, an analysis of O₃ desorption will follow later in this chapter, in section 3.3.6. Monitoring m/z = 16 (O⁺ atoms alone) leads to no deviation from the O₂ signal meaning that single oxygen atoms are not observed during the experiments which has also been the case for other research projects [18]. However, O atom desorption has been noted by various sources as leaving SiO₂ and H₂O surfaces with energies ranging from about 10 – 15 kJ mol⁻¹ [9, 19] and other values such as 12.1 kJ mol⁻¹ [20, 21] from C₂H₂ and 11.2 kJ mol⁻¹ from pyrene [22].

Considering how these and the following O atom beam dosing experiments were only done for the maximum possible time to obtain the highest levels of O₃ formation, LEA was not done. However, this was done for O₂ beam dosing as discussed earlier and for that reason the O₂ TPD traces can be analysed by assuming zero order desorption kinetics as discussed earlier. Inverting Figure 3.8 to find the kinetic parameters for O₂ desorption when dosing O atoms, similar to the O₂ beam analysis, leads to the Arrhenius plot of Figure 3.9.
Figure 3.9: This is the Arrhenius plot of the desorption profile from the TPD trace in Figure 3.8. The black scatter is representative of the inverted TPD trace after the atomic beam has bombarded the bare SiO$_2$ for 50 minutes with the red points being the leading edge of the TPD trace.

From Figure 3.9 we can estimate the activation energy for desorption, $E_{\text{des}}$, and the pre-exponential factor, $\nu$, for desorption of O$_2$ molecules through the gradient and the intercept, respectively, through the red linear scatter points as stated in Equation 2. As

Figure 3.10: This figure shows the comparison between the experimental data (black scatter) and the CKS model (red solid line). This fit has been created with an $E_{\text{des}}$ of 6.7 kJ mol$^{-1}$ and $5 \times 10^{27}$ molecules cm$^{-2}$ s$^{-1}$. 
a first estimate Figure 3.9 yields a value for $E_{\text{des}}$ of 6.5 kJ mol$^{-1}$ and $\nu$ of $2 \times 10^{33}$ molecules cm$^{-2}$ s$^{-1}$. These values can be used in a similar set of CKS equation as Equation 3 earlier. With this model arranged and considering an initial [O$_2$] corresponding to 5 ML the graph in Figure 3.10 can be produced.

Figure 3.10 shows the experimental data in circles with the simulated spectra as a line. When the $E_{\text{des}}$ and $\nu$ are set to 6.7 kJ mol$^{-1}$ and $5 \times 10^{27}$ molecules cm$^{-2}$ s$^{-1}$ the agreement between the two curves is good. Initial thoughts when comparing the desorption energy of molecular O$_2$ dosing (8.5 kJ mol$^{-1}$) and atomic beam dosing (6.4 kJ mol$^{-1}$) could be that the values should be the same. O atoms and O$_2$ molecules are deposited at the same time, leading to more O$_2$ molecules and O$_3$ formation. As further O atoms bombard the O$_2$ molecules on the surface, a change in the morphology is possible, due to O$_2$ and O$_3$ formation. The energy released as the molecules are formed has to be dissipated in order for the reaction product to remain on the ice surface. This reaction enthalpy release promotes the morphological change. When this reaction occurs on SiO$_2$, the energy is dissipated into the surface of the sample, however an O$_2$ layer is continually being made during O beam deposition. As more O$_2$ molecules are deposited and formed, new O$_2$ reaction will begin to take place on O$_2$ rather than SiO$_2$. The formation energy is now dissipated into the O$_2$ film which could lead to changes in the morphology and structure of the film. If this is the case, a more fluffy ice could begin to be formed, an O$_2$ film that is partially amorphous. Amorphous solids generally have a lower $E_{\text{des}}$ as compared to its crystalline counterpart [24 and references therein]. Similar amorphisation mechanisms have been observed in other experiments where energy is in a thin film, e.g. electron bombardment of benzene films [25] and exposure of H$_2$O ices to ionising sources, both protons and electrons [26].

### 3.3.3 O Atoms on Porous Amorphous Solid Water

Having investigated what happens as the O:O$_2$ beam bombards a naked SiO$_2$ surface, the focus will turn to the more realistic scenario where H$_2$O is already present on a dust grain. The same beam flux as for the previous experiments is used, but a 20 ML film of H$_2$O is now pre–deposited onto the SiO$_2$ surface before O atom bombardment. To begin with the H$_2$O film will be deposited as porous amorphous solid water (p–ASW).
With the presence of H₂O already on the surface, the same O₃ formation pathway is possible, however H₂O₂ formation could possibly become important [27] through 

**Equation 5:**

\[ O + H₂O \rightarrow H₂O₂ \]  \hspace{1cm} \text{Equation 5 (A)}

or possibly more accurately

\[ O + H₂O \rightarrow 2OH \]  \hspace{1cm} \text{(B)}

\[ 2OH \rightarrow H₂O₂ \]  \hspace{1cm} \text{(C)}

The formation of H₂O₂ in **Equation 5** proceeds through O¹D and as stated in Chapter 2, only O³P is believed to be present in the atomic beam. Therefore, formation of H₂O₂ would mean that the atomic beam is not pure as expected. Formation of H₂O₂ has also been studied through ion irradiation of H₂O surfaces [28], the HO₂ + HO₂ reaction [29] and by hydrogenation of O₂ through the intermediary molecules of 2OH [30] as depicted in **Figure 3.1**.

### 3.3.3 (a) Reflection–Absorption Infrared Spectroscopy (RAIRS)

Any formation of H₂O₂ and O₃ can be observed as the H₂O is bombarded through RAIRS. As has been discussed previously; O₃ shows a peak in the IR spectrum at about 1140 cm⁻¹, this peak can be seen in **Figure 3.11**.

![Figure 3.11](image_url)

**Figure 3.11:** This figure shows the formation of O₃ when the O atom beam bombards 20 ML p–ASW. As can be seen, the shape and character of the feature is similar to when O atoms probe the bare SiO₂ surface.
Figure 3.11 can be fitted similar to Figure 3.7 to show what components make up the O3 band. From the previous analysis of O3 on SiO2, the same vibrational characteristics can be seen to make to the \( \sim 1145 \text{ cm}^{-1} \) feature, Table 3.2.

<table>
<thead>
<tr>
<th>Wavenumber / cm(^{-1})</th>
<th>Assignment</th>
<th>Literature / cm(^{-1})</th>
</tr>
</thead>
<tbody>
<tr>
<td>1031 ± 1</td>
<td>([O_3]...O)</td>
<td>1032 ± 2</td>
</tr>
<tr>
<td>1037 ± 1</td>
<td>(O_3 (\nu_3)) O–O asymmetric stretch</td>
<td>1037 ± 2</td>
</tr>
<tr>
<td>1045 ± 1</td>
<td>([O_3]...O_3)</td>
<td>1042 ± 2</td>
</tr>
</tbody>
</table>

Table 3.2: This table shows the result of resolving the components of the O3 band when fitted with Gaussians and their comparison with literature values.

As can be seen in Table 3.2, the feature in Figure 3.11 corresponds to O3 in different environments and matches the literature frequencies nicely. Having confirmed that O3 is produced on different surfaces, the focus will shift towards H\(_2\)O\(_2\) formation. The infrared spectrum of H\(_2\)O\(_2\) has been studied extensively, as for example by looking at the 3700 and 1601 cm\(^{-1}\) features [27], the 2850 cm\(^{-1}\) feature [28], and small clusters and monomers isolated in different matrices [31, 32], making it simple to follow any formation of this molecule in the IR spectrum. Figure 3.12 shows these regions.

Figure 3.12: This figure shows the three regions of interest in the IR spectrum. These are difference spectra showing the difference in absorption of the p–ASW film \((A_{p-ASW})\) after O atom bombardment \((A_{O \text{ atoms}})\). The red boxes indicate the specific regions where H\(_2\)O\(_2\) features are expected if formed, however no such features are observed.
Figure 3.12 is of three difference spectra of the p–ASW film \( (A_p-ASW) \) and the same film after 50 minute O atom bombardment \( (A_O \, atoms) \). The red boxes indicate the regions of interest where \( \text{H}_2\text{O}_2 \) features are expected if the molecules has been formed during O atom bombardment, however no features are observed. The sharp peaks from 3600 cm\(^{-1}\) and greater and about 1500 – 2000 cm\(^{-1}\) are of gas–phase water in the optics boxes outside of the UHV chamber. Considering the entire detection range of the MCT detector used 4000 – 800 cm\(^{-1}\), the only change observed is at about 1045 cm\(^{-1}\) as \( \text{O}_3 \) is formed as seen in, for example, Figure 3.11.

3.3.3 (b) Temperature Programmed Desorption

As with the studies of O atom beam irradiation of SiO\(_2\), the initial molecule studied will be \( \text{O}_2 \), however as the procedure has been explained in the previous chapter, Section 3.3.2, only a brief summary will be given here before the general results.

Monitoring \( m/z = 32 \) as the temperature is raised, post–atom beam bombardment, leads to Figure 3.13.

Figure 3.13: This figure is of the 20 ML p–ASW film after 50 minute O atom bombardment as it desorbs. The species of interest in this figure is \( \text{O}_2 \) as it leaves the surface, the shape and temperature at which it leaves the surface is due to the porosity of \( \text{H}_2\text{O} \). The insert is an Arrhenius plot where the red dots (the leading edge of desorption) are used to extract the kinetic information of the desorption process.
Figure 3.13 shows the desorption process of O$_2$ from 20 ML p–ASW. At first glance, the temperature at which O$_2$ begins to leave the surface, about 32 K, is greater than observed when O$_2$ leaves bare SiO$_2$ as shown in Figures 3.2 and 3.8. A change can also be seen in the shape of the peak. The reasons for these new features are put down to the change in the surface. The porous nature of the H$_2$O underlayer leads to a varying and different surface as compared to SiO$_2$. Dangling bonds are present at a much greater concentration on p–ASW as compared to other types of H$_2$O films [33, 34] which could be a contributing factor to the observed differences. The insert in Figure 3.13 is of the Arrhenius plot of the TPD data. This plot leads to an approximate $E_{des}$ (6.6 kJ mol$^{-1}$) and pre–exponential factor ($6 \times 10^{29}$ molecules cm$^{-1}$ s$^{-1}$) as previously demonstrated. A similar CKS model can be built, including only the same two steps as earlier of solid O$_2$ becoming gas phase and the gas leading to the pumping stage as seen in Equation 3 above. With this model and the various parameters included, Figure 3.14 has been created.

![Arrhenius plot of TPD data](image)

**Figure 3.14**: This figure shows the comparison between the experimental data (black) of O$_2$ desorption from 20 ML p–ASW and the model (red).

**Figure 3.14** shows the fit of the CKS model to the experimental results. A perfect fit was not obtained due to the peculiar line–shape of the TPD trace which could possibly be due to both multi– and monolayer desorption from p–ASW. The long trailing edge after the second peak is indicative of sub–monolayer desorption from rough surfaces [6]
and pores of p–ASW films [35, 36]. The $E_{des}$ as modelled through CKS is still lower than the literature, and even though there are pores and O\textsubscript{2} does diffuse, O\textsubscript{2} formation could still possibly occur on a pre–existing O\textsubscript{2} layer. This would explain why an $E_{des} = 7.4$ kJ mol\textsuperscript{-1} is found for this desorption process.

Formation and desorption of O\textsubscript{3} is also investigated from p–ASW and is as limited as when the O\textsubscript{3} is observed to leave the bare SiO\textsubscript{2} surface. **Figure 3.15** shows the observed QMS count rate as the temperature increases showing a slight change above the noise level as O\textsubscript{3} desorbs.

![Figure 3.15](image)

**Figure 3.15**: This figure shows the desorption of O\textsubscript{3} after 20 ML p–ASW has been bombarded by O atoms for 50 minutes. A change is observed in the temperature region above 62 K as O\textsubscript{3} begins to leave the surface.

A full analysis of the kind of TPD as seen in **Figure 3.15** is not possible, however a discussion of the TPD spectra of O\textsubscript{3} will follow at the end of this chapter.

Recollecting that the RAIR spectra gave no positive indication of H\textsubscript{2}O\textsubscript{2} being present on the surface or in the molecular film, does not necessarily imply that no H\textsubscript{2}O\textsubscript{2} formation occurs at all. Therefore, a second test is needed to verify this using a different technique, such as mass spectrometry. The fragmentation pattern for this species comprises of mass fractions at m/z = 34, 32, 17 and 16. The masses monitored so far in this chapter
have mainly been m/z = 32 and 16 for O₂ desorption with m/z = 18 and 17 intended for H₂O desorption, formation and therefore desorption of H₂O₂ will therefore lead to differences in the TPD profiles when comparing the various masses. These comparisons can be seen in Figure 3.16 where the addition of m/z = 34 has been shown together with m/z = 32 and 16 in panel (A) and m/z = 17 and 18 are shown in panel (B) against experimental time.

Figure 3.16 shows what happens as a 20 ML p–ASW bombarded with O atoms for 50 minutes, is desorbed from the SiO₂ surface. Previously in this section, O₂ and H₂O desorption experiments were analysed. Through those results it can be said that the peaks in panel (A) correspond to O₂ desorption, initially from the sample and then the broad peak being from the cold finger. As is typically expected, and also discussed in Chapter 2, the O₂ to O (m/z = 32 to 16) ratio is constant and invariant as the experiment progresses. A m/z = 34 is also expected when monitoring O₂, however at a much smaller intensity, usually at about 0.04% of the O₂ signal [37, 38]. If this
anomaly, which could be due to a mass spectrometer calibration issue, is ignored, then the overall trend of m/z = 16, 32 and 34 should follow each other exactly if the mass spectrometer is monitoring the same molecule, such as O₂ in this case. **Figure 3.16 (A)** shows no change in any of the three masses throughout the TPD experiment. H₂O₂ will desorb at a temperature similar to H₂O desorption at about 165 K [28]. However, no change in the profile of m/z = 32 and 34 is observed. Thereby H₂O₂ is not observed in the TPD data and has not been formed during the experiment. Further verification comes from panel (B) in **Figure 3.16** where m/z = 17 and 18 are monitored. A m/z = 18 obviously represent H₂O desorbing from p–ASW. However, m/z = 17 should also be present at a level of 23%. [37, 38]. The m/z = 17 mass fragment is also formed from H₂O₂ as it desorbs and decomposes in the ion source of the QMS. Panel (B) point towards no change being observed in the TPD profiles of m/z = 17 and 18 during the experiment. The relative signal of m/z = 17 compared to 18 is as unusual as when comparing m/z = 32 and 34. However, if only the profiles are compared, no change is observed. The initial sets of peaks correspond to co–desorption of H₂O as O₂ desorbs. At later stages of the experiment, the m/z = 17 signal is expected to diverge from the 18 signal if H₂O₂ were to desorb. This does not seem to occur.

Following various masses with the QMS related to the mass of H₂O₂ and attempting to observe the specific frequencies with RAIRS expected from thin films of H₂O₂, it can be said that H₂O₂ production is not possible under these experimental conditions.

### 3.3.4 O Atoms on Compact Amorphous Solid Water

Having studied what happens as the O atom beam bombards bare SiO₂ and a multilayer of p–ASW, the focus will now shift towards changing the surface further to compact amorphous solid water (c–ASW). The main difference between porous and compact amorphous solid water is that pores are now closed and O/O₂ will not be as free to thermally diffuse into them. The compact form of H₂O is believed to be the dominant form on the surface of an icy dust grain in the ISM [39]. The focus will remain the same, O₂ and O₃ observation and desorption; however H₂O₂ is still not observed in any of the experiments and as such, spectra similar to **Figures 3.12** and **3.16** have been excluded from this section.
3.3.4 (a) Reflection–Absorption Infrared Spectroscopy

After the 20 ML c–ASW have been deposited, the ground state O atoms will bombard the surface for 50 minutes. Before and after the bombardment RAIR spectra were obtained at every step of the experiment, yielding Figure 3.17.

As can be seen from Figure 3.17, the general shape, position and character of the band is very similar to the previous O₃ spectra shown above in Figures 3.7 and 3.11. This might be indicative of the surface not being of immense importance for the adsorption of O₃ as the amount of H dangling bonds have changed drastically with the surfaces already investigated. The O₃ band in Figure 3.17 is made up of the same contributions as the above O₃ bands, namely an [O...O₃], [O₃...O₃] and the O₃ asymmetric stretching mode. These modes are found are 1032, 1045 and 1037 cm⁻¹ respectively, similar to the former experiments.

![Figure 3.17](image)

**Figure 3.17**: This figure shows the O₃ peak after the O atom beam has bombarded a multilayer surface of c–ASW for 50 minutes. There are no other observed differences in the IR spectrum.

3.3.4 (b) Temperature Programmed Desorption

Similar to the previous experiments, O₂ desorption can be studied by looking at m/z = 32 as the sample temperature increases as can be seen in Figure 3.18.
The main differences between O\(_2\) desorption from p–ASW in Figure 3.14 and from c–ASW as in Figure 3.18 is the temperature at which desorption initiates and the shape of the TPD profile. The amount of O\(_2\) should in theory be the same, however the difference in porosity of the two surfaces is significant. Pores are still present in this type of ASW, however pores collapse from about 30 K [35] leading to less of a variety of binding sites in c–ASW as compared to p–ASW and a reduced surface area. This trend is expected to continue in the next section with O\(_2\) desorption from CSW. The insert in Figure 3.18 is of the Arrhenius plot, which has been constructed the same way as previously described, to yield an initial estimate of the kinetic parameters involved in O\(_2\) desorption from c–ASW. With a CKS model being set up as follows Equation 3 above, Figure 3.19 can be made to show the fit of the model in red with experimental data in black.

The fit between the experimental data and the CKS model in Figure 3.19 is not perfect. However, the Arrhenius analysis and the knowledge that the pores in the H\(_2\)O film are closed means that O\(_2\) can be considered as following zero order desorption during the experiment. With this being said, a fit with an \(E_{des}\) of 6.3 ± 0.4 kJ mol\(^{-1}\) and a \(\nu\) of \(10^{26±2}\) molecules cm\(^{-2}\) s\(^{-1}\) is not great. The leading edges do not line up and the entire TPD...
trace spans a greater temperature range than expected for multilayers, however this has also been observed when desorbing a pre-deposited CO multilayer on a c–ASW substrate [36]. The fit of the model in Figure 3.19 leads to an $E_{des}$ which is similar to the value of $E_{des}$ found for the O beam on SiO$_2$ experiments. The same reason for a lower energy for c–ASW applies as when analysing the O atom on SiO$_2$ experiment as there are no pores in the H$_2$O film. Formation of O$_2$ molecules leads to excess energy which is dissipated into the O$_2$ layer leading to amorphisation. The desorption trace in Figure 3.19 is broad spanning a range greater than 10 K which is however unusual.

Following this analysis of the O$_2$ desorption, a quick glance will also be taken at the O$_3$ desorption. The experiment yielded results which are very similar to the previous TPD experiments of O$_3$ desorption from SiO$_2$ and p–ASW and the TPD profile has not been shown as examples are shown in Figures 3.8 and 3.15 previously. As for the other O$_3$ TPD experiments, an analysis involving an Arrhenius plot is not possible from the data obtained when monitoring O$_3$ desorption from c–ASW. Extraction of $E_{des}$ and $\nu$ will follow in the last section of this chapter after O atom bombardment of CSW has been reported.
3.3.5 O atoms on Crystalline Solid Water

The final surface to be studied is the crystalline solid water (CSW) surface where the experimental procedure will be the same as for the previously discussed experiments. The difference between the CSW and the ASW surface is that now there are no pores, a greater surface area and a more rigid and long–range ordered structure is found in the molecular film. H$_2$O$_2$, and the lack of observable data for H$_2$O$_2$, has also been excluded in this section as no evidence for its formation was observed.

3.3.5 (a) Reflection–Absorption Infrared Spectroscopy

Once again, only the O$_3$ peak was observed to be the region with any change, this peak, which is similar to the previous experiments, is shown in Figure 3.20. This peak can be seen to span from about 1050 – 1030 cm$^{-1}$ exactly as when studying the O$_3$ feature of SiO$_2$, p–ASW and c–ASW considering the uncertainty of 1 cm$^{-1}$. For this reason, fitting Figure 3.20 with Gaussians leads to the overall feature being broken down into a O$_3$ asymmetric stretching vibration at about 1037 cm$^{-1}$, a [O...O$_3$] (1032 cm$^{-1}$) and a [O$_3$...O$_3$] part (1045 cm$^{-1}$).

![Figure 3.20](image)

**Figure 3.20:** This figure shows the result, when looking at O$_3$, when a 20 ML CSW film has been bombarded with O atoms for 50 minutes. No other change in the 800 – 4000 cm$^{-1}$ region was observed.

The difference in the experiment now is that H–dangling bonds are not present to the same extent of the previous ASW films. In essence, the CSW surface is similar to the
bare SiO$_2$ surface, and should therefore show similar RAIR spectra. However, all four experiments show the same span of wavenumbers for the O$_3$ peak. This could be due to O$_3$ being formed and embedded in an O$_2$ matrix. Another option is that 20 ML H$_2$O does not cover the entire sample leaving bare SiO$_2$ for O$_2$ and O$_3$ to adsorb to.

3.3.5 (b) Temperature Programmed Desorption

Focussing on O$_2$ desorption once again, and excluding a figure for O$_3$ desorption as any simple TPD profile of O$_3$ is, in itself, unrevealing, Figure 3.21 can be analysed of O$_2$ desorption from a multilayer of CSW.

Figure 3.21 has yielded a sharp leading edge at a temperature similar to that seen when O$_2$ desorbs from SiO$_2$ (Figure 3.8). The insert in Figure 3.21 is of the Arrhenius plot for this TPD profile and the clear leading edge in the TPD spectrum is noticeable in the insert. This insert is used to extract the kinetic information regarding this desorption process which will be used in a CKS model similar to the analysis and models previously described. The model and reaction steps used can be seen in Equation 3, following the fitting of the model to the experimental data, Figure 3.22 can be made.

Figure 3.21: The figure illustrates the shape as O$_2$ is desorbed from SiO$_2$ after a 50 minute atomic beam dose. The reason for the long trailing edge of this multilayer desorption spectra is believed to be due to the O atom beam affecting the morphology of the CSW surface. The insert sheds light on the desorption kinetics through linear analysis of the red points.
Figure 3.22: This figure shows the similarity in the leading edge of the experimental data and the CKS model of O$_2$ desorption from CSW after 50 minute O atoms beam dosing.

From the CKS model as compared to the experimental data (Figure 3.22) the final kinetic parameters of $6.7 \pm 0.2$ kJ mol$^{-1}$ and $5 \times 10^{27\pm1}$ molecules cm$^{-2}$ s$^{-1}$ can be evaluated against the other experiments. Again the value of $E_{des}$ is seen to be below the literature of about 7.5 kJ mol$^{-1}$, which can be explained as in the previous cases.

3.3.6 O$_3$ Characterisation

As can be seen from the individual O$_3$ TPD experiments, the peaks are not particularly intense. Furthermore, O$_3$ desorption unfortunately occurs in the same temperature range as O$_2$ desorption from the cold finger. Hence as O$_3$ desorption is monitored through the m/z = 32 fragment TPD traces are mixtures of O$_2$ and O$_3$ and not pure O$_3$. Co–adding each O$_3$ TPD spectra at m/z = 48 can be done and a more defined peak can be obtained as seen in Figure 3.23.
Figure 3.23: This figure shows the result of adding all the TPD spectra into one graph. A clearly defined peak is observed which can be used for further analysis.

The heating rates for all the O$_3$ desorption experiments are similar and only vary by 0.07 K s$^{-1}$, allowing the simple co–addition to work successfully, however, great care was still used when lining up the peaks of desorption leading to the co–addition. The initial stage of O$_3$ desorption can be seen at about 50 K with a peak at about 55 K. No other evidence of O$_3$ desorption is apparent at other temperatures, such as volcano desorption when 50 ML ASW crystallises or co–desorption with H$_2$O. These temperature values are consistent with the literature of 55 K [41]. However, the double peak observed by Minissale et al. [42] was not clearly observed due to less resolved spectra and possibly as a result of co–adding all the spectra. The double peak in the work of Minissale et al. [42] corresponds to multilayer desorption at a lower temperature and monolayer desorption at higher temperatures. However, the shoulder forming at higher temperatures of about 62 K could possibly be the monolayer, but more experimental data would be needed to confirm this assignment.

Inverting Figure 3.23 means the Arrhenius parameters can be extracted. The inversion has been shown in Figure 3.24 where the red points corresponds to the leading edge of desorption.
Figure 3.24: This inverted figure leads to the desorption energy through the gradient of the red line while the intercept gives an indication of the pre–exponential factor.

Fitting the red region in Figure 3.24 with a straight line gives an estimate of the desorption energy from the gradient and the pre–exponential factor from the intercept. These initial values are about 15.4 kJ mol$^{-1}$ for the desorption energy and $10^{33}$ molecules cm$^{-2}$ s$^{-1}$ for the pre–exponential factor. From here, a simple CKS analysis can be used to obtain better kinetic values for the desorption of O$_3$ from a SiO$_2$ surface. The simple steps are shown in Equation 6 for O$_3$ on the surface (s), in the gas phase (g) and when it is being pumped out of the chamber (pump).

\[
\begin{align*}
\text{O}_3 \ (s) & \rightarrow \text{O}_3 \ (g) \quad \text{Equation 6 (A)} \\
\text{O}_3 \ (g) & \rightarrow \text{O}_3 \ (\text{pump}) \quad \text{(B)}
\end{align*}
\]

The pumping stage is temperature independent and has an associated rate constant of 0.03 cm$^2$ mol$^{-1}$ s$^{-1}$ to model the pumping speed of the diffusion pump. With these steps and experimental results in mind, remembering that the heating rate was 0.17 K s$^{-1}$, the CKS model was optimised and the simulated spectra can be compared to the experimental as seen in Figure 3.25.
Figure 3.25: This figure shows the correlation between the experimental data (black scatter) and the model (red solid line) of O$_3$ desorption.

As can be seen in Figure 3.25, the model fits the experimental data. The model was generated using a desorption energy of 14.7 ± 0.5 kJ mol$^{-1}$ which is similar to He et al. and Jing et al. [9, 43] who reported a value of 15.2 ± 0.5 kJ mol$^{-1}$.

3.3.7 O$_3$ Formation and Destruction

Looking at the combined TPD traces of O$_3$ (for instance Figure 3.23) one can see the total MS count rate being minor as compared to a general O$_2$ TPD spectra. Considering the MS counts as being directly proportional to the molecular concentration on the surface it can be said that the TPD experiments show a ratio of 0:1 for O$_3$ to O$_2$ when integrating the desorption peak of O$_3$ (Figure 3.23) and O$_2$ (e.g. Figure 3.10). As has also been said in this report, issues with measuring O$_3$ desorption due to cold finger desorption of O$_2$, along with O$_3$ dissociating in the MS head, meant that this O$_2$:O$_2$ ratio is not precise. Further to this, O$_3$ can be destroyed by addition of O atoms as seen in Equation 4.

The work of Minissale et al. [18, 44] has shown that O and O$_2$ diffuse with an activation energy as low as 2.4 kJ mol$^{-1}$ on silicate surfaces. Minissale et al. have also considered O$_2$ and O$_3$ formation pathways as occurring with no reaction barrier. With this in mind the reaction steps in Equation 7 can be setup to study O$_3$ formation and destruction.
The bracketed terms of g, surf and diff refer to atoms and molecules either in the gas–phase, on the surface or diffusing on the surface, respectively. The gas phase concentration of O atoms and O\(_2\) molecules are taken from the estimated beam flux of about 5.8 \times 10^{14} \text{ molecules cm}^{-2} \text{ s}^{-1} and cracking fraction of about 20%. A sticking coefficient of unity has been considered for steps (A) and (B), while diffusion parameters are taken from Minesale et al. as mentioned previously. The destruction of O\(_3\) by addition of another O atom has not been discussed to a great extent in this chapter, however such a step has been included in this model. Parameters for this destruction reaction are not easily come by, however it has been mentioned in similar experiments as being negligible [18, 41]. Since no values for the energy or pre–exponential factor are available, a variety of values will be used to show the possible extent of O\(_3\) destruction.

- Chapman type chemistry: With a reaction barrier of about 17 kJ mol\(^{-1}\), O\(_3\) and O combine to form 2O\(_2\) in the gas–phase in the atmosphere of the Earth. For this reaction to occur in the solid state, the dependency on the diffusion or hopping rate of O atoms is needed. This hopping rate becomes the pre–exponential factor for the destruction mechanism of O\(_3\).

- Barrierless reaction: All chemical reactions are considered as proceeding with no activation barrier.

The hopping rate, \(\Gamma\), can be calculated through an Arrhenius–type equation, Equation 8.
Initially, with a temperature of 17 K, Equation 8 gives a value of $4.22 \times 10^4$ s$^{-1}$, but is naturally dependent on temperature, $T$. With this estimate of the pre–exponential factor and with the two limits discussed in the bulleted list above, the CKS model can be setup as seen in Table 3.3 and depicted in Figure 3.26. As can be seen, the models have been computed over a variety of deposition temperatures ranging from 7 K to 52 K. Also, the pre–exponential factor has been varied by $\pm 10^5$ s$^{-1}$ due to its unknown nature which lead to no change in the O$_3$:O$_2$ ratio. The lower–end of the uncertainty leading to a pre–exponential factor of $10^{-1}$ s$^{-1}$ has not been shows as this lead to all O$_3$ remaining intact. Further to this, the high–end uncertainty level leads to negligible level of O$_3$ destruction.

<table>
<thead>
<tr>
<th>Temperature / K</th>
<th>Barrierless O$_2$:O$_3$</th>
<th>Barrierless O$_3$:O$_2$</th>
<th>$E_A = 17$ kJ mol$^{-1}$ and $\nu = 4.22 \times 10^4$ O$_2$:O$_3$</th>
<th>O$_3$:O$_2$</th>
</tr>
</thead>
<tbody>
<tr>
<td>7</td>
<td>1:0.16</td>
<td>1:0.09</td>
<td>1:0.25</td>
<td>1:0.00</td>
</tr>
<tr>
<td>12</td>
<td>1:0.16</td>
<td>1:20</td>
<td>1:0.25</td>
<td>1:0.00</td>
</tr>
<tr>
<td>17</td>
<td>1:0.16</td>
<td>1:21</td>
<td>1:0.25</td>
<td>1:0.00</td>
</tr>
<tr>
<td>22</td>
<td>1:0.16</td>
<td>1:20</td>
<td>1:0.25</td>
<td>1:0.00</td>
</tr>
<tr>
<td>27</td>
<td>1:0.16</td>
<td>1:20</td>
<td>1:0.25</td>
<td>1:0.00</td>
</tr>
<tr>
<td>32</td>
<td>1:0</td>
<td>1:20</td>
<td>1:0</td>
<td>1:0.00</td>
</tr>
<tr>
<td>37</td>
<td>1:0</td>
<td>1:21</td>
<td>1:0</td>
<td>1:0.00</td>
</tr>
<tr>
<td>42</td>
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<td>1:0.00</td>
</tr>
<tr>
<td>47</td>
<td>1:0</td>
<td>1:20</td>
<td>1:0</td>
<td>1:0.00</td>
</tr>
<tr>
<td>52</td>
<td>1:0</td>
<td>1:21</td>
<td>1:0</td>
<td>1:0.00</td>
</tr>
</tbody>
</table>

Table 3.3: This table shows the results of the different limits put onto the CKS model for investigating the O$_2$ and O$_3$ formations in columns two and four (labelled O$_2$:O$_3$) and O$_2$ destruction (labelled O$_3$:O$_2$) in columns three and five. As can be seen, a greater extent of O$_3$ is produced than observed in the TPD experiments with negligible destruction.

What can be seen in Table 3.3 and Figure 3.26 is O$_3$ formation and destruction leading to 2O$_2$ molecules. The barrierless reaction does show O$_3$ decomposition while the reactions with a barrier show negligible destruction. Further to this, leaving the reaction energy as 17 kJ mol$^{-1}$ and increasing the pre–exponential factor to a value of $10^{50}$ leads to an O$_3$:O$_2$ ratio of 1:0.06. With this simple CKS model, it can be said that O$_3$
Figure 3.26: This figure shows the results as gathered from the CKS model and presented in Table 3.3. Formation of O₃ (A) occurs as expected, however to a greater extent than shown in the experimental TPD data. O₃ destruction (B) has also been shown in this figure and is considered not to be the cause for the lack of O₃ signal during desorption in the TPD experiments.

destruction by reactions of diffusing O atoms is negligible which has also been the conclusion of Minissale et al. [18]. Sivaramen et al. [41] have stated that O atoms prefer to react with other O atoms to form O₂ as compared to reacting with O₂ molecules to form O₃. This, by extension, could mean that O atoms are even less likely to react with O₃ molecules, which is what this simple CKS model indicates. Overall the CKS model shows that O₃ is created to a greater degree than what is observed experimentally through the TPD experiments. Also, the O₂:O₃ ratio cannot be determined through IR as O₂ is not observed in these experiments.

The simulated data presented in Table 3.3 and Figure 3.26 range from 7 K to 52 K. At temperatures above 37 K O₂ is not expected to reside on a SiO₂ surface for long and will naturally not yield an experimental TPD trace, however these simulations were done without the TPD model as they were done in the previous sections. The fundamental reason for including these values was to examine what effect the temperature has on O₃ formation and destruction. As seen, for temperatures above 32 K the O₂:O₃ ratio shows only O₂ which would not be expected in experimental TPD experiments. However, O₃
destruction is only observed for barrierless reactions, but the extent of simulated destruction when no barrier is present (around 20%) does not fully explain the lack of O\textsubscript{3} signal during TPD experiments. This, therefore, leads back to the previous idea that O\textsubscript{2} contamination from cold finger desorption is the cause of lack of O\textsubscript{3} signal along with a great extent of O\textsubscript{3} decomposition with the QMS filaments. Also, experiments with different deposition temperatures were not conducted, however a lesser amount of O\textsubscript{3} would be expected as the temperature is raised as there will be less O\textsubscript{2} molecules present on the SiO\textsubscript{2} surface as explained by the TPD experiments.

3.4 Conclusion

This chapter has discussed one of the steps in the H\textsubscript{2}O formation pathway in the interstellar environment. To do this O\textsubscript{2} molecules were initially beam dosed onto a bare SiO\textsubscript{2} surface and subsequently desorbed through temperature programmed desorption (TPD). This lead to higher values of \( E_{\text{des}} \) as compared to background dosed O\textsubscript{2}; 8.5 kJ mol\textsuperscript{-1} and 7.5 kJ mol\textsuperscript{-1} respectively. Atomic beam dosing of O onto SiO\textsubscript{2} leads to a significant reduction in the \( E_{\text{des}} \) which further changed as the SiO\textsubscript{2} was covered in different forms of H\textsubscript{2}O. The experimental values have been summarised in Table 3.4.

<table>
<thead>
<tr>
<th>O\textsubscript{2} beam</th>
<th>O atomic beam</th>
</tr>
</thead>
<tbody>
<tr>
<td>( E_{\text{des}} / \text{kJ mol}^{-1} )</td>
<td>( \nu / \text{molecules cm}^{-2} \text{s}^{-1} )</td>
</tr>
<tr>
<td>SiO\textsubscript{2}</td>
<td>SiO\textsubscript{2}</td>
</tr>
<tr>
<td>8.5 ± 0.1</td>
<td>6.7 ± 0.2</td>
</tr>
<tr>
<td>4 \times 10^{30±1}</td>
<td>4 \times 10^{27±1}</td>
</tr>
</tbody>
</table>

Table 3.4: This table shows the TPD results of O\textsubscript{2} desorption. The first column of values is of O\textsubscript{2} desorption after having been beam dosed onto the bare SiO\textsubscript{2} sample. The other columns are of O\textsubscript{2} having been dosed with the atomic beam onto the different surfaces.

As can be seen in Table 3.4, the overall results vary in a significant fashion as the underlayer changes. The reasons for this have been discussed throughout this chapter, where the deposition method has been argued to be the main reason for the changes in the O\textsubscript{2} beam dosing experiment as compared to background dosing. Also, amorphisation during the reactions has been indicated as possibly being the reason for the changes when different H\textsubscript{2}O multilayers are deposited prior to O atom dosing. Further to the desorption experiments, no reactive desorption of any species was observed during
beam dosing. This does not mean that reactive desorption does not occur, however more experiments will be needed to further study this.

O$_3$ has been observed to be formed no matter the surface and with no relative change in amount of formation. Individual TPD traces of O$_3$ do not lead to much information as seen. The reason for this is that O$_3$ decomposes as it interacts with the QMS during the experiments leading to part of m/z = 32 and 16. These masses were recorded in all experiments, however O$_3$ desorption has been shown to occur at the same time as O$_2$ desorption from the cold finger. With a considerable O$_2$ desorption from the cold finger also contributing to the increase in m/z = 16, O$_3$ desorption could not be determined through the O or O$_2$ TPD traces. However, co–addition of the O$_3$ TPD experiments did lead to an overall desorption peak. This peak has a considerable amount of uncertainty. However, an $E_{des}$ value of 14.7 ± 0.5 kJ mol$^{-1}$ was estimated through CKS which is very similar to the literature. To summarise the overall results of the O$_3$ band on the different surfaces as studied through RAIRS, Table 3.5 has been constructed.

<table>
<thead>
<tr>
<th></th>
<th>SiO$_2$ (± 1)</th>
<th>p–ASW (± 1)</th>
<th>c–ASW (± 1)</th>
<th>CSW (± 1)</th>
<th>Literature (± 2)</th>
</tr>
</thead>
<tbody>
<tr>
<td>[O$_3$...O] / cm$^{-1}$</td>
<td>1031</td>
<td>1031</td>
<td>1032</td>
<td>1032</td>
<td>1032</td>
</tr>
<tr>
<td>O$_3$ O–O asymmetric stretch / cm$^{-1}$</td>
<td>1036</td>
<td>1037</td>
<td>1037</td>
<td>1037</td>
<td>1037</td>
</tr>
<tr>
<td>[O$_3$...O$_3$] / cm$^{-1}$</td>
<td>1045</td>
<td>1045</td>
<td>1045</td>
<td>1045</td>
<td>1042</td>
</tr>
</tbody>
</table>

Table 3.5: This table summarises all the values of the O$_3$ band from the different surfaces after they have been fitted with Gaussians as compared to the literature values [16].

Table 3.5 shows the component of the O$_3$ band and their frequencies as H$_2$O is added and changed in the different experiments discussed in this chapter. As can be seen, the values of the O$_3$ components do not change as the substrate changes and are similar to the literature values [16] when considering the uncertainties. The invariance in the RAIRS band of O$_3$ could indicate that the formed molecules are imbedded in an O$_2$ matrix, O$_3$ islands on the differing surfaces or 20 ML does not cover the entire SiO$_2$ surface on where O$_3$ would then prefer to be adsorbed directly onto SiO$_2$. From this stage, hydrogenation of O$_3$ has been shown to lead to H$_2$O [45].
3.5 References


Chapter 4

Towards a more Realistic Icy Grain Mantle Model

Contents of this chapter

4.1 Introduction ........................................................................................................... 118
4.2 Experimental ....................................................................................................... 119
4.3 Results and Discussion ...................................................................................... 120
  4.3.1 H₂O de-wetting ............................................................................................ 120
  4.3.2 O Atom Bombardment of H₂O Films ............................................................ 130
4.4 Astrophysical Implications of H₂O De-Wetting ................................................ 135
4.5 Conclusion .......................................................................................................... 140
4.6 References .......................................................................................................... 143
4.1 Introduction

Having investigated one of the key sequences of reactions in the H$_2$O formation cycle, the thesis will now turn to look at how such multilayers begin to form on interstellar dust grains. H$_2$O has recently been of interest again with the Rosetta mission as it was found in the solid state on the comet 67P / Churyumov–Gerasimenko [1]. Reactive accretion is the dominant formation route of H$_2$O, however adsorption of H$_2$O from the gas–phase also occurs to a minor extent. In the early stages of mantle formation on a dust grain only small coverages of H$_2$O will be formed on the bare surface before it builds a coat. Temperature programmed desorption, TPD, experiments of H$_2$O have consistently shown zero order desorption kinetics on SiO$_2$ [2], on Au [3], Sapphire [4] and Ru (000)/Al(001) [5]. As explained in Chapter 2, TPD probes the surface–adsorbate and adsorbate–adsorbate interactions through analysis of the leading edges and the maximum temperature of desorption. The results of this kind of analysis allow one to say that the H$_2$O–H$_2$O interaction is favoured over the H$_2$O–SiO$_2$ interaction. The H$_2$O–H$_2$O interaction being dominant is indicative of multilayer desorption with ballistic deposition [6] (hit–and–stick adsorption) as likely occurs at cryogenic temperatures of the ISM [7], a mixture of isolated monomers or random sized groups of H$_2$O is produced on the grain surface. This would mean that H$_2$O begins to become mobile at some temperature, leading to cluster formation, before desorption ensues. So, when does a sub–monolayer coverage of H$_2$O become a multilayer? One way of observing how H$_2$O behaves on a SiO$_2$ surface is by using RAIR spectroscopy. This chapter illustrates what happens on the grain surface in the initial conditions of low H$_2$O coverage.

Preliminary experimental results can be found in the literature where 0.5 ML H$_2$O was deposited on SiO$_2$ at 20 K and progressively annealed in 20 K steps [2]. These results show a marked change in the intensity profile of the νO–H stretching region of RAIRS as H$_2$O is annealed as seen in Figure 4.1.

Similar IR based techniques have been used to study the movement of, for instance, CH$_3$OH and (CH$_3$CH$_2$)$_2$O (diethyl ether) on SiO$_2$ [9] and HCl on H$_2$O surfaces [10].
Figure 4.1: Temperature programmed RAIRS of 0.5 ML H$_2$O on SiO$_2$ showing an increasing intensity of the νOH band as the temperature increases. The magenta band shows a 20 ML spectrum of H$_2$O, as can be seen, the annealed appear similar to the multilayer. The sharp features are due to gas–phase water in the optics boxes on the air side of the UHV apparatus. This figure is taken from [2] and [8].

One interesting aspect of looking at the movement of H$_2$O on a dust grain analogue surface has to do with the Onion model [11, 12] as discussed in Chapter 1. The model describes how the polar H$_2$O layer forms and a layer of apolar CO covers it being a large consituent of the icy mantle [13]. Another way of thinking of the layer formation is in terms of H–bond capability. Naturally, since H$_2$O is the dominant part, a multilayer is expected, but a precise description of the construction of the polar layer is not available. The idea of a H$_2$O multilayer shielding the dust grain from other molecules is proposed through the Onion model, however if water is mobile at cryogenic temperatures, the whole grain might not be shielded by the H$_2$O. This would lead to a mixture of binding sites where other icy mantle molecules will find the optimum binding site on H$_2$O clusters or bare dust grain surfaces.

4.2 Experimental

The general equipment and experimental method were detailed in Chapter 2. The specific steps used to obtain the results for this chapter are, however, briefly explained here. Before any results were obtained the sample was cleaned by heating the sample to 220 K for a variable time. The heating time was dependent on the level of H$_2$O in the
chamber as determined by the QMS, when a quantity of H₂O amounting to 2 × 10⁻¹⁰ mbar or lower was reached the cleaning process was stopped and the sample was left to cool to base temperature. H₂O was prepared by three freeze–pump–thaw, FPT, cycles and the glass gas handling line was purged with water vapour to ensure a high purity of H₂O. Background dosing of 0.5 ML H₂O was done after the initial set of background and bare sample RAIR spectra. The H₂O film was annealed from base temperature of 17 K to the specified temperatures of 18, 21, 24, 27, 30, 40, 50, 60 and 100 K as stated in the results in Section 4.3.1 at 100 s steps for a total of 500 s. After this stage a final annealing step was conducted at 100 K for 20 min. RAIR spectra were collected on these H₂O coverages and temperatures with a resolution of 1 cm⁻¹ and a total of 512 scans per experiments and all data was collected by the liquid nitrogen cooled mercury cadmium telluride, MCT, detector. Initial testing of the time between RAIR scans at temperature >18 K was on average 1 hr. For that reason, the time taken between RAIRS spectra collected at ≤18 K was also 1 hr. To minimise the effect of gas–phase water re–adsorbing on the sample and biasing the experimental results, only one experiment was done per day.

4.3 Results and Discussion

4.3.1 H₂O De–Wetting

Due to repairs on the UHV apparatus, as briefly mentioned in Chapter 2, the system was baked before the H₂O de–wetting experiments were initiated. This helped to reduce the background contamination of H₂O However, additional measurements and tests were conducted to look at H₂O partial pressure effects and the effect of re–adsorption of H₂O after a temperature programmed desorption experiment.

Measuring the background levels of H₂O vapour in the UHV chamber is important as any extra adsorption of H₂O will inevitably lead to an increase of the νOH stretch in a RAIR spectrum. The partial pressure of H₂O was measured by background filling the chamber with H₂O at certain pressures, 1 × 10⁻⁸, 5 × 10⁻⁸, 1 × 10⁻⁷, 5 × 10⁻⁷ and 1 × 10⁻⁶ mbar, with the QMS measuring the counts of m/z = 18. The pressure reading was allowed to stabilise and left at said pressures for one minute at a time. The results are shown in Figure 4.2.
Figure 4.2: This plot shows the correlation between pressure in mbar and counts of m/z = 18 as monitored by the QMS. This linear relationship between pressure and counts was used throughout to note the background H2O pressure during an experiment.

The test concerning the TPD experiments were done by depositing 0.5 ML H2O onto the sample and collecting an IR spectrum. The film was then desorbed by heating the sample with a 0.04 K s⁻¹ heating ramp, after desorption from the sample the temperature was kept at 170 K. The QMS monitored this process and when the counts reached a plateau equivalent to 2 × 10⁻¹⁰ mbar of H2O, the sample was cooled to 17 K where another IR scan was collected. The results of this test are shown in Figure 4.3 below.

Figure 4.3: These spectra show the deposition of 0.5 ML H2O (black) on SiO₂ followed by TPD of that film. After the partial pressure of H₂O has decreased to <2 × 10⁻¹⁰ mbar the sample was cooled and another spectrum was taken (red). Re-adsorption of H₂O on the timescale of the experiment is not significant due to the low H₂O partial pressure.
The red spectrum in Figure 4.3 displays a clear absence of H\textsubscript{2}O. Maintaining a surface temperature greater than the desorption temperature of H\textsubscript{2}O on SiO\textsubscript{2} until the QMS indicates a low partial pressure means re–adsorption of H\textsubscript{2}O is negligible. Following the knowledge that a partial pressure of H\textsubscript{2}O <2 \times 10^{-10} \text{mbar} leads to no H\textsubscript{2}O RAIRS observable adsorption, all IR scans reported in this work have been conducted in this low partial pressure regime. The QMS was continuously used to verify this, and following background filling the chamber with 0.5 ML H\textsubscript{2}O, the first RAIR spectrum was only taken when the QMS counts were deemed sufficiently low to reflect these observations.

With these constraints in mind, dosing 0.5 ML H\textsubscript{2}O at base temperature and conducting the time dependent experiment, yields Figure 4.4 below. From here on the initial spectra of 0.5 ML H\textsubscript{2}O deposited on SiO\textsubscript{2} will be referred to as \( A_0 \) while the final annealing step at 100 K for 20 minutes will be referred to as \( A_{\infty} \) or \( A_\infty \).

![Absorbance vs. Wavenumber](image_url)

**Figure 4.4:** The result of depositing 0.5 ML H\textsubscript{2}O onto SiO\textsubscript{2} at 18 K. The time between each RAIR spectrum was one hour as this was determined to be the average time between scans when H\textsubscript{2}O is annealed at the other temperatures investigated. The sharp peaks are due to gas–phase H\textsubscript{2}O in the optics boxes on the air side of the UHV apparatus.

What is observed in Figure 4.4 is initially only the red trace. This was collected when the background partial pressure of H\textsubscript{2}O was in <2 \times 10^{-10} \text{mbar}. The film was then left for one hour before the next spectrum was collected giving the blue broad band of νOH.
The increase in absorbance throughout of 0.5 ML H$_2$O continues for the next spectra before the film is annealed at 100 K to get the $A_{\infty}$, or $A_\infty$, spectrum. The same experiments were done for annealing temperatures of 18, 21, 24, 27, 30, 40, 50, 60 and 100 K which all show the same trend in increasing absorbance with temperature. **Figure 4.5** shows the result of annealing 0.5 ML H$_2$O at 100 K for a total of 500 seconds.

![Graph showing absorbance vs. wavenumber](image)

**Figure 4.5**: The result of depositing 0.5 ML H$_2$O onto SiO$_2$ at 100 K for a total of 500 sec before annealing to the $A_{\infty}$ times, $A_\infty$, factor. The sharp peaks at 3500 – 3600 cm$^{-1}$ are due to gas-phase H$_2$O in the optics boxes on the air side of the UHV rig.

In **Figure 4.5**, the same trend can be seen as that of **Figure 4.4** with an increase of absorbance as a function of annealing time at 100 K, albeit a greater change from the $A_0$ spectrum to the first of the annealing times of 100 s. H$_2$O molecules accommodate on the SiO$_2$ surface *via* a hit–and–stick mechanism at the cryogenic temperatures. However, as the partial pressure of H$_2$O is negligible, meaning further adsorption of H$_2$O after the $A_0$ trace is close to zero, another process must cause the increases in the observed absorbencies. De–wetting of H$_2$O molecules forming H–bonded islands and clusters would explain this. This can be seen in **Figure 4.5** where the main νOH band centred at roughly 3250 cm$^{-1}$ for the $A_0$ spectra (the red trace) and the minor peak at just above 3400 cm$^{-1}$. These are the TO and LO modes of amorphous solid water [14]. As has been explained in **Chapter 2**, the LO–TO modes only occur in a 3–D network indicating that the 17 K spectra have enough of a bulk network to create this optical effect at sub–monolayer coverages. The dangling bond of H$_2$O at about 3692 cm$^{-1}$ [15–
cannot be observed in these experiments due to gas–phase H₂O interference in the optics boxes. Smaller clusters such as dimers, trimers and tetramers [18, 19] also appear in the regions of the spectra where gas–phase H₂O is dominant and were not observed either. However, as H₂O is mobile at the base temperature of these experiments such observations were not expected.

The band profiles between Figure 4.4 and 4.5 are the same, and as can be seen in Figure 4.5, annealing at 100 K still shows increases in the absorbance. The increase in absorbance means the de–wetting process still occurs and that H₂O is still forming clusters at this high temperature. For all the experiments below 100 K, the A∞ factor has been estimated by annealing the 0.5 ML H₂O coverage at 100 K, however as Figure 4.5 still shows absorbance increases A∞ must be an underestimate. A correction for all A∞ spectra has to be made which is done by depositing 0.5 ML H₂O at 17 K, annealing this to 100 K for 20 minutes (the usual A∞ spectra) before taking a spectrum and then annealing it further for 120 minutes. The results of this can be seen in Figure 4.6 below.

![Figure 4.6](image)

**Figure 4.6:** These spectra show the change when depositing 0.5 ML H₂O at 17 K before annealing to 100 K for 20 minutes and again for 120 minutes.

A change in the absorbance in Figure 4.6 is still observed, albeit a slight change of a factor of 1.25, and the difference in the area of the vOH band between the two 100 K spectra is used to scale all A∞ spectra. The reason for this correction is to approach a closer and more accurate value of A∞ used for calculating the activation energy for de–
wetting of H\textsubscript{2}O from SiO\textsubscript{2} where all H\textsubscript{2}O molecules have formed a bulk solid, \textit{i.e.} a multilayer of H\textsubscript{2}O. A further increase is expected if the annealing time is increased to a greater value, however this was not done as only a relatively small change is observed in \textbf{Figure 4.6} after increasing the annealing time six–fold.

An example of the values obtained can be seen in \textbf{Table 4.1} for the 24 K annealing experiment (not shown).

<table>
<thead>
<tr>
<th>Time / s</th>
<th>Integrated Absorbance</th>
<th>Corrected Integrated Absorbance</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>0.480</td>
<td>–</td>
</tr>
<tr>
<td>100</td>
<td>0.566</td>
<td>–</td>
</tr>
<tr>
<td>200</td>
<td>0.603</td>
<td>–</td>
</tr>
<tr>
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<td>0.663</td>
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</tr>
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<td>0.748</td>
<td>–</td>
</tr>
<tr>
<td>500</td>
<td>0.793</td>
<td>–</td>
</tr>
<tr>
<td>1200</td>
<td>1.340</td>
<td>1.678</td>
</tr>
</tbody>
</table>

\textbf{Table 4.1}: This table shows the areas of the νOH band after the spectra have been baseline corrected and smoothed. The correction of the $A_\infty$ value comes as a result of \textbf{Figure 4.6}.

The values seen in \textbf{Table 4.1} are the results for the integrated smoothed spectra in the region of 3050 – 3500 cm\textsuperscript{-1}. The reason for this range and the smoothening is to minimise the additional area added to the experimental results from gas–phase H\textsubscript{2}O observed as sharp peaks at higher wavenumbers in \textbf{Figure 4.4}.

If we assume that the de–wetting process:

$$\text{H}_2\text{O}_{\text{isolated}} \rightarrow \text{H}_2\text{O}_{\text{clustered}}$$  \hspace{1cm} \textbf{Equation 1}

follows first order kinetics with time, $t$:

$$[\text{H}_2\text{O}_{\text{isolated}}]_t = [\text{H}_2\text{O}_{\text{isolated}}]_0 e^{-kt}$$  \hspace{1cm} \textbf{Equation 2}

with a rate constant, $k$, then a simple kinetic analysis of the spectroscopic data gives \textbf{Equation 3} [20]
\[ \ln \left( \frac{A_\infty - A_0}{A_\infty - A_t} \right) = kt \]

Equation 3

where \( t \) is the annealing time at a set temperature. This leads to **Table 4.2**:

<table>
<thead>
<tr>
<th>Time / s</th>
<th>Area under spectra</th>
<th>Corrected area for ( A_\infty )</th>
<th>( \ln \left( \frac{A_\infty - A_0}{A_\infty - A_t} \right) )</th>
</tr>
</thead>
<tbody>
<tr>
<td>0</td>
<td>0.480</td>
<td>–</td>
<td>0</td>
</tr>
<tr>
<td>100</td>
<td>0.566</td>
<td>–</td>
<td>0.105</td>
</tr>
<tr>
<td>200</td>
<td>0.603</td>
<td>–</td>
<td>0.154</td>
</tr>
<tr>
<td>300</td>
<td>0.663</td>
<td>–</td>
<td>0.239</td>
</tr>
<tr>
<td>400</td>
<td>0.748</td>
<td>–</td>
<td>0.373</td>
</tr>
<tr>
<td>500</td>
<td>0.793</td>
<td>–</td>
<td>0.452</td>
</tr>
<tr>
<td>1200</td>
<td>1.340</td>
<td>1.678</td>
<td>–</td>
</tr>
</tbody>
</table>

**Table 4.2**: This table shows the next step in the analysis using **Equation 3**. The areas used come from smoothing of the spectra for the 24 K de–wetting experiment.

Constructing a graph, **Figure 4.7**, from **Table 4.2** leads to the value of \( k \) in the linear relationship, **Equation 3**, as expected from a first order process.

![Figure 4.7](image)

**Figure 4.7**: This figure shows the linear relationship of **Equation 3**. The slope is the rate constant, \( k \), for the isolated \( \text{H}_2\text{O} \) to a bulk process. The values for this figure are obtained from **Table 4.2**.

With a value of \( k \) for the experiment involving an annealing temperature of 24 K, and doing the same analysis for the other experiments leads to **Table 4.3**.
<table>
<thead>
<tr>
<th>$T_{\text{anneal}} / \text{K} (\pm 0.3 \text{ K})$</th>
<th>$1/T_{\text{anneal}} / \text{K}^{-1}$</th>
<th>$k / \text{s}^{-1} (\pm 3%)$</th>
<th>$\ln(k / \text{s}^{-1})$</th>
</tr>
</thead>
<tbody>
<tr>
<td>17</td>
<td>0.059</td>
<td>$2.432 \times 10^{-3}$</td>
<td>$-10.624$</td>
</tr>
<tr>
<td>18</td>
<td>0.056</td>
<td>$3.640 \times 10^{-3}$</td>
<td>$-10.221$</td>
</tr>
<tr>
<td>21</td>
<td>0.048</td>
<td>$5.188 \times 10^{-4}$</td>
<td>$-7.564$</td>
</tr>
<tr>
<td>24</td>
<td>0.042</td>
<td>$8.894 \times 10^{-4}$</td>
<td>$-7.025$</td>
</tr>
<tr>
<td>27</td>
<td>0.037</td>
<td>$8.788 \times 10^{-4}$</td>
<td>$-7.037$</td>
</tr>
<tr>
<td>30</td>
<td>0.033</td>
<td>$1.508 \times 10^{-3}$</td>
<td>$-6.497$</td>
</tr>
<tr>
<td>40</td>
<td>0.025</td>
<td>$2.046 \times 10^{-3}$</td>
<td>$-6.192$</td>
</tr>
<tr>
<td>50</td>
<td>0.020</td>
<td>$1.392 \times 10^{-3}$</td>
<td>$-6.577$</td>
</tr>
<tr>
<td>60</td>
<td>0.0167</td>
<td>$1.300 \times 10^{-3}$</td>
<td>$-6.645$</td>
</tr>
<tr>
<td>100</td>
<td>0.1</td>
<td>$1.400 \times 10^{-3}$</td>
<td>$-6.571$</td>
</tr>
</tbody>
</table>

Table 4.3: This table shows the individual values of the rate constant, $k$, with respect to its annealing temperature. Plotting the inverse temperature and the $\ln(k)$ will lead to the associated energy through Equation 4.

The results of Table 4.3 lead to the Arrhenius plot which is shown in Figure 4.8 below.

Figure 4.8: This figure shows the Arrhenius plot where two regimes can be observed. The first regime, a), illustrates a rising edge while b) indicates a plateau. A series of fits have been done to estimate an average gradient for each a) and b) in order to obtain an activation energy, however a clear change is apparent as the temperature increases. The figures have been shown in two parts for clarity with matching colours for the linear fits.
As can be seen in Figure 4.8, two clear regions are presented. The initial region, Figure 4.8a, represents the value of \( \ln(k) \) as the annealing temperature is increased. A clear rise is apparent which leads to a plateau region as shown in Figure 4.8b. The exact temperature separating the regions can be argued and for that reason linear fits have been done to various points as seen in Figure 4.8 where the colour coding matches each \( a \) and \( b \) sections. Table 4.4 states the values of the gradient for each linear fit plotted in Figure 4.8a and 4.8b above.

<table>
<thead>
<tr>
<th>Linear fit</th>
<th>Rising edge / K(^{-1})</th>
<th>Plateau / K(^{-1})</th>
</tr>
</thead>
<tbody>
<tr>
<td>Black</td>
<td>(-284.595 (± 47.709))</td>
<td>(-14.022 (± 9.709))</td>
</tr>
<tr>
<td>Red</td>
<td>(-229.971 (± 35.877))</td>
<td>(-8.526 (± 12.591))</td>
</tr>
<tr>
<td>Blue</td>
<td>(-184.503 (± 35.636))</td>
<td>8.928 (± 10.496)</td>
</tr>
<tr>
<td>Green</td>
<td>(-166.972 (± 27.509))</td>
<td>23.285 (± 16.199)</td>
</tr>
<tr>
<td>Average</td>
<td>(-216.510 (± 36.683))</td>
<td>2.416 (± 12.249)</td>
</tr>
</tbody>
</table>

Table 4.4: This table shows the gradients for the linear fits of Figure 4.8a and 4.8b.

Taking the average values for the slopes from Figure 4.8 leads to a simpler graph as seen below, Figure 4.9.

![Figure 4.9: This figure shows the final step after analysis with an indication of the best linear fits to the two data regions in the experimental results.](image)
This method of analysis has been used for finding activation energies, $E_{act}$ for various purposes such as desorption energy from temperature programmed desorption [21].

$$\ln(k) = \ln(A) - \frac{E_{act}}{RT}$$

where $A$ is the pre–exponential factor, $R$ is the ideal gas constant and $T$ is the temperature. The associated values for the energies from Figure 4.9 can be calculated by considering Equation 4 and a value for $R$ of 8.314 J K$^{-1}$ mol$^{-1}$. This has been shown in Table 4.5.

<table>
<thead>
<tr>
<th>$E_{act}$ / kJ mol$^{-1}$</th>
<th>Rising edge</th>
<th>Plateau</th>
</tr>
</thead>
<tbody>
<tr>
<td>1.8 ± 0.3</td>
<td>0.0 ± 0.1</td>
<td></td>
</tr>
</tbody>
</table>

Table 4.5: This table reports the activation energy values associated with the de–wetting process of H$_2$O (rising edge) and the subsequent region (plateau) where isolated H$_2$O molecules have formed a greater bulk.

From Table 4.5, the rising edge has an associated energy of about 1.8 kJ mol$^{-1}$ ± 0.3 kJ mol$^{-1}$ which changes to the plateau with what amounts to 0.0 ± 0.1 kJ mol$^{-1}$ at 24 K. The plateau seems to have a negative gradient, however the error associated with the data outweighs this gradient, suggesting a value of 0.0 kJ mol$^{-1}$. This means that a sub–monolayer coverage of H$_2$O of 0.5 ML will have formed a bulk multilayer after being heated to about 24 K when considering Figure 4.9. The implication of this means that a coverage of 0.5 ML H$_2$O on SiO$_2$ has formed an island or cluster as observed when conducting TPD experiments of a sub–monolayer coverage of H$_2$O on SiO$_2$.

An assumption about diffusion of molecules on surfaces is that in general 10 – 15% of the binding energy approximates the activation energy of diffusion [22] or, in the case of this work, the energy required for H$_2$O to de–wet from SiO$_2$. This assumption holds true for C, N, O, H, S, CO and NO on metal surfaces [22 and references therein]. With this assumption in mind and knowing that H$_2$O has a desorption energy of 43.9 kJ mol$^{-1}$ [2] for the two H–bonds breaking one H–bond in water has an associated energy of about 22 kJ mol$^{-1}$. This value of a H–bond corresponds well with the known values of 8 – 40 kJ mol$^{-1}$ [23] or more generally described as 20 kJ mol$^{-1}$ [24]. Considering the diffusion energy assumption of 10% of the binding energy leads to an energy for H$_2$O
diffusion of about 2.2 kJ mol\(^{-1}\), which is very similar to the 1.8 kJ mol\(^{-1}\) determined in this work.

An important note to consider, however, is that reorganisation of H\(_2\)O molecules at the temperature used in these experiments can also occur. As stated in the introduction, Section 4.1, H\(_2\)O undergoes a phase change from p–ASW to c–ASW starting at a temperature of about 38 K \([25]\) and a further phase change from c–ASW to CSW at above 130 K \([26, 27]\). When purely looking at the temperature profile of the experiments, the rising edge leads to a plateau at about 24 K. Recent work regarding the amorphous H\(_2\)O has shown the porous to compact amorphous H\(_2\)O phase change to possibly begin at temperatures of 25 K \([28]\). However, phase changes between amorphous states of H\(_2\)O cannot be detected with IR in these experiments presented in this thesis due to the lack of observable H–dangling bonds. Other techniques can be used to investigate this phase transition such as co–deposition of CO onto H\(_2\)O films at different temperatures followed by TPD experiments to look at CO entrapment \([25, 29, 30]\). That is not to say that re–organisation of the bulk H\(_2\)O molecules cannot happen at these low temperatures before a phase change occurs. Experiments looking at the de–wetting of H\(_2\)O at temperatures approaching the compact to crystalline phase change were not possible due to a change in the νOH band sharpening up as the onset of crystallisation occurs and at higher temperatures due to the initial stages of desorption.

### 4.3.2 O Atom Bombardment of H\(_2\)O Films

Considering the work discussed in Chapter 3, a question could be; what happens as such a sub–monolayer coverage of H\(_2\)O is bombarded by O atoms? When looking at the experiment where H\(_2\)O moves on the SiO\(_2\) surface at 18 K one can see that the de–wetting process is relatively slow and only picks up when thermal energy is supplied to the molecular film. De–wetting is observed within the first hour of the experiment, as seen in Figure 4.4, however the rate constant associated with the entire de–wetting experiment at 18 K is comparatively low and therefore should be a slow process. Starting from this basis, depositing 0.5 ML H\(_2\)O at 18 K and bombarding with O atoms leads to Figure 4.10.
Figure 4.10: This figure shows the effect of O atom bombardment on 0.5 ML H$_2$O. The large sharp peaks are due to gas phase H$_2$O in the optics boxes outside of the UHV chamber.

From Figure 4.10 one can see that the general trend is still observed; the intensity of the main band centred at about 3250 cm$^{-1}$ increases as atomic O beam dosing time increases. The features in the spectrum at about 3400 cm$^{-1}$, corresponding to smaller clusters of H$_2$O, seem invariant throughout the experiment. This is an indication that the diffusion process is slow and barely active at this time scale. The main band is seen to increase though leading to a different process occurring when O atoms bombard the surface. A possible process is network reconnection of the hydrogen bonds in small H$_2$O clusters. Analysis of Figure 4.10 was done as previously explained with smoothed spectra in the 3500 – 3000 cm$^{-1}$ range (not shown here) and yields a rate constant of $1.8 \times 10^{-3} \pm 0.2 \times 10^{-3}$ s$^{-1}$ which is about 2 orders of magnitude greater than the 18 K de-wetting of Figure 4.4.

Increasing the H$_2$O coverage will inevitably lead to greater clusters on the SiO$_2$ surface, and thereby a greater chance for O atoms to strike H$_2$O instead of SiO$_2$. Deposition of 1 ML p–ASW will not create a monolayer and clusters are expected considering TPD data and the work presented in this chapter. For that reason a change in intensity of the main O–H stretch remains expected. This is indeed what is observed in Figure 4.11.
Figure 4.11: This figure is of 1 ML p–ASW as O atoms bombard the sample for a total of 50 minutes. The same trend is seen here, however to a greater extent, as is seen in Figure 4.10.

Deposition of 1 ML H$_2$O, as in Figure 4.11, still shows increases in the main band at about 3250 cm$^{-1}$, however the features at about 3400 cm$^{-1}$ seem to remain unaltered throughout the experiment. In general, the behaviour observed in Figure 4.10 is also observed in Figure 4.11, a difference is observed when calculating the rate constant. The value for $k$ is $1.2 \times 10^{-3} \pm 0.2 \times 10^{-3}$ s$^{-1}$, having fallen when increasing the H$_2$O coverage. If O atom bombardment were to aid in the de–wetting process, a greater rate constant would be expected; this is not observed. However, O$_2$ formation releases about 580 kJ mol$^{-1}$ [31] which has to be dissipated into the film for molecular formation to take place. A greater concentration of H$_2$O would be able to dissipate this energy more efficiently than a lesser concentration leading to the observed difference in the rate constants.

With no H$_2$O present on the film, O$_2$ formation would take place and the energy dissipated in to the SiO$_2$ underlayer with no change to the SiO$_2$ network. This was the basis of Chapter 3. However, O atomic bombardment could induce a change in the H$_2$O H–bonded network. Altering the H$_2$O film before O atomic bombardment will give information regarding the H$_2$O H–bonded network.
Figure 4.12: As can be seen in this figure, 1 ML of c–ASW does not behave as the p–ASW films. Throughout O atom irradiation for 50 minutes, the band is invariant, however has the same shape as the p–ASW spectra presented in this work.

Firstly, looking at the 1 ML coverage of compact amorphous solid water (c–ASW) and bombarding it with O atoms for 50 minutes gives Figure 4.12. As can be seen, the band shape is similar to other H2O spectra presented, however the main 3250 cm⁻¹ band is not observed to vary with time or atomic O bombardment. The integrated areas do no differ by a substantial amount, leading to the rate constant nearly equalling zero considering the uncertainty (8.6 × 10⁻⁴ ± 7.9 × 10⁻⁴ s⁻¹). The rate constant is not fully equal to zero as re–connection of the H–bonded network is still a possibility. At the deposition temperature of 100 K, the H2O molecules will have enough thermal energy to de–wet instantly meaning the de–wetting process is not believed to occur and be the reason for the value of the rate constant.

Further changing the H2O to produce a crystalline solid water (CSW) film can be seen in Figure 4.13.
Figure 4.13: This figure shows the effect of O atoms bombarding a 1 ML CSW film. The atomic beam was dosed in steps for a total of 50 minutes. The bump seen in the 1 ML CSW spectrum (red spectra) at about 3350 cm$^{-1}$ disappears during O atom bombardment.

The red spectrum in Figure 4.13 shows the initial 1 ML CSW film prior to O atom irradiation. A bump can be seen in the 3300 – 3400 cm$^{-1}$ range which has previously been described as a feature of crystalline H$_2$O films [32]. This feature disappears as O atoms bombard the surface leaving the final spectrum (after 50 minute O atom dosing) similar in shape to the spectra shown in Figure 4.12. There is no information regarding the rate constant because of this disappearance of the 3350 cm$^{-1}$ feature leaving the area of the $A_0$ spectra greater than all $A_r$ spectra rendering Equation 3 of no mathematical use. Disregarding the rate constant of the CSW experiment, Table 4.6 has been produced to directly compare the results.

<table>
<thead>
<tr>
<th>Water type and coverage</th>
<th>$k / s^{-1}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.5 ML p–ASW</td>
<td>$1.8 \times 10^{-3} \pm 0.2 \times 10^{-3}$</td>
</tr>
<tr>
<td>1 ML p–ASW</td>
<td>$1.2 \times 10^{-3} \pm 0.2 \times 10^{-3}$</td>
</tr>
<tr>
<td>1 ML c–ASW</td>
<td>$8.6 \times 10^{-4} \pm 7.9 \times 10^{-4}$</td>
</tr>
<tr>
<td>1 ML CSW</td>
<td>–</td>
</tr>
</tbody>
</table>

Table 4.6: This table has been made to show the difference in the rate constant ($k$) as the coverage changes in p–ASW films and the film itself is changed to c–ASW and CSW.
O atom bombardment of a H$_2$O will produce O$_2$ as discussed in Chapter 3, and as previously said, the energy of fusion has to be dissipated by surrounding molecules for the reaction product to remain. In the p–ASW and CSW films, this excess energy is possibly used to form a c–ASW film through the breaking of H–bonds from the dissipated fusion energy [27]. This would explain why the RAIR spectra of CSW after O atoms irradiation (Figure 4.13) begin to become similar to the c–ASW spectra in Figure 4.12. A simple way of looking at this has been described in Equation 5.

\[ p\text{–ASW} \rightleftharpoons c\text{–ASW} \]

Equation 5

This idea and equation could also be part of the reason why the main constituent of an interstellar grain’s icy mantle is c–ASW and not p–ASW or CSW.

4.4 Astrophysical Implications of H$_2$O de–wetting

Returning to the H$_2$O de–wetting results and looking at these from an astrochemical stand–point one should consider the cooling environments of the ISM, i.e. a diffuse cloud collapsing into a dense one. Initially, however, the focus will be on a dust grain already in the core of a dark cloud and following the dust grain as the cloud warms up. The heating rate in these environments of the ISM is estimated to be 1 K century$^{-1}$ [33].

Using the results obtained for the de–wetting experiments, a simple picture can be drawn to compare the data with the H$_2$O monolayer formation time through Equation 6 where $i$ refers to isolated H$_2$O and $c$ is clustered H$_2$O.

\[ \text{H}_2\text{O} (i) \xrightarrow{k} \text{H}_2\text{O}(c) \]

Equation 6

The result of this equation and the associated simulation can be seen in Figure 4.14 below. Figure 4.14 indicates that isolated H$_2$O moves to a clustered environment on a timescale of about 400 years at a temperature of about 5 K which is considerably less than the typical temperatures of 10 K in a dark cloud [34]. The results therefore indicate that H$_2$O will have the mobility to form clusters even in the coldest parts of the ISM. This will also mean that the time for H$_2$O to complete an entire film on interstellar dust grains might be higher than the estimated 10,000 years [35] as cluster formation at these early times and low temperatures will delay this time.
Figure 4.14: This figure shows the H$_2$O as isolated (i) converting into clusters (c) with time through a heating rate of 1 K century$^{-1}$ (a) and the corresponding temperature for the cluster formation (b). The simulation has been done for 0.5 ML H$_2$O with an $E_{act}$ of 1.8 kJ mol$^{-1}$ and a pre–exponential factor of $10^{12}$ s$^{-1}$.

The results of the simulation in Figure 4.14 come from taking a bare dust grain and plunging it into the depths of the cold core of a molecular cloud to look at the mobility of H$_2$O. However, a bare grain will build an icy mantle as a cloud collapses and the environment cools. As stated in the introduction, the time for a cloud to collapse has been estimated to be at least in the order of $10^6$ years [36, 37] and as this happens the temperature will gradually fall from about 100 K in diffuse clouds [38] to 10 K in the core of dark molecular clouds [34]. As this occurs molecules will adsorb onto dust grains, this freeze–out process occurs on a time scale of $10^6$ years [39]. Therefore, the cooling rate can be estimated as being about 1 K per $10^4$ years when cooling from about 100 K to 10 K. As this happens, accreted H$_2$O will naturally find itself in different structural states such as crystalline (CSW) and compact amorphous (c–ASW). For that reason a second CKS model can be built to show the effect of this, more natural, process while knowing that H$_2$O prefers to be in its clustered c–ASW or CSW state. The steps used are as follows:
The adsorption processes in **Equation 7 (A)** and **(B)** have an assumed sticking coefficient of unity. Further to the adsorption steps; it is assumed that H₂O will adsorb at random and in equal proportion of isolated and clustered states. The de–wetting step in **(C)** follows the values supplied in this chapter. The reverse (step **(D)**) proceeds via H–bond breaking similar to the desorption processes in **(F–G)** with energies ranging from 45 – 47 kJ mol⁻¹ [2, 40]. With the data in **Figure 4.14**, a likely result will be to see H₂O only in the clustered or bulk phase on the surface. This is indeed what **Equation 7** leading to **Figure 4.15** below indicates.

**H₂O (g) → H₂O_{isolated} (s)**  \hspace{1cm} **Equation 7 (A)**

**H₂O (g) → c – ASW (s)** \hspace{1cm} **(B)**

**H₂O_{isolated} (s) → c – ASW (s)** \hspace{1cm} **(C)**

**c – ASW (s) → H₂O_{isolated} (s)** \hspace{1cm} **(D)**

**c – ASW (s) → CSW (s)** \hspace{1cm} **(E)**

**H₂O_{isolated} (s) → H₂O (g)** \hspace{1cm} **(F)**

**c – ASW (s) → H₂O (g)** \hspace{1cm} **(G)**

**CSW (s) → H₂O (g)** \hspace{1cm} **(H)**

**Figure 4.15**: This figure shows what happens as H₂O adsorbs onto an interstellar dust grain as during cloud collapse and freeze–out as the temperature falls from 110 K to 10 K. Gas phase molecules (g) will either adsorb as isolated or clustered H₂O. As the temperature is above the energy needed for de–wetting, isolated molecules instantly become crystalline or clustered depending on temperature. The simulation has been done for 0.5 ML H₂O with an E_{act} for de–wetting of 1.8 kJ mol⁻¹ and a pre–exponential factor of 10¹² s⁻¹ with a cooling rate of 1 K century⁻¹.
Figure 4.15 shows H$_2$O initially in the gas phase, (g), before adsorbing to the surface as either isolated or clustered H$_2$O. As the temperature falls and H$_2$O is adsorbed, no isolated molecules are found on the surface as seen in the H$_2$O$_{isolated}$ (s) trace, this means H$_2$O is found in a clustered form from the initial stages. As the temperature is great enough to give H$_2$O the thermal energy needed to construct the crystalline form, the red trace (H$_2$O$_{crystalline}$ (s)) grows until the temperature reaches 80 K. At this stage, H$_2$O can only form the compact amorphous solid structure while isolated molecules are still not expected to form. The cooling rate used for Figure 4.15 was only 1 K century$^{-1}$ due to restrictions with the CKS software. Changing the cooling rate to 1 K per ten millennia (which is a better estimate of the astrophysical cooling rate) will shift the temperature scale so that adsorption occurs at a higher temperature, however the general and overall trend regarding isolated H$_2$O moving to clusters will remain consistent.

All the experiments and simulations have been done considering a pure SiO$_2$ surface, since H$_2$O is mobile at low temperatures one large cluster can be expected to form. However, silicate dust grains in the ISM, as explained in Chapter 1, are highly amorphous and comprised of metal centres scattered throughout. These metal centres, such as iron are initially thought to be cationic leading to iron nanoparticles due to space weathering [41]. At low coverages H$_2$O will dissociate on a polycrystalline Fe surface [42] however, the interstellar dust grains would have a variety of binding sites leading to preferred sites of H$_2$O adsorption. Therefore, the possibility of H$_2$O forming more than one cluster is possible. However many clusters are formed, bare grain surfaces could be expected, due to the de–wetting process, for other molecules to adsorb to. As stated earlier, CO is a large component of the icy mantle coating dust grains. If a simple dust grain model is assumed where only H$_2$O is present and CO adsorbs at a later stage, onto what surface would CO adsorb? Once again, TPD experiments can provide the answer. Firstly, CO will form a monolayer on a SiO$_2$ surface [2, 21] and also on a H$_2$O surface [43] before it binds to another CO molecule to form a multilayer. Further to this, at a very low coverage of CO, 0.1 ML, the binding energy of CO to SiO$_2$ is greater by about 1 kJ mol$^{-1}$ than for compact amorphous H$_2$O, at monolayer and greater thicknesses the CO–CO interaction becomes dominant and the energies of desorption become similar for the SiO$_2$ and H$_2$O surfaces mentioned [21]. Pontoppidan et al. [44] investigated CO in various H$_2$O poor environments in the ISM. Three features linked to CO were found at 2143.7 cm$^{-1}$, 2139.9 cm$^{-1}$ and 2136.5 cm$^{-1}$, where the first two features were assigned to multilayers of CO. The latter feature was left unidentified.
Experiments conducted by Collings et al. [2] with 0.5 ML CO deposited onto an amorphous SiO$_2$ surface lead to a peak at 2137 ±1 cm$^{-1}$ which could correspond to the unassigned feature detected by Pontoppidan et al. This would therefore mean that CO can possibly be found to interact directly with the dust grains and that H$_2$O will not cover the entire grain as it will rather form clusters or islands. However, this same feature at 2136.5 cm$^{-1}$ can also be assigned to CO in a CH$_3$OH matrix as this alcohol is the final hydrogenation product of CO [45]. If the 2136.5 cm$^{-1}$ feature is considered to be CO on SiO$_2$, then another simple CKS model can be created while considering the difference in CO–SiO$_2$ and CO–H$_2$O interaction energy leading to CO preferably interacting with SiO$_2$. Once again running the model in a cooling environment where 0.5 ML H$_2$O, in its c–ASW form, is already on the dust grain surface and letting one ML CO adsorb from the gas–phase onto the dust grain leads to Figure 4.16.

![Figure 4.16](image)

**Figure 4.16:** This figure shows the behaviour of CO as it adsorbs onto an interstellar dust grain with H$_2$O already present. Assuming an equal probability of CO initially adsorbing onto H$_2$O or SiO$_2$, CO then migrates to the preferred SiO$_2$ sites until all SiO$_2$ sites are inhabited leaving H$_2$O sites open for interactions as compared to the less favoured CO multilayer formation.

Shown in Figure 4.16 is the adsorption of CO onto SiO$_2$ and c–ASW. There is no preference for where CO adsorbs, but the molecules do migrate to the SiO$_2$ surface leading to almost all CO adsorbed onto SiO$_2$. When the CO coverage approaches the full monolayer, CO will have to adsorb onto the H$_2$O as this interaction is still favoured
over CO multilayer formation. This model has been constructed with energies for CO–SiO$_2$ interaction being favoured over CO–H$_2$O as has been shown experimentally [21]. Also, the same steps for H$_2$O adsorption were used as described in Equation 7, with the extra steps shown in Equation 8 leading to CO adsorption.

\[
\begin{align*}
\text{CO (g)} & \rightarrow \text{COH}_2\text{O (s)} \\
\text{CO (g)} & \rightarrow \text{CO}_{\text{SiO}_2} (s) \\
\text{COH}_2\text{O (s)} & \rightarrow \text{CO}_{\text{SiO}_2} (s)
\end{align*}
\]

Equation 8 (A)
Equation 8 (B)
Equation 8 (C)

The step in Equation 8 (C) illustrates the preferred interaction of CO with SiO$_2$ as compared to H$_2$O. This simple model therefore shows that regions of CO directly adsorbed onto dust grains are possible.

### 4.5 Conclusion

This chapter has focused on the initial stages of the icy mantle covering an interstellar dust grain as H$_2$O is formed as studied through the use of RAIRS. As explained in the introduction of this chapter, Section 4.1, TPD experiments show zero order desorption which explains that the H$_2$O–H$_2$O interaction is favoured over the H$_2$O–SiO$_2$ interaction even at a sub–monolayer coverage. Therefore, if a hit–and–stick mechanism of H$_2$O adsorption is applied at cryogenic temperatures, H$_2$O will need an amount of energy to begin to move from isolated to clustered regions. According to this work, the mobility of H$_2$O has an activation energy of about 2 kJ mol$^{-1}$ forming clusters at very low temperatures on a SiO$_2$ surface. H$_2$O does therefore not hit and stick as is typically thought. Further to this, when bombarding H$_2$O cluster with O atoms a general shift from p–ASW and CSW to c–ASW films is observed. H$_2$O ice covering interstellar dust grains is thought mainly to be in the c–ASW form due to a lack of the dangling H–bond. These O atom bombardment experiment could be one mechanism for the transformation of different H$_2$O structures leading to the observable evidence of c–ASW ices in the ISM.

The simulations of this process indicate that, even at temperatures experienced by grains at the very core of molecular clouds H$_2$O will form clusters before a complete monolayer is formed. Figure 4.17 is a simple cartoon of the H$_2$O cluster formation as a diffuse interstellar clouds collapses to become a dense molecular cloud. Figure 4.17
displays CO as binding with only one end of the molecule to the surface. This is because of the work done by Collings et al. [46] showing that a so-called sigma binding of CO occurs through the C end of the molecule leaving the positive O end protruding to the vacuum.

As a cloud collapses the temperature decreases and the gas becomes mainly molecular, leaving the dust grains covered with a mantle of ice. During the cooling process all H₂O molecules reactively accreted and adsorbed onto a dust grain will have sufficient energy to agglomerate. The warmer the grain, the faster the de-wetting process. The dust grains will continue to cool and more H₂O will be formed still able to cluster leaving relatively pure H₂O environments and bare regions of dust grain surfaces. These experiments

![Figure 4.17](image)

**Figure 4.17:** This cartoon represents the onset of H₂O cluster formation and the de-wetting process even at temperatures of 10 K on dust grains, brown substrate, in the cores of molecular clouds. The red circles are representative of O atoms, black circles are H atoms, blue ovals are H₂O molecules and green ovals are molecules of CO. This figure draws inspiration from [8].

therefore demonstrate that the Onion model will have to be revised. The typical idea of a dust grain coated with H₂O, sometimes estimated as about 100 ML [35] followed by
CO does not match the experimental data in this work. Bare dust grain surfaces will be available for other molecules, such as CO, to interact with, this interaction can be stronger and therefore CO could be desorbed less efficiently from bare dust grain surfaces. Astronomical models will also need to reflect this as the binding energies of other molecules can be different when adsorbing to the dust grain surface, SiO$_2$, as compared to H$_2$O.
4.6 References


Chapter 5

The Spontelectric Effect

Contents of this chapter

5.1 Introduction .............................................................................................................. 148
  5.1.1 The Spontelectric Effect ...................................................................................... 148
  5.1.3 RAIRS and the Spontelectric Effect ................................................................. 150
5.2 Experimental ............................................................................................................ 151
5.3 Results and Discussion ............................................................................................ 152
  5.3.1 Multilayer N$_2$O Films .................................................................................. 152
  5.3.2 Spontelectric CO Films on SiO$_2$ ...................................................................... 160
  5.3.3 Spontelectric CO on Films H$_2$O ....................................................................... 167
5.4 Modeling RAIRS Data ............................................................................................ 171
  5.4.1 LO and TO Modes with Dipole Orientation ...................................................... 179
  5.4.2 LO and TO Modes with Temperature ............................................................... 181
  5.4.3 Spontelectric CO Films .................................................................................... 183
5.5 Astrophysical Implications of the Spontelectric Effect ............................................. 192
5.6 Conclusion ............................................................................................................... 198
5.7 References .............................................................................................................. 201
5.1 Introduction

5.1.1 The Spontelectric Effect

The introduction mentioned interstellar dust grain charging and, in brief, the spontelectric effect of dipolar molecules. Chapter 2 delved further into how direct measurements of the spontelectric effect are carried out at Aarhus University and the model developed by David Field explaining the experimental results. This chapter will describe the characteristics of the spontelectric effect as also found in references [1–8] and its relevance to this thesis and the astronomical community.

The study of the surface potential created by spontelectric molecules and the spontelectric effect itself is a new area of research, for that reason there are some outstanding questions. One of these questions regards the origin of the effect. This is not yet known, however what is known is that it is a bulk effect arising after a certain number of ML of material is deposited onto a surface [1]. The specific number of ML depends on the molecule investigated. The characteristics of spontelectric films as determined through experimental observations have been listed below [1]:

- Deposition of certain dipolar molecules leads to a spontaneous and measureable surface potential which can reach several volts;
- The surface potential increases linearly with increasing film thickness. This potential will be positive or negative depending on the end of the dipolar molecule at the film–to–vacuum interface;
- Long–range (or non–local) interactions between spontelectric molecules lead to a measured surface potential;
- The measured surface potential is independent of the substrate;
- However, the spontelectric effect is dependent on the nature of the spontelectric molecule and temperature of the sample;
- Warming (or annealing) a typical spontelectric film leads to an irreversible decrease in the measured surface potential. Changing the temperature at which the film is deposited brings a greater irreversible reduction to the surface potential as compared to annealing;
- Above a certain temperature, termed the Curie point, the surface potential drops to zero;
These observations lead to the idea that the surface potential arises from the bulk effect of the spontlectric molecules from the sample–to–film interface to the film–to–vacuum interface. An example of effect of the molecular film thickness and deposition temperature has been shown in Figure 5.1 [1].

![Figure 5.1: This figure shows how the surface potential varies proportionately with amount of N₂O. A decrease in the potential is observed as the deposition temperature rises. At temperatures above 65 K, N₂O does not stick effectively to the gold surface under UHV conditions and no measurements are made [1].](image)

As the molecules are deposited, the species are believed to spontaneously adjust their orientation to adopt more thermodynamically unfavoured positions as illustrated in Figure 5.2 (B). However, if intermolecular forces are too great for the spontlectric state to cope with, no surface potential is observed.

![Figure 5.2: This cartoon illustrates the thermodynamically most favoured structure for a dipolar molecular solid (A) and the likely molecular orientation in the spontlectric phase (B).](image)
As the temperature of the dipolar films is increased the potential decreases [1]. This is likely caused by thermal perturbation of the dipolar alignment in the films. This supply of thermal energy could lead to the thermodynamically favoured structure as seen in Figure 5.2 (A) as compared to the believed molecular orientation as seen in (B). This is the case for all molecules save the anomalous case of methyl formate where the surface potential has been observed to increase with increasing temperature until its Curie point is reached [5].

5.1.2 RAIRS and the Spontelectric Effect

One way to investigate molecules in a solid film is to employ the technique of infrared (IR) spectroscopy, in the case of this work, specifically reflection–absorption infrared spectroscopy (RAIRS). For the time being, only dipolar molecules have been investigated with regards to the spontelectric effect, meaning molecules investigated will not be IR inactive.

If we consider thermal perturbation of dipole orientation leading from the spontelectric structure seen in Figure 5.2 (B) to a non–spontelectric state and more favoured structure of (A), then changes in the IR bands must become visible. Such orientational changes have been studied by other research groups, for instance the work of Jones and Swanson [9] which has yielded Equation 1:

\[
\nu_{LO}^2 - \nu_{TO}^2 = \frac{4\pi}{\varepsilon V} \times \left( \frac{\partial \mu}{\partial q} \right)^2.
\]

This equation correlates the frequencies of the longitudinal optical (\(\nu_{LO}\)) and transverse optical (\(\nu_{TO}\)) modes to the degree of dipole alignment (\(\partial \mu / \partial q\)) through a factor of the unit cell volume (\(V\)) and the relative permittivity (\(\varepsilon\)).

As discussed in Chapter 2, RAIRS is one of the analytical techniques which can be employed to study molecular films on the SiO\(_2\) surface. Chapter 2 also discussed the LO–TO splitting which is presented in Equation 1 where the splitting is related to the dipole alignment which itself is related to the spontelectric effect. Therefore, RAIRS can be used as an indirect probe to study the dipole alignment of spontelectric molecules through the LO–TO splitting. This splitting has also been observed for a
variety of molecules both with a permanent dipole moment, such as N$_2$O [9–11] and CO [12], and molecules with induced dipoles moments such as CO$_2$ [13], CF$_4$ [14].

Up until this point of this thesis, an investigation into one of the H$_2$O formation pathways has been studied. H$_2$O will slowly build up on a dust grain, however initially only small quantities will be found on the surface. Isolated H$_2$O molecules and small clusters have been shown to move at cryogenic temperature as shown in this thesis. As the icy mantle covering a dust grain grows, sub–monolayer amounts of ice become multilayer amounts. Now, light will be cast upon these solid films of multilayer ice as found in the dark clouds of interstellar clouds. As already observed in Chapter 4, the H$_2$O band is very broad and even though an LO–TO splitting has been discussed as being present in H$_2$O films [15–17], these films are not analysed here since observations of the splitting is difficult. However, the second most abundant molecule in interstellar ice is CO which has a permanent dipole. Initially, though, a study of N$_2$O must be conducted to illustrate how the spontelectric effect of molecules can be studied without direct surface potential measurements. Therefore, this chapter will outline how reflection–absorption infrared spectroscopy (RAIRS) can be used as an indirect measure of the spontelectric effect.

5.2 Experimental

The overall capabilities of the UHV equipment have been explained in Chapter 2, however, a brief outline of the steps taken to produce the results shown in this chapter will be supplied here. Temperature programmed desorption (TPD) was used to a small extent to determine the number of monolayers (ML) deposited onto the 300 nm SiO$_2$ layer coating the Cu sample block. These experiments were done with an average heating rate of 0.6 K s$^{-1}$ for N$_2$O (Sigma–Aldrich, purity $\geq$ 99.998%) and 0.3 K s$^{-1}$ for CO (BOC, purity $\geq$ 99.9%) desorption. Ionisation coefficients in the ion gauge head of 1.2, 1 and 1 were taken into account when dosing N$_2$O, CO and H$_2$O, respectively [18]. Reflection–absorption infrared spectroscopy (RAIRS) was the main analytical method used to investigate the deposited films with a grazing incidence of 75° and collected by the liquid nitrogen cooled MCT detector. A total of 512 scans were collected with a resolution of 1 cm$^{-1}$ and 0.1 cm$^{-1}$ for the N$_2$O and CO experiments, respectively.
5.3 Results and Discussion

In this section, results from experiments of N$_2$O deposited onto SiO$_2$ will first be reported. Temperature programmed desorption (TPD) will be employed first to determine when a multilayer is present on the surface. Then 100 L of N$_2$O (equivalent to 14 monolayer (ML)) will be deposited onto SiO$_2$ and reflection–absorption infrared spectroscopy (RAIRS) will be used to study the LO–TO splitting of the ν$_{NN}$ feature as the temperature (both annealing and deposition temperatures) is increased. Next the same procedure will be done for CO on SiO$_2$ where a 5 ML film will be studied with RAIRS. Following this, 20 ML CO on different H$_2$O surfaces will be studied. The types of H$_2$O used are porous amorphous solid water (p–ASW), compact amorphous solid water (c–ASW) and crystalline solid water (CSW). As will become apparent throughout this section, the relative ML coverage is not important as long as the LO–TO splitting is observable in the multilayer films.

5.3.1 Multilayer N$_2$O Films

As explained in the introduction of this chapter, Section 5.1, N$_2$O is the model spontaneous molecule which is the reason for this being the initial test molecule to determine the spontaneous effect as observed through reflection–absorption infrared spectroscopy (RAIRS). The figures in this section can also be found in Lasne et al. [19].

Initially, temperature programmed desorption (TPD) experiments were conducted to determine the coverage equivalent to one monolayer (ML) of N$_2$O, following this a multilayer will be deposited onto the SiO$_2$ surface for RAIRS studies. The results of the TPD experiment can be seen in Figure 5.3.

As can be seen in Figure 5.3, the monolayer is formed after depositing 7 L of N$_2$O. The peak temperature of desorption in the multilayer is 72.7 K to 73.7 K (± 0.3 K) which corresponds well with other experiments on multilayer N$_2$O desorption where a temperature of 75 K ± 5 K has been stated [20]. The higher temperature bumps relate to the more favourable binding sites of N$_2$O to SiO$_2$ in the sub–monolayer regime. Desorption kinetics have not been analysed as the focus of this experiment was to determine when N$_2$O is found to be a multilayer on SiO$_2$. 

152
Figure 5.3: This figure shows the TPD results of depositing various amounts of N$_2$O onto SiO$_2$ and desorption of the molecular films. N$_2$O detected as m/z = 44 is recorded as a function of temperature of the substrate. As can be seen, a clear change is observed between 6 L and 7 L which is the change between the sub–monolayer and the multilayer regimes as explained in Chapter 2.

As the spontelectric effect is a bulk effect and a multilayer is required for a surface potential to be measured, a film thickness corresponding to 100 L (about 14 ML) will be used for the RAIRS experiments. This means the splitting should be observed at this film thickness. In Figure 5.4 [19], the LO–TO splitting is indeed apparent.

Figure 5.4: This figure shows the full range of the spectrum obtained when having deposited 14 ML N$_2$O onto SiO$_2$ at 50 K. The peaks of interest at about 2250 cm$^{-1}$ have been highlighted in the insert [19].
As can be seen in the Figure 5.4, the νNN mode is the dominant mode when compared to the other modes observed, such as νNO, in the IR spectrum centred at roughly 2250 cm⁻¹, or more precisely at 2256 ± 1 cm⁻¹ and 2239 ± 1 cm⁻¹ for the LO and TO modes, respectively. The peak position and its LO–TO splitting has already been of interest for other research groups [10–12] and will also be used in this work due to its clarity and intensity. As explained in Section 5.1, the spontaneous effect decreases for N₂O as the temperature increases, be it annealing or deposition temperature. Also, as per Equation 1, the degree of LO–TO splitting is proportional to the dipole order in a solid [9]. Thereby, supplying thermal energy to the 14 ML film will lead to thermal disorder of the dipole ordering, meaning less order of the dipoles and a decrease of the LO–TO splitting. The first step is to investigate IR peak position with respect to N₂O amount to ensure any shifts are not caused by the N₂O film thickness. This has been displayed in Figure 5.5.

![Figure 5.5](image)

**Figure 5.5**: This figure indicates that changing the amount of N₂O from 1.4 ML to 28 ML has little bearing on the peak positions. The N₂O films were deposited at 50 K to ensure the sharp features of the LO–TO splitting. The dashed lines are a guide to the eye to show peak shifts as compared to the centre of the peak of the 14 ML N₂O spectrum.

From Figure 5.5, one can see that the LO–TO splitting changes slightly with film thickness. The uncertainty of background dosing is large (about 20%) meaning that a film of 7 or 28 ML N₂O is not expected as this would be half or double of 14 ML. The
RAIR spectra of 7 ML N₂O shows LO and TO mode peak positions at 2256 ± 1 cm⁻¹ and 2239 ± 1 cm⁻¹, respectively, and 2257 ± 1 cm⁻¹ and 2239 ± 1 cm⁻¹ for the 28 ML amount. Therefore, considering the resolution of the experiment giving the uncertainty of 1 cm⁻¹, 14 ML of N₂O is used for the experiments described in the next sections can be regarded as not being dependent of film thickness. The effect and implication of molecular amount will be discussed in more detail later on in this chapter. This means change in the frequency of the peaks must be due to changes in the temperature. The effect of this can be seen in **Figure 5.6** for annealing.

![Figure 5.6](image.png)

**Figure 5.6**: This figure shows 14 ML N₂O on SiO₂ being annealed from base temperature. The red arrows indicate the movement of the peaks as they shift with increasing temperature. N₂O deposited at 18 K is believed to be amorphous and the higher temperature spectra (>48 K) are crystalline. When the film is annealed to 48 K characteristics of both structural states can be observed.

As can be seen in **Figure 5.6**, increasing the temperature leads to a contraction of the LO–TO splitting and thereby as explained the dipole ordering decreases too. As this occurs the spontlectric effect diminishes. What can also be seen in **Figure 5.6** is a change in the band profile as the N₂O film is annealed past 48 K. This change is normally, in IR spectroscopy, associated with an amorphous to crystalline phase change in a molecular film as seen in, for instance, films of ethanol [21], vinylacetylene [22] and acetone [23] where peaks become more narrow due to a greater degree of structural order throughout a molecular film. However, as stated in Cassidy *et al.* [24] techniques such as neutron diffraction is a better way of clarifying the nature of the phase change.
Considering the sharp features of the observed N$_2$O bands and the ease with which a peak positions can be specified, this work will focus on molecular films as studied by RAIRS above 48 K. The surface potential decreases more rapidly if molecules are deposited at higher temperatures as compared to when a molecular film is annealed to the same temperature. For that reason 14 ML films of N$_2$O have also been deposited at a variety of temperatures as seen in Figure 5.7 [19].

![Figure 5.7](image)

**Figure 5.7**: This figure shows the effect of changing the deposition temperature of 14 ML of N$_2$O. A greater contraction of the LO–TO splitting is observed as compared to Figure 5.6. To make the figure easier to read, only five experiments have been shown instead of the full range [19].

Figure 5.7 has been shown with only five different deposition temperature experiments (48, 53, 60, 62 and 66 K). However, a total of nine experiments were done also including 51, 52, 55 and 56 K which are not shown for clarity. As can be seen in Figure 5.7, the same trend is observed as witnessed in Figure 5.6 where the LO–TO splitting contracts as the temperature of the sample increases. The LO–TO splitting contracts more as the deposition temperature is increased as compared to when the N$_2$O film is annealed. As explained earlier, this is also a characteristic of the spontaneous electric effect. The data in Figure 5.7, and the >48 K annealing data from Figure 5.6, has been fitted with Gaussians as was also done in Chapter 3. As explained in the experimental section of this chapter, the RAIR spectra for the N$_2$O experiments were conducted with a resolution of 1 cm$^{-1}$. However, fitting the data with Gaussians leads to a greater
accuracy of the peak positions, and therefore also the LO–TO splitting. The results of such fits can be seen in Figure 5.8.

![Figure 5.8](image)

**Figure 5.8:** This figure shows the comparison between the experimental data (open circles), and the Gaussian fits (solid red line) to the LO–TO splitting of N₂O with the residuals shown in the box above the graph.

The Gaussian fits, as seen in Figure 5.8, was done to all >48 K experimental data of N₂O. The result of this means that the peak positions of the LO and TO modes can be stated to a greater degree of certainty, now ±0.1 cm⁻¹ for the LO mode and ±0.2 cm⁻¹ for the TO mode. The peak positions and LO–TO contractions for all N₂O experimental data shown in Figure 5.6 and 5.7 have been detailed in Table 5.1 and further displayed in Figure 5.9 [19].

<table>
<thead>
<tr>
<th>Annealing Temperature / K</th>
<th>Wavenumber / cm⁻¹</th>
<th>ΔLO-TO / cm⁻¹</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>LO (± 0.1 cm⁻¹)</td>
<td>TO (± 0.2 cm⁻¹)</td>
</tr>
<tr>
<td>50</td>
<td>2256.8</td>
<td>2239.05</td>
</tr>
<tr>
<td>53</td>
<td>2256.6</td>
<td>2239.3</td>
</tr>
<tr>
<td>56</td>
<td>2256.4</td>
<td>2239.6</td>
</tr>
<tr>
<td>60</td>
<td>2256.3</td>
<td>2239.8</td>
</tr>
<tr>
<td>63</td>
<td>2256.2</td>
<td>2240.0</td>
</tr>
<tr>
<td>Deposition Temperature / K</td>
<td>Wavenumber / cm(^{-1}) LO (± 0.1 cm(^{-1}))</td>
<td>Wavenumber / cm(^{-1}) TO (± 0.2 cm(^{-1}))</td>
</tr>
<tr>
<td>--------------------------</td>
<td>---------------------------------</td>
<td>---------------------------------</td>
</tr>
<tr>
<td>48</td>
<td>2256.35</td>
<td>2239.15</td>
</tr>
<tr>
<td>51</td>
<td>2255.9</td>
<td>2239.6</td>
</tr>
<tr>
<td>52</td>
<td>2255.8</td>
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<td>2254.9</td>
<td>2240.1</td>
</tr>
<tr>
<td>66</td>
<td>2254.2</td>
<td>2240.8</td>
</tr>
</tbody>
</table>

Table 5.1: This table shows the peak positions and the difference in the LO–TO splitting for the annealing data (upper section) and the different deposition temperature data (lower part) from Figures 5.6 and 5.7. Only data at ≥48 K have been included due to the more clearly defined peaks.

Figure 5.9: This figure shows the result of plotting the data outlined in Table 5.1 where squares and dots correspond to the LO and TO peaks, respectively. Further to this, the black and red represent the annealing and deposition temperature experiments, respectively. As can be seen, a contraction occurs with increasing temperature, and greater so when the deposition temperature is increased [19].
**Figure 5.9** has been created to better illustrate the effect of temperature on the LO–TO splitting. As can be seen, depositing a 14 ML film of N₂O at 18 K and annealing it to higher temperatures the splitting contracts as shown through the black data set. The same can be said for depositing the N₂O at different temperatures leading to a greater contraction which is seen with the red data points. The squares and dots are representative of the LO and TO modes of N₂O. As stated earlier, this is an indication of disorder of dipoles in the molecular film. Another method of look at the dipole alignment with RAIRS is to study the inhomogeneous broadening in a qualitative fashion as this broadening measures the range of environments a molecule finds itself in. To do this, and to be able to compare different experiments, means estimating the intensity at 2150 cm⁻¹ (central position of the LO–TO splitting) and normalising by the entire integrated area of the feature. The results of this can be seen in **Figure 5.10** [19].

![Graph showing inhomogeneous broadening](image)

**Figure 5.10**: This figure shows the change in the inhomogeneous broadening of the LO–TO splitting of N₂O from the annealing experiment (black squares) and the different deposition experiments (red dots) [19]. The data points were calculated by measuring the intensity at 2150 cm⁻¹ and normalising the data from Figures 5.6 and 5.7.

As the inhomogeneous broadening increases, so does the disorder of dipoles of a molecular film, this is what is observed in **Figure 5.10**. The difference in gradients of **Figure 5.10** is about 50% larger for the deposition temperature data as compared to the
annealing experiments. This is once again the same trend and characteristic of the spontelectric effect with regards to temperature effects on the surface potential.

With the presented data so far one can state that the LO–TO splitting and the inhomogeneous broadening behaves as expected for the prototypical spontelectric molecule of N₂O.

5.3.2 Spontelectric CO Films on SiO₂

Having demonstrated the potential of RAIRS to probe the spontelectric effect of N₂O, the thesis will now focus on the impact of the spontelectric effect in the astronomical environment. As this effect is a solid bulk effect, the nature of the solid state in such environments must be considered and this highlights the importance of interstellar dust grains and their icy mantles. As explained in Chapter 1, molecular clouds play host to a wide range of molecules of which H₂O is the dominant solid phase species [25 and references within]. Direct surface potential measurements of H₂O were conducted at Aarhus University, but no spontelectric effect was observed [1]. As a dipolar molecule, a surface potential could be expected to exist, but the strong H–bonding capability in solid H₂O is thought to overpower any spontelectric dipolar ordering. However, surface work function changes has been measured using a Kelvin probe which may indicate that a surface potential could be present on ballistically–deposited H₂O films at very low temperatures [26]. The O–H stretching frequency in the sub–monolayer regime was studied in Chapter 4 where the LO–TO splitting was difficult to observe even though multilayer thick films were explored. For that reason monitoring shifts in the LO–TO splitting of H₂O multilayer films were not carried out. The attention of this thesis is therefore shifted onto the second most abundant solid state species, CO. The gas–phase dipole moment of CO (0.122 D) is similar to that of N₂O (0.167 D) and the C–O stretching frequency at about 2140 cm⁻¹ and its LO–TO splitting [27] lie in a relatively clean part of the IR spectrum as there is no interference from gas–phase H₂O or CO₂. Initially, multilayer CO films directly adsorbed on amorphous SiO₂ will be studied.

As with the N₂O experiment, initial TPD experiments were conducted to convert units of Langmuir (L) to monolayer (ML). The results of this can be seen in Figure 5.11.
Figure 5.11: This figure shows the desorption of different CO coverages from SiO$_2$. As can be seen, a clear change in behaviour is observed between 15 L and 20 L indicating that this is the completion of the first monolayer.

As can be seen in Figure 5.11, a ML is formed after introducing 20 L of CO into the chamber. Only the monolayer to multilayer transition is of interest in this work and desorption kinetics have therefore not been analysed. However, another indication of

Figure 5.12: This figure shows the whole spectrum when depositing 5 ML of CO onto SiO$_2$ at 20 K. The feature of interest, the CO stretch, at about 2140 cm$^{-1}$ has been highlighted in the insert to show the LO–TO splitting. The sharp bands at $>$3500 cm$^{-1}$ and in the 1250–2000 cm$^{-1}$ range are of gas–phase H$_2$O with the negative bands at about 2300 cm$^{-1}$ being gas–phase CO$_2$ in the optics boxes outside of the UHV chamber [28].
this is the presence of the LO–TO splitting when studying the molecular film with RAIRS. Depositing 5 ML CO onto SiO₂ gives this LO–TO splitting as can be seen in Figure 5.12 [28].

As can be seen in Figure 5.12, a clear LO–TO splitting is observable with a film thickness of 5 ML, there is also a certain degree of inhomogeneous broadening between the peaks. Once again, the 300 nm SiO₂ layer softens the MSSR and allows both the LO and TO modes to be observed. These peaks will be the focus in this section and the next. From the base temperature of these experiments (20 K) no phase change of the solid CO layer is observed until desorption. The next experiment was to see if the peaks observed in Figure 5.12 change with film thickness. The results of this are displayed in Figure 5.13.

Figure 5.13: This data shows that as the amount of CO is increased from 2.5 ML to 10 ML a slight change above the spectrometer resolution is observed when the film thickness is doubled. However, considering the general uncertainty of background dosing being about 20%, the amount of molecules on the surface can be said to have no impact of the LO–TO peak positions.

Knowing that the thickness of the film has no impact on peak position when considering the uncertainty in background dosing (i.e. 5 ML ± 20 %), a 5 ML film of CO was annealed from 20 K to 22 K to 24 K to 26 K leading to the data displayed Figure 5.14.
Figure 5.14: This shows the LO–TO splitting as the 5 ML CO film is annealed from 20 K to 26 K. Observing shifts of the peaks over the resolution of the spectrometer is impossible.

No contraction or expansion of the LO–TO splitting is observed in Figure 5.14 during annealing of a 5 ML CO film at a resolution of 1 cm\(^{-1}\). Due to the lack of observable changes, the spectrometer resolution was increased to 0.1 cm\(^{-1}\), however further annealing experiments of CO films were not conducted. The reason for this is the increased effect of deposition temperature of measured surface potentials, and the following figures will therefore be of 0.1 cm\(^{-1}\) RAIR scans with different deposition temperatures. Due to the cooling power of the cryostat, a lower base temperature cannot be obtained, however there seems to be no LO–TO shifts at temperatures below 20 K [29]. Further to the temperature constraints of these experiments, the TPD experiment indicates that 26 K is the highest possible temperature before desorption of the multilayer from SiO\(_2\) ensues. Having said this, a decrease in intensity is observed in Figure 5.14 when the 5 ML CO film is annealed to 26 K. However, as explained in Section 5.3.1, annealing a spontelectric film will lead to less of a change in the IR spectrum as compared to changing the deposition temperature. Therefore CO was deposited at variety of temperatures in order to investigate the possible spontelectric properties of CO films, the results of the deposition temperature experiments can be seen in Figure 5.15 [28].
This figure shows the results of depositing 5 ML CO onto SiO$_2$ at different temperatures. A slight shift in the LO–TO splitting of the νCO band is now observed which is greater than the resolution of the spectrometer (0.1 cm$^{-1}$) [28].

As can be seen in Figure 5.15, a contraction of the LO–TO splitting is now observed as the deposition temperature is increased, again showing that the deposition temperature has a greater effect on frequency shifts as compared to annealing. This, as previously explained, is an indication of a spontaneous material as measured through the surface potential in Aarhus and through the use of RAIRS of N$_2$O as in Section 5.3.1. This contraction although slight in the temperature range possible for these experiments is still greater than the 0.1 cm$^{-1}$ resolution of the spectrometer. These spectra were fitted with Gaussians as the N$_2$O peaks were in Section 5.3.1 and an example of this has been shown in Figure 5.16.

Fitting the other CO spectra with Gaussians means that the peak position can be quoted to a greater degree of certainty. The errors in the peaks can now be estimated as 0.01 cm$^{-1}$ and 0.02 cm$^{-1}$ for the LO and TO mode, respectively, an increased accuracy of an order of magnitude. Table 5.2 has been constructed to display the data from the deposition experiments (annealing data has not been fitted with Gaussians due to the lack of frequency shifts, and therefore not shown in Table 5.2).
Figure 5.16: This figure shows the comparison between the experimental RAIRS data of the νCO band of 5 ML CO on SiO$_2$ at 20 K and the fit with Gaussians with the residuals shown above the data and fit.

<table>
<thead>
<tr>
<th>Deposition Temperature / K</th>
<th>Wavenumber / cm$^{-1}$</th>
<th>$\Delta_{\text{LO-TO}}$ / cm$^{-1}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>20</td>
<td>2142.52</td>
<td>2138.50</td>
</tr>
<tr>
<td>21</td>
<td>2142.51</td>
<td>2138.55</td>
</tr>
<tr>
<td>22</td>
<td>2142.48</td>
<td>2138.58</td>
</tr>
<tr>
<td>24</td>
<td>2142.41</td>
<td>2138.62</td>
</tr>
<tr>
<td>26</td>
<td>2142.38</td>
<td>2138.63</td>
</tr>
</tbody>
</table>

Table 5.2: This table produces a more clear sight of the peak shifts of CO as the deposition temperature changes. A contraction is observed which is indicative of a spontelecric material.

The data in Table 5.2 shows a contraction of the LO–TO splitting as calculated in the last column. This contraction has also been graphed in Figure 5.17 [28] of the LO and TO position with respect to deposition temperature.
As is more clearly shown on Figure 5.17, the LO–TO splitting contracts with increasing deposition temperature. This leads on to the next determination of dipole disordering in the CO multilayer as temperature increases, the inhomogeneous broadening as shown in Figure 5.18 [28].
As was observed for N₂O (Figure 5.10), the inhomogeneous broadening of CO also increases with temperature. The method for producing this graph is the same as that for N₂O, however now the central point between the LO and TO modes of the νCO band is 2141 cm⁻¹. All the CO on SiO₂ data shown exhibits the same behaviour in the RAIR spectra as seen for N₂O when the temperature is changed. Thereby, these data sets indicate CO to be another molecule exhibiting the spontelectric effect. What cannot be determined from the RAIRS data is if the possible surface potential will be positive or negative. However, the work of Collings et al. [30] has shown that CO will bind to SiO₂ through the carbon leaving the positive oxygen protruding into the vacuum. Thereby, this will create a positive surface potential on the surface. The same is said when CO is deposited onto H₂O as will be discussed in the next section.

5.3.3 Spontelectric CO Films on H₂O

In Section 5.1 a characteristic of the spontelectric effect was stated as being independent of the nature of the surface the spontelectric molecules were deposited on. With this in mind and gearing these experiments towards the astrophysical environment means once again using CO as a probe molecule. In Chapter 4, a conclusion of possibly having CO directly bonded to the interstellar grain surface was put forward and this situation with regards to the spontelectric effect was discussed in the previous subsection. However, CO can still be found on a H₂O layer when the icy mantle is thick enough. The spontelectric effect being a long–range interaction means CO on H₂O should also exhibit a surface potential when CO film is great enough. For that reason, this section will focus on CO on H₂O multilayers with different structures. The H₂O structures under investigation will be porous amorphous solid water (p–ASW), compact amorphous solid water (c–ASW) and crystalline solid water (CSW).

For these experiments TPD, was not conducted to estimate the coverage of CO on the different H₂O surfaces. Instead the procedure as described in Section 5.3.3 was used leading to 20 ML CO on the H₂O surfaces. An important note regarding the amount of data points with temperature is that once again only data from 20 K have been recorded. But this time, a maximum temperature of 24 K is used because CO desorption from H₂O occurs at lower temperature [13] as compared to SiO₂. As can be seen in Figure 5.19 [31], CO on the different substrates are indeed multilayers as the bulk optical effect leading to the LO–TO splitting is observed.
Figure 5.19: This figure shows all the RAIRS data collected when 20 ML CO is deposited onto multilayers of p–ASW (A), c–ASW (B) and CSW (C) at the indicated temperatures in the 20 K to 24 K range. A shift in the LO–TO splitting of νCO is observed as the temperature increases [31].

The LO–TO splitting of the νCO band is observed to contract when on the surface of the different H₂O substrates as the deposition temperature is increased as seen in Figure 5.19. Annealing experiments of CO on H₂O were not conducted as the peak shifts were expected to be too small to be seen, as observed when depositing CO on SiO₂. At first sight, the shifts seem to be similar considering the uncertainties, however fitting the peaks with Gaussians leads to a greater estimate of the uncertainties and peak positions as done for N₂O and CO on SiO₂ previously. The uncertainties can once again be quoted as 0.01 cm⁻¹ and 0.02 cm⁻¹ for the LO and TO modes respectively. The peak positions and their shifts as the deposition temperature is increased have been detailed in Table 5.3 and graphed in Figure 5.20.
<table>
<thead>
<tr>
<th>Deposition Temperature / K</th>
<th>Wavenumber / cm(^{-1})</th>
<th>(\Delta_{\text{LO–TO}} / \text{cm}(^{-1})</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>LO (± 0.01 cm(^{-1}))</td>
<td>TO (± 0.02 cm(^{-1}))</td>
</tr>
<tr>
<td>p–ASW</td>
<td></td>
<td></td>
</tr>
<tr>
<td>20</td>
<td>2142.96</td>
<td>2138.08</td>
</tr>
<tr>
<td>22</td>
<td>2142.82</td>
<td>2138.12</td>
</tr>
<tr>
<td>24</td>
<td>2142.43</td>
<td>2138.34</td>
</tr>
<tr>
<td>c–ASW</td>
<td></td>
<td></td>
</tr>
<tr>
<td>21</td>
<td>2142.89</td>
<td>2138.08</td>
</tr>
<tr>
<td>22</td>
<td>2142.89</td>
<td>2138.10</td>
</tr>
<tr>
<td>24</td>
<td>2142.63</td>
<td>2138.29</td>
</tr>
<tr>
<td>CSW</td>
<td></td>
<td></td>
</tr>
<tr>
<td>20</td>
<td>2142.75</td>
<td>2138.16</td>
</tr>
<tr>
<td>22</td>
<td>2142.54</td>
<td>2138.19</td>
</tr>
<tr>
<td>24</td>
<td>2142.47</td>
<td>2138.29</td>
</tr>
</tbody>
</table>

**Table 5.3**: This table shows the peak positions with respect to deposition temperatures for CO on p–ASW, c–ASW and CSW. The data in this table can also be seen in Figure 5.24.

As can be seen from the data presented in **Table 5.3** and **Figure 5.20** [31], changes in the LO–TO splitting occur as the substrate is changed. The differences between the surfaces involves many factors such as density of H–dangling bonds, surface area and porosity [32, 33] and any one of these or a combination could cause the difference in the observed splitting. As will be discussed later, this also has an impact on the calculated surface potential of CO films on H\(_2\)O. The LO–TO splitting does not give an idea of the different environments CO finds itself in when deposited on different H\(_2\)O substrates. However, such environments can once again be qualitatively investigated through the
Figure 5.20: This figure displays the data from Table 5.3 of the LO (squares) and TO (circles) modes of the νCO band contracting with increasing deposition temperature. As can be seen, a greater splitting is observed at 20 K for p–ASW (blue) as compared to the other c–ASW (black) and CSW (red) [31].

The idea of the inhomogeneous broadening. The procedure to obtain Figure 5.21 [31] is exactly the same as that described when looking at CO on SiO₂ in Section 5.3.3.

Figure 5.21: This figure shows the inhomogeneous broadening as measured at 2141 cm⁻¹ between the LO and TO modes of the νCO band of 20 ML CO on H₂O ice. The blue data points are from CO on p–ASW, black is c–ASW and red is CSW. The linear regressions of the points give an idea of the similarity of environments of CO on H₂O surfaces [31].

From Figure 5.21 differences or similarities in the environment CO finds itself on the different H₂O surfaces can be extracted. The linear fits between the data points from c–ASW (black data) and CSW (red data) have very similar gradients of 0.68 ± 0.11 K⁻¹.
and $0.69 \pm 0.05 \text{ K}^{-1}$ respectively. In one way, this similarity of CO environments makes sense as there are no open pores in the c–ASW film and the larger uncertainty in the c–ASW can possibly be explained by the H–dangling bonds which are only present at the surface of the ASW film, but not in the bulk. p–ASW films are very different to the other H$_2$O films, as stated previously, which explains why the gradient of $0.88 \text{ K}^{-1}$ in Figure 5.21 is determined, however this is associated with a large standard deviation of $0.55 \text{ K}^{-1}$. Considering the uncertainties of these gradients, it is possible that CO finds itself in similar environments, no matter the H$_2$O underlayer. Factors such as porosity, H–dangling bonds and surface area could be irrelevant for these measurements. However, changes in the LO–TO splitting are still observed leading to the surface having some, for the time being, unknown effect on the data and in the end, the possible surface potential of CO in an astronomical environment.

5.4 Modelling RAIRS Data

As has been explained in subsection 5.3.1, the dipole alignment as seen through the LO–TO splitting changes as the temperature increases. This section will relate RAIRS data obtained in this thesis with the spontaneous experimental results and model from Field and co–workers at Aarhus University in the case of N$_2$O. Based on the findings presented, and the model used for N$_2$O, CO will be similarly analysed to determine the parameters associated with the spontaneous effect when deposited on SiO$_2$ as well as H$_2$O. The model used to explain the N$_2$O RAIRS results was created and built by David Field at Aarhus University and further reading material regarding the model can be found in reference [19].

Before the model is introduced a glossary of the different terms has been made in Table 5.4 for ease of reference.

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\nu_{LO}$</td>
<td>Longitudinal optical (LO) peak frequency</td>
</tr>
<tr>
<td>$\nu_{TO}$</td>
<td>Transverse optical (TO) peak frequency</td>
</tr>
<tr>
<td>$\Delta \nu$</td>
<td>Difference in LO and TO peak frequency</td>
</tr>
<tr>
<td>$\Delta \nu_S$</td>
<td>Splitting due to spontaneous Stark field</td>
</tr>
<tr>
<td>$\Delta \nu_B$</td>
<td>Intrinsic splitting (Berreman effect)</td>
</tr>
</tbody>
</table>
Symbols used for the model

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\mu$</td>
<td>Dipole moment in the solid state</td>
</tr>
<tr>
<td>$&lt;\mu^2&gt;/\mu$</td>
<td>Degree of dipole orientation</td>
</tr>
<tr>
<td>$T$</td>
<td>Deposition temperature</td>
</tr>
<tr>
<td>$\zeta$</td>
<td>Locking term (frustration term)</td>
</tr>
<tr>
<td>$E_s$</td>
<td>Spontelectric field</td>
</tr>
<tr>
<td>$E_{sym}$</td>
<td>Symmetric spontelectric field parameter</td>
</tr>
<tr>
<td>$E_{asym}$</td>
<td>Asymmetric spontelectric field parameter</td>
</tr>
</tbody>
</table>

Table 5.4: This table describes the different terms that the models use to relate the experimental RAIRS data to the surface potential measurements for N$_2$O and to show the possible extent of the spontelectric effect of solid state CO.

First, consideration of factors which might cause changes in the LO–TO splitting besides the temperature fluctuations with the spontelectric field and the Stark effect must be examined. Two contributions are considered, thermal changes of the unit cell and changes in thickness of the films which will be shown to produce a negligible effect on the LO–TO splitting as the deposition temperature is raised.

Supplying the film with thermal energy, through annealing or changing the deposition temperature will lead to changes in the (unit cell) arrangement, i.e. the density can change as for instance is also seen for H$_2$O [34, 35]. This thermal change can therefore also affect the IR spectrum and LO–TO splitting seen on the bands of solid N$_2$O. The effect of density changes related to the dipole moment derivative is explained by Equation 1 [9]:

$$v_{LO}^2 - v_{TO}^2 = \frac{4\pi}{\varepsilon V} \times \left(\frac{\partial \mu}{\partial q}\right)^2.$$  

Equation 1

This equation can be rewritten to find the density of the molecular film, $N$, through Equation 2:

$$N = 2.307 \times 10^{17} \frac{(v_{LO}^2 - v_{TO}^2)}{(\partial \mu / \partial q)^2}.$$  

Equation 2

If the data from the 48 K experiment is taken into consideration (where $v_{LO}$ is 2256.35 ± 0.1 cm$^{-1}$ and $v_{TO}$ is 2239.15 ± 0.2 cm$^{-1}$) and $\partial \mu / \partial q$ is 0.292 for the $v_{NN}$ band a value of
1.848 × 10^{22} \text{ molecules cm}^{-3} \text{ is found for } N. \text{ This value can be converted to } 1.35 \text{ g cm}^{-3}, \text{ which is the density of N}_2\text{O} [36] \text{ at an unknown temperature. By cycling through the data, and using Equation 2, it is found that the density changes as the temperature changes. This therefore means that as the density changes the LO–TO splitting can also change through the relationship in Equation 3;}

\[ \Delta \nu \propto \frac{N}{\nu_L + \nu_T}. \]  

\text{Equation 3}

If the assumption that the average of LO and TO frequencies is not dependent of the density of the film, \( N \), and state the LO–TO splitting as \( \Delta \nu \). Using the same 48 K data as previously for the LO and TO frequencies, we can then create Equation 4;

\[ N = 1.074 \times 10^{21} \times \Delta \nu \rightarrow \frac{\partial N}{\partial \Delta \nu} = 1.074 \times 10^{21} \text{ cm}^{-3} \text{ per cm}^{-1}. \]  

\text{Equation 4}

When the experimental values from Table 5.1 are considered, say from 48 to 51 K, the value of \( \Delta \nu/\Delta T \) equals 0.3 cm \( ^{-1} \) K \( ^{-1} \). This leads on to the thermal expansion coefficient \( (dN/dT) \) of N\(_2\)O equalling \(-3.22 \times 10^{22} \text{ cm}^{-3} \text{ K}^{-1}\) through \( dN/d\nu \times d\nu/dT \). The negative sign for this value means that the surface loses \( 3.22 \times 10^{22} \text{ molecules for every degree K. Such a value is equivalent to a volume expansion coefficient of } 0.017 \text{ K}^{-1} \text{ as there are } 1.848 \times 10^{22} \text{ molecules cm}^{-3} \text{ in solid N}_2\text{O when deposited at 48 K. Typical values of volume expansion coefficient lie in the range of } 10^{-5} – 10^{-6} \text{ K}^{-1}, \text{ meaning that the volume expansion can be disregarded as having an effect on the LO–TO splitting as it changes with deposition temperature.}

Variation in thickness of the films is also a factor to consider which has already been shown to have a slight effect on the LO–TO splitting in Figure 5.5. It can be seen that changing the thickness from 7 ML to 28 ML of N\(_2\)O changes the difference in the LO–TO splitting by 0.5 cm \( ^{-1} \) which can be considered negligible when referring the smallest contraction observed in Table 5.1 of 13.4 cm \( ^{-1} \). Further to this, the uncertainty in background dosing is about ±20% meaning films of 7 or 28 ML of N\(_2\)O are not expected. The value of 13.4 cm \( ^{-1} \) is the smallest change in the LO–TO splitting observed and occurs where N\(_2\)O is deposited at 66 K. This spectrum, as seen in Figure 5.7, shows a marked decrease in intensity as compared to the other deposition temperature experiments. As the amount of material on the surface is proportional to the intensity, then comparing the 66 K spectrum from Figure 5.7 to the 7 ML N\(_2\)O film of
Figure 5.5 shows similar intensities. It can therefore be argued that the 66 K spectrum is actually 7 ML instead of 14 ML as initially dosed. The reason for this decrease is the sticking coefficient as the sample temperature approaches the temperature at which multilayers of N$_2$O desorb. For that reason the experiments concerning deposition of N$_2$O at 66 K have been disregarded. Also, the effect of film thickness has been disregarded as having a significant effect on the LO–TO splitting.

Having considered the possible factors affecting the LO–TO splitting (besides the spontelectric effect) and considered them to be negligible, we will move on to the splitting itself. The LO–TO splitting is a fundamental optical effect in the solid state and would occur if there was a spontelectric field affecting a molecular film or not. For that reason, the intrinsic optical effect and the vibrational Stark effect also have to be accounted for to be able to relate the LO–TO splitting to the spontelectric effect. To look at this Table 5.5 [19] has been created for ease of reference.

<table>
<thead>
<tr>
<th>Temperature / K (± 0.3 K)</th>
<th>$v_{LO}$ / cm$^{-1}$ (± 0.1 cm$^{-1}$)</th>
<th>$v_{TO}$ / cm$^{-1}$ (± 0.2 cm$^{-1}$)</th>
<th>$\Delta v$ / cm$^{-1}$</th>
<th>$\Delta v_s$ / cm$^{-1}$</th>
<th>$\Delta v_s/\Delta v$</th>
<th>$&lt;\mu Z&gt;/\mu$</th>
</tr>
</thead>
<tbody>
<tr>
<td>48</td>
<td>2256.35</td>
<td>2239.15</td>
<td>17.2</td>
<td>5.2</td>
<td>0.303</td>
<td>0.0813</td>
</tr>
<tr>
<td>51</td>
<td>2255.9</td>
<td>2239.6</td>
<td>16.3</td>
<td>4.3</td>
<td>0.265</td>
<td>0.0683</td>
</tr>
<tr>
<td>52</td>
<td>2255.8</td>
<td>2239.8</td>
<td>16.0</td>
<td>4.0</td>
<td>0.251</td>
<td>0.0639</td>
</tr>
<tr>
<td>53</td>
<td>2255.8</td>
<td>2239.7</td>
<td>16.1</td>
<td>4.1</td>
<td>0.256</td>
<td>0.0614</td>
</tr>
<tr>
<td>55</td>
<td>2255.3</td>
<td>2240.05</td>
<td>15.25</td>
<td>3.3</td>
<td>0.214</td>
<td>0.0565</td>
</tr>
<tr>
<td>56</td>
<td>2255.3</td>
<td>2240.0</td>
<td>15.3</td>
<td>3.3</td>
<td>0.217</td>
<td>0.0540</td>
</tr>
<tr>
<td>60</td>
<td>2255.4</td>
<td>2239.85</td>
<td>15.55</td>
<td>3.4</td>
<td>0.229</td>
<td>0.0449</td>
</tr>
<tr>
<td>62</td>
<td>2254.9</td>
<td>2240.01</td>
<td>14.8</td>
<td>2.8</td>
<td>0.191</td>
<td>0.0386</td>
</tr>
<tr>
<td>66</td>
<td>2254.2</td>
<td>2240.8</td>
<td>13.4</td>
<td>1.4</td>
<td>0.106</td>
<td>0.0117</td>
</tr>
</tbody>
</table>

Table 5.5: This data is from the experiment where N$_2$O is deposited at different temperatures [19]. The first four columns are the same as seen in the bottom part of Table 5.1.

The first four columns, the same as in Table 5.1 in Section 5.3.1, are of the deposition temperature, the position of the vNN LO and TO modes and the difference in their frequencies, $\Delta v$. The fifth column is the change in frequency due to the spontelectric effect, $\Delta v_s$, due to the vibrational Stark effect, of the LO–TO splitting with the sixth
column being the ratio between \( \Delta v \) and \( \Delta v_S \). The last column are values for the dipole ordering \( \langle \mu_Z^2 \rangle / \mu \) of \( \text{N}_2\text{O} \) at their specific temperatures as taken from Field et al. [1].

The LO–TO splitting, as stated previously, is an intrinsic optical effect in solid films when observed with infrared spectroscopy in grazing incidence arising from the Berreman effect. However, the Berreman effect is independent of temperature and should therefore not change in these experiments. This means the difference in the LO and TO frequencies (\( \Delta v \)) can be described as being made of two terms, one constant part caused by the Berreman effect (\( \Delta v_B \)) and one variable part caused by the spontelectric effect (\( \Delta v_S \)) which enhances the LO–TO splitting as shown in Equation 5:

\[
\Delta v = \Delta v_B + \Delta v_S. \tag{Equation 5}
\]

Having said this, the need to know the value for \( \Delta v_B \) becomes important as the spontelectric contribution of the LO–TO splitting (\( \Delta v_S \)) makes up column five of Table 5.5. Firstly, if \( \Delta v_S \) is considered as being due to the Stark effect which in turn is due to the presence of the spontelectric field, Equation 6 can be written;

\[
\Delta v_S = \phi_{LO} \times E_{LO} + \phi_{TO} \times E_{TO} \tag{Equation 6}
\]

and therefore

\[
\frac{\Delta v_S(T_i)}{\Delta v_S(T_j)} = \frac{(\phi_{LO} \times E_{LO} + \phi_{TO} \times E_{TO})_i}{(\phi_{LO} \times E_{LO} + \phi_{TO} \times E_{TO})_j} \tag{Equation 7}
\]

where \( \phi \) is the Stark tuning due to the spontelectric potential \( (E) \) which leads to the Stark shift. Equation 7 states the same relationship with respect to differing temperature of \( T_i \) and \( T_j \). An assumption that the LO and TO modes shift by the same amount with opposite signs has to be made here to simplify the unknowns in this equation. This assumption is sustained by considering the data in Table 5.1 where the average of the LO–TO splitting at 48 K is 2247.8 cm\(^{-1}\) and falls by 0.3 cm\(^{-1}\) to 2247.5 cm\(^{-1}\) at 66 K while the overall \( \Delta v \) falls by 3.8 cm\(^{-1}\) from 48 K to 66 K.

It follows from spontelectric theory that the change in dipole ordering \( \langle \mu_Z^2 \rangle / \mu \) leads to the decrease if the spontelectric field, thereby \( \langle \mu_Z^2 \rangle / \mu \) and \( \Delta v_S \) are related. Furthermore, as no other factors affect the LO–TO splitting (save the spontelectric effect), the change
in the splitting as due to the temperature (i.e. \( \Delta \nu_i/\Delta \nu_j \)) is correlated to the orientation of the dipoles. This means \textbf{Equation 8} can be setup;

\[
\frac{\Delta \nu_B}{\Delta \nu_{Sj}} = \frac{\left( \frac{\langle \mu_z \rangle}{\mu} \right)_i}{\left( \frac{\langle \mu_z \rangle}{\mu} \right)_j} - \frac{\Delta \nu_i}{\Delta \nu_j} - 1.
\]

\textbf{Equation 8} now relates the intrinsic splitting, \( \Delta \nu_B \), the spontelectric contribution to the splitting (\( \Delta \nu_S \)), the dipole orientation (\( \langle \mu_z \rangle/\mu \)) and the overall observed LO–TO splitting (\( \Delta \nu \)) at the deposition temperatures of \( i \) and \( j \). For simplicity, the entire right hand side will be denoted as \( A \). Remembering \textbf{Equation 5}, \textbf{Equation 9} can be derived with slight reordering;

\[
\Delta \nu_j = \Delta \nu_B \left( 1 + \frac{1}{A} \right) \rightarrow \Delta \nu_B = \frac{A \times \Delta \nu_j}{(1 + A)}.
\]

From \textbf{Equation 9} the value of \( \Delta \nu_B \) can be calculated from the data in \textbf{Table 5.5} which yields an average value of \( 12.0 \pm 0.3 \text{ cm}^{-1} \) \([19]\). Given the experimental uncertainties in the values from RAIRS and the determination of the dipole orientation, this value can be considered as being fixed; as expected since the Berreman effect has no dependence on temperature. Once again returning to \textbf{Equation 5}, the value for \( \Delta \nu_S \) can be calculated as seen in column six of \textbf{Table 5.5}.

The vibrational Stark effect is known to behave linearly with changes in the electric field \([37–40]\), such as the spontelectric field generating the surface potential of \( \text{N}_2\text{O} \). As the spontelectric field arises from the alignment of dipoles along the \( z \)-axis (\( \langle \mu_z \rangle/\mu \)) the calculated values of \( \Delta \nu_S \) can be examined to see if a linear relationship exists with \( \langle \mu_z \rangle/\mu \). This is shown in \textbf{Figure 5.22} \([19]\).

As can be seen in \textbf{Figure 5.22} \([19]\), a linear relationship does exist between the spontelectric contribution to the LO–TO splitting and the dipole orientation which in itself is proportional to the spontelectric effect. The linear fit goes through the origin as when there is no alignment of the dipole at high temperature a surface potential is not observed. This, as explained earlier, is also the reason for the data point relating to the
66 K data not fitting the trend as the sticking coefficient is less than unity as this temperature is close to the N\(_2\)O desorption temperature.

**Figure 5.22:** This figure shows the relationship with the spontelectric contribution to the LO–TO splitting and the dipole alignment for N\(_2\)O. A linear relationship exists as expected except for the 66 K data point due to the decrease in the sticking coefficient when the temperatures approaches the desorption temperature of N\(_2\)O [19].

With the different contributions of the Berreman effect and the Stark/spontelectric effect leading to the observed LO–TO splitting characterised, the focus will now change to look at the impact of temperature on the splitting as based on the Stark effect. The goal is to create a model to fit the spontelectric parameters as discussed in the introduction. For clarity, **Equations 10 and 11** will be shown here which was introduced as **Equations 17 and 18** in **Chapter 2**:

\[
E_Z = E_{\text{sym}} \times \left(1 + \zeta \left(\frac{<\mu_Z>}{\mu}\right)^2\right) - E_{\text{asym}} \times \frac{<\mu_Z>}{\mu}.
\]

**Equation 10**

\[
<\mu_Z>/\mu = \coth \left(\frac{E_Z \mu}{T}\right) - \left(\frac{E_Z \mu}{T}\right)^{-1}
\]

**Equation 11**

Both \(E_{\text{sym}}\) and \(E_{\text{asym}}\) are related to the Langevin expression (**Equation 11**) through the dipole orientation \(<\mu_Z>/\mu\) as seen in **Equation 10**. Since two different modes are observed in the RAIRS data, the LO and TO modes must have differing force constants. To discuss the differing force constants, the differing frequencies of the LO and TO modes and their associated energies, a brief explanation is required.

177
Two distinct peaks related to the same vibration mode in RAIR spectra will have different force constants as they appear at different frequencies. Expressions for the high wavenumber peak \((k + \delta_A)\) and \((k - \delta_B)\) for the low wavenumber peak can be written in terms of a harmonic approximation, \(v_A \propto (k + \delta_A)^{0.5}\) and \(v_B \propto (k - \delta_B)^{0.5}\). Once again to simplify the equations to relate them, introducing an \textit{ansatz}, the \(\delta\) terms are said to be equal to each other and referred to simply as \(\delta\) (i.e. \(\delta = \delta_A = \delta_B\)). If these expressions are to be related to the LO–TO splitting, then the terms involving A would be for the LO mode as this is always at higher wavenumbers, and B for the TO mode. Also, if the expressions are to be related to the spontelectric effect, then the \textit{ansatz} involves the assumption that the \(E_{sym}, \zeta\) and \(\langle \mu_Z >/\mu\) are the same for both LO and TO modes. \textbf{Equation 12} can be set up assuming that \(\delta \ll k\):

\[
v_A \propto \left[ k \left(1 + \frac{\delta}{k}\right) \right]^{0.5} / \sqrt{M} \approx \frac{\sqrt{k/M}}{k} \times \left(1 + \frac{1}{2} \frac{\delta}{k}\right)
\]

where \(M\) is the molar mass of a molecule. A similar expression for \(v_B\) can be made where the right hand side involves a negative term in the bracketed expression.

Therefore, if the ratio of A and B are taken, \textbf{Equation 13} is made:

\[
\frac{v_A}{v_B} \approx \left(1 + \frac{1}{2} \frac{\delta}{k}\right)^2 \approx 1 + \frac{\delta}{k}.
\]

\textbf{Equation 13} relates to the RAIRS data, where \(v_A\) is \(v_{LO}\) and \(v_B\) is \(v_{TO}\), and \(\Delta v\) is equal to \(v_{LO} - v_{TO}\), it can therefore be said that;

\[
\frac{\Delta v}{v_{TO}} = \frac{\delta}{k}
\]

where \(k\) is 11.034 [41] and therefore \(\delta/k \approx 0.008\) in this case, an accuracy of greater than 0.4% is found with these approximations when looking at the data on \textbf{Table 5.5}.

Using the result from \textbf{Equation 14} including \(\delta \ll k\) and that \(\Delta v\) is small compared to \(v_{LO}\) or \(v_{TO}\) thereby saying that \(\Delta v/v_{TO} \approx \Delta v/v_{TO}\), we can look at the energies of the LO and TO modes, \(U_{LO}\) and \(U_{TO}\) respectively;

\[
\frac{U_{LO} - U_{TO}}{U_{TO}} = \frac{v_{TO}}{v_{LO}} \times \frac{1 + \frac{\delta}{k}}{1 - \frac{\delta}{k}} - 1 \approx \frac{\Delta v}{v_{TO}}.
\]

\textbf{Equation 15}
Using the data from Table 5.5, an accuracy of greater than about 0.75% is achieved with the approximations while negligible inaccuracies are found in the differential of $\Delta v/\nu_{TO}$ with respect to the dipole orientation $<\mu_Z>/\mu$. Combining Equation 14 with the spontelectric parameters discussed earlier, Equation 16 can be setup;

$$\frac{\Delta v}{\nu_{TO}} \approx \frac{\Delta v_S}{\Delta v} \times \frac{E_{asym} \times (<\mu_Z/\mu>^2)}{E_{sym} \times [1 + \zeta \times (<\mu_Z>/\mu)^2]} + \frac{\Delta v_B}{\nu_{TO}}.$$

**Equation 16** is constructed by considering the entire field relevant to the TO mode. This field introduces both the Berreman effect ($\Delta v_B$) and the spontelectric effect ($\Delta v_S$) components of the LO–TO splitting which for the surface potential and its model relate to the $E_{sym}$ term from Equation 10. Now, the ratio of the total field to the spontelectric part is proportional to $\Delta v/\Delta v_S$, and remembering that the total LO–TO splitting is the difference between the LO and TO modes means the total spontelectric field must itself also be proportional to the relevant $\nu_{TO}$. This relationship has been described in Equation 17;

$$\nu_{TO} \propto \frac{\Delta v}{\Delta v_S} \times E_{asym} \times [1 + \zeta \times (<\mu_Z>/\mu)^2].$$

**Equation 17**

Also, the difference in energies of the LO and TO modes ($U_{LO} - U_{TO}$) is proportional to the spontelectric field multiplied by the degree of dipole orientation $<\mu_Z>/\mu$. This leads to the effective spontelectric field, however the extra contribution to the LO–TO splitting from the intrinsic Berreman effect has to be accounted for in each RAIR spectrum. Overall, these factors are included to obtain Equation 16 which can be used to explain the shifts observed in the LO–TO splitting with temperature when using parameters of $E_{sym}, \zeta$ and $<\mu_Z>/\mu$ as already discussed. The value of the parameters are taken from the initial work of Field et al. [1] where the model was introduced.

However, for Equation 16 to be used with deposition temperature, we need to initially investigate the LO and TO modes with respect to the dipole orientation.

### 5.4.1 LO and TO Modes with Dipole Orientation

Determining the degree of dipole orientation $<\mu_Z>/\mu$ from the value of the LO–TO splitting means having to perform another simplification; that the intrinsic effect in the splitting (Berreman effect, $\Delta v_B$) is independent of $<\mu_Z>/\mu$. Having said that, it is
recognised that this may not be true since the LO and TO motions (and associated potentials) are influenced by the degree of dipole alignment. Furthermore, if the potentials are affected in differing manners, the $\Delta \nu_B$ will be dependent on the temperature since the spontlectric material is affected with a likewise dependence on temperature. This in turn means that the intrinsic effect could be coupled to the spontlectric effect

As the degree of dipole alignment and the LO–TO splitting has been linked, Figure 5.9 becomes important again. Once again, focusing on the deposition temperature experiment for N$_2$O, a linear fit can be applied to the frequency shift per unit temperature of the LO and TO modes leading to $-0.1 \pm 0.020$ cm$^{-1}$ K$^{-1}$ and $0.06 \pm 0.022$ cm$^{-1}$ K$^{-1}$, respectively, over the 48 – 62 K range. An assumption has to be made, that the shifts of both LO and TO bands can be said to be of the same amount per degree K which is almost covered by the uncertainty in the fits. This means Equation 18 can be set up as a simplification. It is important to note that there is no reason as to why these values are the same, it just so happens to almost be the case for N$_2$O;

\[
\frac{d\nu_{LO}}{dT}\bigg|_T = -\frac{d\nu_{TO}}{dT}\bigg|_T
\]

which, when considering how the dipole orientation ($<\mu Z>/\mu$) is related to the LO–TO splitting, therefore implies that;

\[
\frac{d\nu_{LO}}{d<\mu Z>/\mu}\bigg|_T = -\frac{d\nu_{TO}}{d<\mu Z>/\mu}\bigg|_T.
\]

After heavy manipulation, Equation 20 can be created;

\[
\frac{d\nu_{TO}}{d<\mu Z>/\mu} = -\frac{E_{sym}E_{asym}(<\mu Z>/\mu)(\nu_{LO} - \Delta \nu_B)[2\xi + \eta (\xi)(<\mu Z>/\mu)]}{[\eta E_{sym} + \xi E_{asym}(<\mu Z>/\mu)^2] \times [2\eta E_{sym} + \xi E_{asym}(<\mu Z>/\mu)^2]}
\]

In Equation 20 new symbols have been introduced to make the equation more readable, the additions are summarised in Equation 21;

\[
\xi = \frac{\Delta \nu_S}{\Delta \nu}.
\]

Equation 21 (A)
From Equation 20, it can be seen that as \( \nu_{\text{TO}} \) increases, the dipole orientation \( <\mu_z>/\mu \) decreases. This means that as the deposition temperature increases, the TO mode increases in frequency as the dipoles become less aligned. The opposite is seen for the LO mode as this decreases with increasing temperature as the dipoles are forced out of alignment. This is also the behaviour seen in the experimental RAIRS data, showing the consistence of the RAIRS results and their interpretation with the physics behind the spontaneous effect.

### 5.4.2 LO and TO Modes with Temperature

The final step in the modelling of the data is to obtain an expression relating the dipole orientation and the temperature. This is done by combining Equations 10 and 11 and differentiating this by the temperature \( (T) \) to give Equation 22:

\[
\frac{d <\mu_z>/\mu}{dT} = \frac{(1/\mu E_z) - (\mu E_z/T^2) \cosh^2(\mu E_z/T)}{(\mu E_{\text{sym}} - 2\mu(\mu E_z(\mu_{\text{sym}})/\mu)) \cosh(\mu E_z/T) - ((E_{\text{sym}} - 2\mu E_{\text{sym}}(\mu_{\text{sym}}))/T)/\mu E_z^2) - 1
\]

From Equation 22, multiplying this with Equation 20, leads to an expression for \( \frac{d\nu_{\text{LO}}}{dT} \) (and for \( \frac{d\nu_{\text{TO}}}{dT} \) since both quantities are equal and opposite).

From here, the data from the surface potential experiments is needed to complete the model and compare the observed difference in the LO–TO splitting to that of the model. As previously explained, the RAIRS data covers temperatures to 66 K as the difference in intensity (and thereby film thickness) has been shown to have a negligible effect on the peak positions. However, this is not the case for the surface potential experiments. As the surface potential is dependent on the linear relationship with film thickness, the 66 K data has not been used as the film begins to desorb [1]. Therefore, the data used for the model will range from 48 K to 62 K as seen in Table 5.5. To fit the experimental data to the model, the values of \( E_{\text{sym}} \) (4.57 \times 10^8 V m\(^{-1}\) reduced from 5.43 \times 10^8 V m\(^{-1}\)), \( E_{\text{asym}} \) (8.63 \times 10^8 V m\(^{-1}\) increased from 7.88 \times 10^8 V m\(^{-1}\)) and \( \zeta \) (75, unitless) [1] are
substituted into the equations to produce the values stated in Table 5.6 [19]. The increase and decrease in the $E_{\text{sym}}$ and $E_{\text{asym}}$ give an indication of the uncertainty level as a consequence of the simplifications made throughout the modelling.

<table>
<thead>
<tr>
<th>Temp. / K</th>
<th>$-d\nu_{TO}/d&lt;\mu Z&gt;/\mu$ / cm$^{-1}$</th>
<th>$-d(&lt;\mu Z&gt;/\mu)/dT$ / cm$^{-1}$ K$^{-1}$</th>
<th>$d\nu_{TO}/dT$ / cm$^{-1}$ K$^{-1}$</th>
<th>$\Delta\nu$ / cm$^{-1}$ (Model)</th>
<th>$\Delta\nu$ / cm$^{-1}$ (Exp. Data)</th>
</tr>
</thead>
<tbody>
<tr>
<td>48</td>
<td>76.9</td>
<td>4.30 × 10$^{-3}$</td>
<td>0.330</td>
<td>17.8</td>
<td>17.2</td>
</tr>
<tr>
<td>51</td>
<td>65.8</td>
<td>2.53 × 10$^{-3}$</td>
<td>0.167</td>
<td>16.4</td>
<td>16.3</td>
</tr>
<tr>
<td>52</td>
<td>61.3</td>
<td>2.18 × 10$^{-3}$</td>
<td>0.129</td>
<td>16.1</td>
<td>16.0</td>
</tr>
<tr>
<td>53</td>
<td>60.6</td>
<td>1.97 × 10$^{-3}$</td>
<td>0.119</td>
<td>15.8</td>
<td>16.1</td>
</tr>
<tr>
<td>55</td>
<td>51.0</td>
<td>1.64 × 10$^{-3}$</td>
<td>0.084</td>
<td>15.4</td>
<td>15.25</td>
</tr>
<tr>
<td>56</td>
<td>49.8</td>
<td>1.50 × 10$^{-3}$</td>
<td>0.075</td>
<td>15.3</td>
<td>15.3</td>
</tr>
<tr>
<td>60</td>
<td>44.9</td>
<td>1.11 × 10$^{-3}$</td>
<td>0.045</td>
<td>14.75</td>
<td>15.55</td>
</tr>
<tr>
<td>62</td>
<td>34.2</td>
<td>1.83 × 10$^{-3}$</td>
<td>0.062</td>
<td>14.6</td>
<td>14.8</td>
</tr>
</tbody>
</table>

Table 5.6: This table shows the values as calculated from the model and compared to the observed RAIRS data for N$_2$O. Explanations for each column can be found in the text [19].

Table 5.6 shows the various values as calculated and finally compared to the observed RAIRS data in column six. The first column is the deposition temperature of the experiments. The values for column two and three are obtained from Equations 20 and 24, respectively. Column four are values of the TO mode as it changes with temperature where values for the LO mode are equivalent to the TO mode, but opposite in sign. In essence, column four is the product of column two and three. Column five are the calculated values for the difference in the peak positions of the LO–TO splitting from the model presented. These values and the overall result can be seen in Figure 5.23.

As can be seen in Figure 5.23, the comparison between the model and the RAIRS data is good, with the exception of the 60 K data. However, the 60 K data point can be considered within the uncertainty limit. The uncertainties in the observed data have been set to 0.3 cm$^{-1}$ as this is the cumulative uncertainty from the Gaussian fits of the experimental data. The uncertainty of the model (red dashed lines) has been set to 0.8 cm$^{-1}$ due to the error propagation during the calculations and estimated from the constants of integration of $k_{\text{LO}}$ and $k_{\text{TO}}$ and the $\zeta''$ term.
Figure 5.23: This figure shows the final result comparing the observed RAIRS data (black scatter) with the modelled data (red solid line). The dashed red lines indicate the level of uncertainty in the modelled data (± 0.8 cm\(^{-1}\)) [19].

5.4.3 Spontelectric CO Films

With the model explained for N\(_2\)O in the previous subsection, the same general procedure follows here to indicate what a possible spontelectric field in CO on SiO\(_2\) will be. For that reason, only changes in the analysis and modelling of the CO data will be mentioned. As for the N2O model, these models regarding spontelectric CO films were created by David Field and can also be read about in references [28] and [31]. As previously stated, surface potential measurements have not been done on CO as the base temperature of the UHV apparatus in Aarhus is too high to permit the deposition of solid CO.

To begin with the same considerations as to possible reasons for peak shifts will be outlined. Here the volume expansion is also neglected as having an impact on the splitting as the splitting with respect to temperature as the coefficient for the expansion is between 0.002 to 0.003 K\(^{-1}\). Typical values for the volume expansion coefficient are usually seen to be a factor of about 10\(^2\) – 10\(^3\) times lower than calculated leaving this parameter as being rejected as causing shifts in the LO–TO splitting. Also, the film
thickness is not regarded as having an impact on the splitting for the same reasons as explained for N$_2$O and as seen in Figure 5.14.

For these experiments, the same assumptions are used as explained earlier, this includes that the overall observed LO–TO splitting is composed of an intrinsic part ($\Delta \nu_B$) from the Berreman effect and a spontelectric component ($\Delta \nu_S$) associated with the vibrational Stark effect, as explained in Equation 5. Previously, Equation 9 was used to determine the intrinsic component of the LO–TO splitting, however this requires information on the degree of dipole orientation ($<\mu_Z>/\mu$) which was determined through the experiments conducted in Aarhus. This value is not known experimentally for solid CO and a different approach must be adopted to estimate the value of $\Delta \nu_B$.

Considering what was determined in the previous subsection about $\Delta \nu_B$ not being dependent on the temperature, i.e. the peak positions of the LO–TO splitting of non–spontelectric molecules should not change with temperature. This means plotting the value of the LO–TO splitting with the inverse temperature will lead to a value of $\Delta \nu_B$ (intercept) when the effect of $\Delta \nu_S$ is eliminated as the temperature tends to infinity. This is shown in Figure 5.24 [28].

![Figure 5.24](image)

**Figure 5.24:** This figure shows the linear relationship between the value of the LO–TO splitting of CO on SiO$_2$ with respect to the inverse temperature. The intercept with the y–axis leads to an approximation for the intrinsic component of the LO–TO splitting of CO [28].

As can be seen in Figure 5.24, a near linear relationship exists. The data at 26 K has been ignored in the further analysis below, but is still shown for clarity. The reason for
ignoring it is due to the proximity to the desorption temperature of CO and the inherent issues with deposition of species close to their desorption temperature as also discussed for N$_2$O. The reason for the plot containing the inverse temperature is because $\Delta \nu_S$ acts to broaden the LO–TO splitting which decreases with temperature as the spontelectric effect diminishes. Excluding the data point at 26 K, the linear fit is accurate to within 0.6% for the slope and 0.3% for the intercept. Extrapolating the linear fit to the intercept leads to a value of 2.59 cm$^{-1}$ as being the intrinsic splitting ($\Delta \nu_B$). This is an ad hoc approach. However, with the lack of experimental data for the dipole orientation of CO, this simple, yet highly accurate linear fit, is deemed sufficient for an approximate determination of a potential spontelectric field in CO. With this data, Table 5.7 [28] can be constructed.

<table>
<thead>
<tr>
<th>Temperature / K (± 0.3 K)</th>
<th>$\nu_{LO}$ / cm$^{-1}$ (± 0.01 cm$^{-1}$)</th>
<th>$\nu_{TO}$ / cm$^{-1}$ (± 0.02 cm$^{-1}$)</th>
<th>$\Delta \nu$ / cm$^{-1}$</th>
<th>$\Delta \nu_S$ / cm$^{-1}$</th>
<th>$\Delta \nu_S/\Delta \nu$</th>
</tr>
</thead>
<tbody>
<tr>
<td>20</td>
<td>2138.50</td>
<td>2142.52</td>
<td>4.02</td>
<td>1.43</td>
<td>0.356</td>
</tr>
<tr>
<td>21</td>
<td>2138.55</td>
<td>2142.51</td>
<td>3.96</td>
<td>1.37</td>
<td>0.346</td>
</tr>
<tr>
<td>22</td>
<td>2138.58</td>
<td>2142.48</td>
<td>3.90</td>
<td>1.31</td>
<td>0.336</td>
</tr>
<tr>
<td>24</td>
<td>2138.62</td>
<td>2142.81</td>
<td>3.79</td>
<td>1.20</td>
<td>0.317</td>
</tr>
<tr>
<td>26</td>
<td>2138.63</td>
<td>2142.38</td>
<td>3.75</td>
<td>1.16</td>
<td>0.309</td>
</tr>
</tbody>
</table>

| Table 5.7: This table shows the data used for the modelling of the CO RAIRS data. The first four columns are taken directly from the experiments with the last two being calculated from the experimental data [28].

From here on a similar approach to before is used to express the $\Delta \nu_S$ in terms of the spontelectric parameters introduced earlier. Firstly, Equations 10 and 11 from before are combined and by expanding the coth function to the first order (coth(x) – 1/x = 1/3x), Equation 23 is obtained;

$$\frac{< \mu_Z >}{\mu} = \frac{3T - 2\sqrt{\mu^2\zeta E_{sym}(E_S - E_{sym}) + 9T^2}}{2\mu\zeta E_{sym}}.$$  \hspace{1cm} \text{Equation 23}

Expanding the coth function as stated has been tested with the values found in Table 5.7 and leads to an accuracy of better than 1 in 10$^5$. Once again, the $E_{sym}$ and $E_{asym}$ are associated with the spontelectric field and $\zeta$ is the frustration/locking term due to the
local force fields. The dipole moment of solid state CO is found to be 0.076 D as discussed previously.

Now, employing different force constants as for the N$_2$O calculations for these vibrational modes leads to **Equation 15** again. The CO data leads to an overall agreement of better than 0.5% (for N$_2$O, this accuracy was better than 0.75%). As in the previously described model, the energies ($U$) can be related to the spontelectric parameters where, for instance, the $U_{TO}$ part corresponds to the local symmetrical and spontelectric effects of the $E_{sym}(1 + \zeta(<\mu_Z>/\mu)^2)$ segment of **Equation 1**. Also, since the total spontelectric field is related to the spontelectric component of the LO–TO splitting, **Equation 16** can once again be setup:

$$
\frac{\Delta v}{v_{TO}} = \frac{\Delta v_S}{\Delta v} \frac{E_{asy}}{E_{sym}} \times \frac{(<\mu_Z>/\mu)^2}{[1 + \zeta \times (<\mu_Z>/\mu)^2]} + \frac{\Delta v_B}{v_{TO}}
$$

**Equation 16**

and from this, including **Equation 5** by substituting **Equation 23** through the $<\mu_Z>/\mu$ with heavy reorganisation, leads to **Equation 27**:

$$
\Delta v_S = \mu(\Delta v/\Delta v_S)v_{TO}E_S \left\{ E_S \left[ 3T + (4\mu^2(\Delta v/\Delta v_S)E_{sym}(E_S - E_{sym}) + 9T^2)^{0.5} \right] - 6E_{sym}T \right\}

\frac{\left[ 2E_{sym}(E_S^2\mu^2\zeta + 9T^2) \right]}{E_{sym}(4\pi\mu^2 + 3\Omega T)}
$$

**Equation 23**

As can be seen in **Equation 24**, both observational RAIRS data and the spontelectric parameters are included here. However, extracting values for the spontelectric parameters becomes an issue as there are too many unknowns ($E_S, E_{sym}$ and $\zeta$), therefore **Equation 25** is setup:

$$
\Delta v_S = \frac{2\pi(\Delta v/\Delta v_S)}{\Omega \zeta E_{sym}(4\pi\mu^2 + 3\Omega T) \left\{ 4\pi\mu^2 - \left[ 9T^2\Omega^2 + 4\mu^2(4\mu^2\pi^2 - \Omega^2\zeta E_{sym}^2 + 6\pi\Omega T)^{0.5} \right] - 3\Omega T \right\}}
$$

**Equation 25**

**Equations 24** and **25** are equivalent to each other when using the $E_S = (<\mu_Z>/\mu)(\mu/e_0\Omega)$ and $E_{asy} = 4\pi\mu/\Omega$ where $\Omega$ is related to the molecular volume of CO. Also, **Equation 26** has been used for further analysis; 186
Equation 26 has also been used before, but in a different manner as when first introduced as Equation 23. Further to these steps in finding the spontelectric parameters and by looking at Equation 26 we can state:

\[
\frac{\langle \mu_Z \rangle}{\mu} = \frac{\mu E_{\text{asym}} + 3T \left[ 1 - \left( 1 + \mu E_{\text{asym}}/3T \right)^2 - 4\zeta^2 E_{\text{asym}}^2/9T^2 \right]^{0.5}}{2\mu \zeta E_{\text{asym}}},
\]

**Equation 26**

Equation 27 can be used in place of the dipole orientation as used in many of the above explained equations. This simplification means the subsequent analysis for finding the spontelectric parameters for \( E_{\text{sym}} \), \( \zeta \) and \( \Omega \) becomes easier before finally estimating the dipole orientation \( \langle \mu_Z \rangle/\mu \). The same assumptions as for the N\(_2\)O modelling have been made when modelling the CO data in that \( \mu \) and \( \zeta \) are constant with temperature. However, as \( E_{\text{sym}} \) (previously considered constant with temperature) and \( \Omega \) are not known for CO multilayers, these values are considered variable before a definite value is assigned to them. So, in order to assign values for the spontelectric parameters which will lead to a possible surface potential of CO, four steps are involved. Firstly, an estimate of \( E_{\text{sym}} \) is made to yield a range of values of which the average is taken as the final value for \( E_{\text{sym}} \). Then, based on the \( E_{\text{sym}} \) value, \( \Omega \) is determined when considering all the temperatures used for the experiments. Thirdly, a value for the overall \( E_S \) is determined, before finally \( \langle \mu_Z \rangle/\mu \) is determined.

Initially, and because of the previous studies of \( \zeta \), a value of 43.8 has been chosen; this is the same value used when modelling the N\(_2\)O data. This value may at first seem random, however it has been shown that \( \zeta \) can be varied from 10 to more than 10\(^5\) with results varying less than 5\%. [1]. This, considering that the dipole moments of CO and N\(_2\)O are similar, has lead to the use of 43.8 for \( \zeta \).

This means the focus will now turn towards the first step of finding a value for \( E_{\text{sym}} \). Ignoring the data point at 26 K, due to the proximity to the desorption temperature, leads to the use of simultaneous equations for the 20, 21, 22 and 24 K data sets to find \( E_{\text{sym}} \). By substituting the values taken from Table 5.7 into Equation 25 leads to

\[
E_S = \left( \frac{\langle \mu_Z \rangle}{\mu} \right) \left( \frac{\mu}{\varepsilon_0 \Omega} \right)\text{ hence } \frac{\langle \mu_Z \rangle}{\mu} = \frac{\Omega E_S}{4\pi \mu}
\]

**Equation 27**
equations with only 2 unknown parameters, $E_{\text{sym}}$ and $\Omega$. Solving the sets of simultaneous equations for the different deposition temperature leads to an average value for $E_{\text{sym}}$ of $4.58 \pm 0.21 \times 10^7$ V m$^{-1}$ and 11.8 atomic units for $\Omega$. The uncertainties stated are due to the deposition temperature, the Gaussian fits and the error in $\Delta \nu_B$. These results were obtained by assuming that $\Omega$ is constant for the different deposition temperatures, the reason for this constant value will now be discussed.

Using the same data as before and now with the averaged value of $E_{\text{sym}}$, still with Equation 25, leads to three different values of $\Omega$ for the deposition temperatures, all summarised in Table 5.8 [28].

<table>
<thead>
<tr>
<th>Temperature / K (±0.3 K)</th>
<th>$\Omega_1$/ au × $10^4$ (±0.16 × $10^4$)</th>
<th>$\Omega_2$/ au × $10^4$ (±7)</th>
<th>$\Omega_3$/ au (±0.3)</th>
</tr>
</thead>
<tbody>
<tr>
<td>20</td>
<td>5.34</td>
<td>341</td>
<td>11.8</td>
</tr>
<tr>
<td>21</td>
<td>5.45</td>
<td>310</td>
<td>11.8</td>
</tr>
<tr>
<td>22</td>
<td>5.52</td>
<td>282</td>
<td>11.8</td>
</tr>
<tr>
<td>24</td>
<td>5.69</td>
<td>236</td>
<td>11.8</td>
</tr>
</tbody>
</table>

Table 5.8: This table illustrates the variety of $\Omega$ as the deposition temperatures change when calculated through Equation 25 [28].

As can be seen in Table 5.8, the second and fourth columns show the values for $\Omega$ are generally constant with temperature. This follows the assumptions based on the analysis for $E_{\text{sym}}$. However, $\Omega_1$ leads to values of the order of $10^4$ au which will give values for the degree of dipole orientation greater than unity which is physically unrealistic. $\Omega_2$ can be seen to vary considerably when the deposition temperature changes, and a recent study has found that the molecular volume can be related to the polarisability [42]. Since the polarisability has been considered a constant (13.159 au for CO), the molecular volume should therefore also be constant leading to the choice of 11.8 au for $\Omega$.

Now the third step can be embarked upon which will lead to values for the spontelectric field, $E_S$ as based on Equation 24 where an upper ($u$) branch and lower ($l$) branch can be found due to the nature of the equation. The results have been shown in Table 5.9 [28].
Table 5.9: This table shows how the values of $E_S$ (upper and lower values) vary with the deposition temperature as calculated through Equation 24 [28].

<table>
<thead>
<tr>
<th>Temperature / K (± 0.3 K)</th>
<th>$E_{Su} / \times 10^7$ V m$^{-1}$ (± 0.15 × 10$^7$ V m$^{-1}$)</th>
<th>$E_{Sl} / \times 10^7$ V m$^{-1}$ (± 0.30 × 10$^7$ V m$^{-1}$)</th>
</tr>
</thead>
<tbody>
<tr>
<td>20</td>
<td>3.78</td>
<td>7.06</td>
</tr>
<tr>
<td>21</td>
<td>3.75</td>
<td>7.43</td>
</tr>
<tr>
<td>22</td>
<td>3.72</td>
<td>7.63</td>
</tr>
<tr>
<td>24</td>
<td>3.66</td>
<td>8.22</td>
</tr>
</tbody>
</table>

From here the dipole orientation of solid CO can be found through the simplified relationship of $E_S$ and $<\mu_Z>/\mu$ as shown in Equation 27.

Table 5.10: This table shows the values of the degree of dipole orientation as the temperature and spontaneous field vary. The subscripts $u$ and $l$ refer to the upper and lower branch as calculated for $E_S$ [28].

<table>
<thead>
<tr>
<th>Temperature / K (± 0.3 K)</th>
<th>$E_{Su} / \times 10^7$ V m$^{-1}$ (± 0.15 × 10$^7$ V m$^{-1}$)</th>
<th>$&lt;\mu_Z&gt;/\mu_u$ (±0.0024)</th>
<th>$E_{Sl} / \times 10^7$ V m$^{-1}$ (± 0.30 × 10$^7$ V m$^{-1}$)</th>
<th>$&lt;\mu_Z&gt;/\mu_l$ (±0.0001)</th>
</tr>
</thead>
<tbody>
<tr>
<td>20</td>
<td>3.78</td>
<td>0.0645</td>
<td>7.06</td>
<td>0.0121</td>
</tr>
<tr>
<td>21</td>
<td>3.75</td>
<td>0.0582</td>
<td>7.43</td>
<td>0.0114</td>
</tr>
<tr>
<td>22</td>
<td>3.72</td>
<td>0.0526</td>
<td>7.63</td>
<td>0.0108</td>
</tr>
<tr>
<td>24</td>
<td>3.66</td>
<td>0.0434</td>
<td>8.22</td>
<td>0.0097</td>
</tr>
</tbody>
</table>

Table 5.10 shows the response of the spontaneous field ($E_S$) and the dipole orientation ($<\mu_Z>/\mu$) as the deposition temperature is increased. As stated throughout this chapter, as the temperature is increased, the general behaviour of spontaneous materials leads to a decrease in the $E_S$ and $<\mu_Z>/\mu$, this is also observed for the upper branch values. However, the lower branch values behave anomalously in that the $E_S$ increases while the $<\mu_Z>/\mu$ (as expected) decreases as the temperature is increased. A possible answer for this behaviour can potentially be found when differentiating Equation 24 with $T$, however this has not yet been attempted. The behaviour in the double–value of $\Omega$ and therefore equivalently $E_S$ as seen for CO has also been observed through direct surface potential experiments at Aarhus University when studying propane. Here, when depositing about 2,500 ML propane, the spontaneous field switches from an upper to a lower branch of values leading to a double–valued $E_S$. 

189
Although the methods of analysis for N$_2$O and CO differ due to lack of certain key experimental data (such as dipole orientation), the analysis as just shown for CO can be done for the N$_2$O data too. Suffice to say that plugging the relevant N$_2$O data into the recently presented equations in this subsection leads to an $E_{\text{sym}}$ value of $4.69 \pm 0.19 \times 10^8$ V m$^{-1}$ which is in good agreement to the previously calculated result of $4.57 \pm 0.14 \times 10^8$ V m$^{-1}$.

The last results to model are when multilayers of CO are deposited onto different types of H$_2$O. For simplicity, only the results will be shown as the entire model and procedure are the same as just shown for CO directly on SiO$_2$. The only changes are the frequencies for the LO–TO splitting as shown in Table 5.3 and the intrinsic Berreman effect of $0.307 \pm 1.589$ cm$^{-1}$ for p–ASW, $0.898 \pm 1.285$ cm$^{-1}$ for c–ASW and $2.119 \pm 0.104$ cm$^{-1}$ for CSW [31]. Because of the large uncertainties in the $\Delta \nu_B$ values, the largest value of $2.119 \pm 0.104$ cm$^{-1}$ will be used. This will naturally have the effect of decreasing the possible surface potential meaning such a value can be regarded as a minimum value for the spontelectric effect of CO on H$_2$O. Following each step, Table 5.11 [31] has been made to show the values of the upper branch spontelectric field for the different H$_2$O layers and deposition temperature.

<table>
<thead>
<tr>
<th>H$_2$O type</th>
<th>$E_{\text{sym}} / \times 10^7$ V m$^{-1}$</th>
<th>$E_S / \times 10^7$ V m$^{-1}$ (± 0.15 $\times 10^7$ V m$^{-1}$)</th>
<th>$&lt;\mu_z&gt;/\mu$ (± 0.0024)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>20 K</td>
<td>22 K</td>
<td>24 K</td>
</tr>
<tr>
<td>p–ASW</td>
<td>4.68 ± 0.1</td>
<td>3.73</td>
<td>3.65</td>
</tr>
<tr>
<td></td>
<td></td>
<td>3.79</td>
<td>3.72</td>
</tr>
<tr>
<td>c–ASW</td>
<td>3.16 ± 0.1</td>
<td>1.99</td>
<td>1.83</td>
</tr>
<tr>
<td></td>
<td></td>
<td>1.96</td>
<td>1.80</td>
</tr>
<tr>
<td>CSW</td>
<td>3.74 ± 0.1</td>
<td>2.89</td>
<td>2.84</td>
</tr>
<tr>
<td></td>
<td></td>
<td>2.85</td>
<td>2.79</td>
</tr>
</tbody>
</table>

Table 5.11: This table shows the overall result of the spontelectric parameters and the dipole orientation when CO multilayers are deposited onto different types of H$_2$O while the deposition temperature is changed. The * marks where the deposition temperature is 21 K which is only the case for the c–ASW experiments [31].

Table 5.11 sums up the different calculations of the spontelectric field of CO on p–ASW, c–ASW and CSW. As can be seen, different values are found which are a result
of the different layers under CO. From [1] experiments have shown, the H$_2$O is not thought to be spontelectric because of the strong H–bonding in the films. However as already mentioned, p–ASW has also been shown to possibly harbouring a surface potential [26] from Kelvin probe measurements. If this potential is positive, as CO, then this could be the reason for the greater calculated potential for CO on p–ASW as a cumulative value would be observed as when combining different spontelectric films [1]. For the c–ASW and CSW films the nature of the H$_2$O surface being different could cause CO to bind in a variety of fashions leading to random orientations of CO on the surface for c–ASW as compared to the more ordered CSW. This would mean that the surface could have an effect on the overall surface potential as previously thought of as not being the case.

To summarise the different models and their results, **Table 5.12** has been created for direct comparison between the averaged values over the deposition temperatures.

<table>
<thead>
<tr>
<th>Molecular system</th>
<th>Measured $E_S$ / $\times 10^7$ V m$^{-1}$</th>
<th>Calculated $E_S$ / $\times 10^7$ V m$^{-1}$</th>
<th>Potential per Monolayer / mV ML$^{-1}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>N$_2$O on SiO$_2$</td>
<td>6.3 ± 0.30</td>
<td>5.71 ± 0.30</td>
<td>19.4</td>
</tr>
<tr>
<td>CO on SiO$_2$</td>
<td>–</td>
<td>3.72 ± 0.15</td>
<td>12.6</td>
</tr>
<tr>
<td>CO on p–ASW</td>
<td>–</td>
<td>3.70 ± 0.15</td>
<td>12.6</td>
</tr>
<tr>
<td>CO on c–ASW</td>
<td>–</td>
<td>1.99 ± 0.15</td>
<td>6.7</td>
</tr>
<tr>
<td>CO on CSW</td>
<td>–</td>
<td>2.83 ± 0.15</td>
<td>9.6</td>
</tr>
</tbody>
</table>

**Table 5.12**: This table summarises the results obtained through the analysis of the RAIRS data of N$_2$O and CO. As can be seen for the CO data, peculiar results are obtained when the substrate is changed as already discussed in the text.

This section has discussed the use of RAIRS to investigate the spontelectric effect of dipolar molecules. Through the analysis a good agreement between observations and modelled N$_2$O data has been shown. The same principles have then been used to show that CO exhibits the spontelectric effect as well. Some questions are still outstanding, such as the double valued–ness of CO and the different spontelectric fields exhibited on different surfaces. However, a surface potential is believed to be present in such multilayer films.
5.5 Astrophysical Implications

While N$_2$O has been detected in the astronomical environment, CO is the main molecule of interest with respect to the spontelectric effect in the interstellar medium (ISM). As stated previously CO has been found in relatively pure quantities [43, 44] where the film thicknesses can reach as much as 50 to 60 ML in molecular clouds and pre–stellar cores. In these cold cores, the degree of ionisation has been estimated to be lower than other ultraviolet (UV) shielded areas of the ISM by a factor of five to ten [45]. The degree of ionisation in a cold core is due to cosmic rays inducing ionisation as they travel unobstructed through different media in the ISM. For a typical core density of about $10^5$ molecules cm$^{-3}$, the cosmic ray induced ionisation fraction has been estimated at about $3 \times 10^{-8}$ [46–48]. The degree of ionisation in these regions of the ISM has considerable impact on the chemistry; on the cooling rates when molecular clouds collapse; and on the magnetic fields during the early stage of stellar formation. A dust grain is typically thought of as having one negative charge per grain on the surface. However, a surface potential from a CO multilayer can have a great impact on this surface charge and possibly change it drastically.

The work of Nielbock et al. [49] and Carelli et al. [50] are two of many studies that discuss the observations of CO being depleted from the gas phase as it condenses onto dust grains. CO can naturally also undergo reactions to form CO$_2$ [51] or CH$_3$OH [52] and thereby be depleted in general. Hence, diminishing a potential spontelectric effect on dust grains. However, this is not considered here for simplicity. An estimate of the time taken for CO to deplete from the gas phase and form nearly 12 ML has been conducted in connection with the spontelectric potential of CO [31]. This analysis was done by considering the highly studied molecular cloud core of Barnard 68 (B68) with H$_2$ number density ($n_{H_2}$) of $10^5$ molecules cm$^{-3}$, ratio of [CO] to [H$_2$] of $10^{-4}$ and temperature ($T$) of 10 K. These parameters along with the density of dust grains of 2 g cm$^{-3}$ as observed astronomically [53, 54] and the proportion of the mass of a grain as compared to the medium of 0.013 [55] lead to the value of 12 ML. This value also considered the effect on the dust grain radius, taken to be 0.1 μm [56], and its change of radius as CO layers grow as a function of time. The overall results of this calculation are shown in Figure 5.25 [31].
Figure 5.25: The two graphs show the depletion of CO from the gas phase (A) as the molecules condense onto the cold interstellar dust grain (B) with time. Both graphs have been done with typical astronomical conditions as found in the core of B68 [31].

As explained, Figure 5.25 (A) shows the depletion of CO from the gas phase while (B) is of CO ice growth in ML with time. As can be seen, nearly all CO is condensed onto the surface in (A) in a time of about $2.9 \times 10^5$ years. A monolayer is formed after about $4 \times 10^4$ years in (B). Further to Figure 5.25, the analysis of CO on a dust grain also involves an estimate of the rate of electrons impacting a grain as based on previous work by Draine and Sutin [48]. Both of these models include a cross-section (dust grain itself), but also a factor involving the effective charge ($\nu$) of a dust grain (either repelling or attracting electrons or ions) with the reduced temperature ($\tau$) which has all been summed up in $f(\nu, \tau)$. $\nu$ in the case of this model relates to the charge on the dust grain divided by the charge of the incident species, either an electron or ion (specifically H⁺ here). The work by Draine and Sutin resulted in Equation 28 for the rate of collision of a species ($X$) per second with a dust grain surface;

$$J_X = n_x S_X \left( \frac{kT_X}{m_X} \right)^{0.5} \times \pi a^2 \times f(\nu, \tau)$$

Equation 28

where the subscript $X$ refers to either electrons ($e$) or ions ($i$). $n$ is the number of species present, $S$ is the sticking coefficient of the species (set to unity [57, 58]), $k$ is the rate constant, $m$ is the mass of the species of interest and $a$ is the grain radius including the increasing size of CO ice. $T$ is the temperature of the species (of the electrons in this case) which has been estimated at 10 K as the electron equilibrates to the kinetic
temperature of the surroundings initially through electronic inelastic collisions and then elastic collision with H\textsubscript{2} in the gas phase. Also, \(f(\nu, \tau)\) is equal to \([1 + (4\tau + 3\nu)^{0.5}]^2\exp((-\nu(1 + \nu^{-0.5})))/\tau\), \(1 + (\pi/2\tau)^{0.5}\) and \((1 - (\nu/\tau))(1 + 2/(\tau - 2\nu))^{0.5}\) for negatively, neutral and positively charge dust grains.

On average, and in principle, the flux of electrons and ions should be the same over time considering how these species are produced from neutral species becoming two oppositely charged species through the interaction with cosmic rays. For this to hold, \(\tau\) is set to 0.1 – 0.2, leading to an implied charge on the dust grains of \(-0.91\) through \(1/[1 + (\tau_0/\tau)^{0.5}]\) where \(\tau_0\) is 0.00139 [48]. This value implies that the grain is negatively charged, however the same calculation can be made for the removal of an electron where the grain charge becomes 1.09. For these values of grain charge, and a value of \(\tau\) set to 0.2, Table 5.13 [31] can be set up when calculating Equation 28.

<table>
<thead>
<tr>
<th>Species</th>
<th>Grain Charge</th>
<th>Lifetime to hit grain / years</th>
</tr>
</thead>
<tbody>
<tr>
<td>(e^-)</td>
<td>-0.91</td>
<td>0.32 – 0.64</td>
</tr>
<tr>
<td>(e^-)</td>
<td>0</td>
<td>0.03</td>
</tr>
<tr>
<td>(e^-)</td>
<td>+1.09</td>
<td>0.01</td>
</tr>
<tr>
<td>(H^+)</td>
<td>-0.91</td>
<td>0.32 – 0.64</td>
</tr>
<tr>
<td>(H^+)</td>
<td>0</td>
<td>1.27</td>
</tr>
<tr>
<td>(H^+)</td>
<td>+1.09</td>
<td>31.71 – 63.42</td>
</tr>
</tbody>
</table>

Table 5.13: This table sums up the estimated timescales for a species (electron or proton) to encounter an interstellar dust grain as calculated through Equation 28 [31].

Table 5.13 shows the result of Equation 28 when using a temperature of 10 K for the species. What can be stated from this is that the time taken for either of the charged species hitting any type of grain (neutral or charged) is much less than the time taken for an icy mantle to grow, as has been estimated being on the mega–year scale for environment such as B68.

Considering the implications of a surface potential due to spontelectric CO on a dust grain, means thinking of the icy mantle formation. CO ice will slowly form as illustrated in Figure 5.25, and as shown in (for instance) Figure 5.15, a multilayer exhibiting the LO–TO splitting is present at about 5 ML. The LO–TO splitting and its shifts with temperature being an indication of a spontelectric field means that at, say, 5
ML a surface potential is present. A value of 5 ML is chosen since the splitting is observed and because the spontelectric effect is a macroscopic effect needing a certain amount of material for it to “turn on”. The time taken for a 5 ML film to be formed is about 5,000 years as seen in Figure 5.25 and at this time, the spontelectric effect becomes active instantly creating a surface potential, $\phi$, of about 33 mV (recollecting 6.695 mV ML$^{-1}$). This potential is equivalent to about 2.3 surface charges, $q$, as calculated through Equation 29.

$$q = 4\pi \varepsilon_0 a n_{ML} \phi$$ \hspace{1cm} \text{Equation 29}

where $\varepsilon_0$ is the permittivity of free space, $a$ is the dust grain radius and $n_{ML}$ is the number of monolayers of CO. This means that a dust grain goes from a surface charge of −0.91 to +1.4, or in other words, some grains will have a charge of +1 and others +2 with an average of +1.4. The reason for the positive potential is because of the orientation of CO on the surface [30] as mentioned earlier. With this in mind, the value of about $10^{-2}$ years for an electron to meet a dust grain is decreased by a factor of 1.09/2 when considering the dust grains with 2 surface charges (encounter time is now about $5 \times 10^{-3}$ years). As the dust grain attracts electrons due to its positive charge, it then becomes neutral needing another $3 \times 10^{-2}$ years before new electrons or ions begin to encounter the dust grain on a timescale of a further 0.32 − 0.64 years. As both electrons and ions stick to the neutral dust grain recombination reactions can occur [57], in turn creating neutral species. However, the spontelectric state of CO is still present and growing as more CO is adsorbed onto the dust grain. The cycle of electron attraction, followed by ion attraction leading to neutral species will continue and drag charge out of the gas phase. This will in effect continue until CO has been depleted from the gas phase and a film of 12 ML, as shown in Figure 5.25, is present. This amount of molecules equates to about 5.75 charges on the surface, meaning that 5.75 electrons will be attracted and again leading to an equal number of ion being attracted. A sketch of this can be seen in Figure 5.26.

Recombination between electrons and cations will involve mobility on the grain surface as discussed by Stamatellos et al. [59] where an electron residence time at an adsorption site was given to be about $10^5$ seconds or about $3 \times 10^{-3}$ years. In this time the electron can tunnel through a distance of about 20 nm, this in turn means that an electron can
Figure 5.26: This figure shows how CO initially aggregates onto a dust grain. The spontelectric effect in CO starts when a multilayer is formed thereby creating a positively charged surface. This attracts electrons, which in turn attracts cations and together they can recombine leading to the cycle starting over.

Generally cover an entire dust grain surface (with a radius of 0.1 μm) in the space of 100 residence lifetimes. Therefore, a time of $\leq 10^7$ seconds (or 0.1 years) is needed for an electron to interact with a cation. Further to this, without the spontelectric effect of CO, an average of 0.91 electrons and 0.91 cations being present on the surface will lead to recombination occurring on the timescale of $\leq 10^7$ seconds (or 0.1 years). The recombination reactions will occur as a proportionality of concentrations of the different species on the dust grain, \( i.e. [e_{grain}] \times [cation_{grain}] \). However, as discussed, the spontelectric state of CO when 12 ML have adsorbed onto the dust grain surface will lead to an average of 5.75 charges on the surface. Therefore a new relationship will be setup where the ratio of species of non–spontelectric grains to spontelectric grains becomes 5.75:0.91, or a factor of about 6.3 increase in recombination efficiency. And, because of the balance between negatively and positively charged species over time \([e_{grain}]=[cation_{grain}]=[e_{grain}]^2\) which leads to the ratio of \((5.75/0.91)^2\) equalling about 40. This value of 40 (where the increase in efficiency of about 6.3 comes from \(40^{0.5}\)) is the increase in timescale for recombination, now being $\leq 2.5 \times 10^5$ seconds (or $7.9 \times 10^{-3}$ years). This increase in recombination will have a direct effect on the degree of ionisation in the ISM thereby reducing it.

To illustrate this reduction of the degree of ionisation in the ISM, B68 will once again be used as an example. The rate of cosmic ray ionisation (\(\zeta_{cr}\)), typically about $3 \times 10^{-17}$
s⁻¹ [55], combined with H₂ density (10⁵ molecules cm⁻³) is responsible for the production of charge while recombination reactions through ion–electron processes in the gas and solid phase remove charge. In the gas phase, removal of charge is mainly seen through the e⁻ + H₃⁺ route where H₃⁺ itself is responsible for about 0.2% of the total ionisation [55] with a rate coefficient of recombination of about 2 × 10⁻⁷ cm⁻³ s⁻¹ [60]. Multiplying these values together gives an effective rate coefficient of about 4 × 10⁻⁸ cm³ s⁻¹ which can be balanced with the cosmic ray ionisation per volume to give 8.7 × 10⁻³ cm⁻³ (through (3 × 10⁻¹⁷ s⁻¹ × 10⁵ cm⁻³ / 4 × 10⁻⁸ cm³ s⁻¹)⁰.⁵) which in turn gives an ionisation fraction of 8.7 × 10⁻⁸. The standard ionisation fraction observed for B68 is about 5 × 10⁻⁹ meaning that pure gas–phase recombination reactions are not enough to produce the observed ionisation fraction values. This must mean that the grain surface accounts for the rest of charge removal in the cores similar to B68.

If, for the time being, only the non–spontelectric grain surface is considered, then a statement can be made that the rate of loss of ionisation is purely due to the dust grain density, n₉ (0.73 m⁻³), where the rate can be symbolised through Equation 30;

\[
\text{rate of loss} = kn_9 = 7.3 \times 10^{-12} \times kn_{H_2}. \quad \text{Equation 30}
\]

In this equation, k is the rate constant for this particular first order process, n_{H₂} is the H₂ density (10⁵ cm⁻³) and as can be seen n₉ has been changed to n_{H₂} by considering the ratio of the two values. As there is a balance between produced charge and removed charge, this equation can be related to the previous mention of the creation of charged species (ζ_{cr} × n_{H₂}) through the Equation 31;

\[
ζ_{cr}n_{H_2} = 7.3 \times 10^{-12} \times kn_{H_2}. \quad \text{Equation 31}
\]

Now, this equation can be solved for k which yields a value of about 4.1 × 10⁻⁶ s⁻¹ which can also be thought of as 2.4 × 10⁵ s (or 7.7 × 10⁻³ years) between different recombination reactions. This value is very similar to the calculated value between recombination reactions on a spontelectric surface of 7.9 × 10⁻³ years when 5.75 charges are found on a complete 12 ML film of CO. This means that the production of charge (as calculated through ζn_{H₂}) is balanced with the removal of charge. For a non–spontelectric grain, the efficiency of charge removal would be decreased by a factor of 6.3 as discussed previously. Gas–phase charge removal combined with non–
spontelectric grain charge removal leads to an ionisation degree of about $3 \times 10^{-8}$ which is not unusual for dark regions of the ISM [55, 61]. For that reason, spontelectric or not, the role of dust grains with regards to charge removal through recombination reactions in dark clouds is pivotal. However, with the presence of spontelectric CO this charge removal will be amplified by a factor of 6.3 [31] as mentioned earlier.

The recombination of charged species on dust grains has been discussed in detail in Whittet et al. [62] where electrons and ions on the surface are removed continuously on a timescale of about $2 \times 10^5$ years as this is close to the completion of the 12 ML CO film in Figure 5.29. In the model proposed by Whittet et al. a polarisation interaction between ions or electrons and the grain is included which is naturally of importance in this work. The model also states that the minimum grain size is important, however this is not accounted for in this work. Using equation 5.15 from Draine et al. [48] with a temperature of 10 K and ion mass of a proton and setting this equal to the charge loss rate on a non–spontelectric grain leads to a degree of ionisation of about $2.8 \times 10^{-8}$. This value includes the gas–phase removal of charge and can be considered the same as the degree of ionisation discussed above with 0.91 charges on a non–spontelectric grain.

The ideas set out above indicate that spontelectric CO will aid in the removal of charge from the gas phase and further decrease the degree of ionisation in cores such as B68. The decrease is on the order of about 6.3 as shown, however there are considerable uncertainties in this value and error bars cannot be simply assigned. As has been stated throughout this work, the assumption of a dust grain having a radius of 0.1 μm might need to be modified as there are more and more observational data showing that the need for the grain size distribution to be re–visited to include larger grain populations [63, 64].

5.5 Conclusion

When considering the data and analysis of the N$_2$O experiments, a correlation between LO and TO peak contraction is observed which can be connected to the behaviour of a spontelectric material. The model developed and explained throughout this chapter is based on the observed and measured spontelectric effect of N$_2$O and has been shown to follow the changes in LO–TO frequencies ($\Delta \nu$) as the deposition temperature increases as measured through RAIRS. Good agreement between the model and experimental
data indicate that the spontelectric effect can be investigated through observation of the LO–TO splitting by RAIRS. Since no surface potential is measured through RAIRS, this is an independent method of investigation and gives further credence to the proposal that the spontelectric effect is based on dipole orientation.

As has been explained, LO–TO splitting arises through the intrinsic effects of activating different phonons in a solid film as it is perturbed by the IR beam. However, as is also explained, the LO–TO splitting is enhanced due to the spontelectric effect through the vibrational Stark effect. The ratio of the splitting due to a spontelectric field with the total splitting ($\Delta v_S/\Delta v$) can be seen to decrease with temperature as the spontelectric effect decreases. This factor therefore furthers the understanding of the LO–TO splitting of solid films when temperature dependent shifts are observed. This can therefore mean that molecules exhibiting a temperature dependence on the peak positions of the LO–TO splitting can be spontelectric.

As the dependence of temperature on the LO–TO splitting has been shown to be due to the spontelectric effect, CO on SiO$_2$ can be stated as being spontelectric. The same behaviour is observed for CO as for N$_2$O, although the peak shifts are smaller. The range of temperature of these experiments is also less than that of N$_2$O leading to reliable data only coming from experiments in the 20 K to 24 K temperature range. Having said this, a trend is observed lending credence to the spontelectric state of CO on SiO$_2$. In addition to this, it has also been shown that inverting the analysis used in the case of N$_2$O that the surface potential arising from the spontelectric effect can be calculated through the LO–TO splitting. The size of this potential is calculated to be $5.71 \pm 0.30 \times 10^7$ V m$^{-1}$ as compared to the directly measured experimental value of $6.30 \pm 0.30 \times 10^7$ V m$^{-1}$. For CO, a surface potential has been calculated to be $3.72 \pm 0.15 \times 10^7$ V m$^{-1}$.

CO on different multilayers of H$_2$O has also been studied. The relative spontelectric field of CO on SiO$_2$ to CO on p–ASW to CO on c–ASW to CO on CSW is 1:1:0.76:0.52 when CO is deposited at 20 K for all substrates save c–ASW. As has already been explained, p–ASW may be spontelectric itself, and if the direction of the field is the same as that of CO, an additive effect will be observed leading to a greater surface potential.
As discussed in **Chapter 4**, bare dust grain regions can become available for CO adsorption in the early stages of mantle formation. At later stages when H\textsubscript{2}O has formed and is the dominant part of an icy mantle, CO can also adsorb onto this. CO on SiO\textsubscript{2} and CO on H\textsubscript{2}O have been shown to both be spontelectric when a great enough film is formed. The effect of the spontelectric CO layer is to drag charge (ions and electrons) from the gas phase. In the solid state, electrons and cations can recombine, returning the grain to its positive charge, thereby attracting more electrons and the catalytic cycle continues. The model, as explained, suggests that the efficiency of spontelectric grains in removing charge from an interstellar cloud is increased by a factor of about 6 as compared to non–spontelectric grains.

Spontelectric CO may not be the only pathway for charge removal in interstellar clouds, and the model being based on a dust grain radius of 0.1 μm leaves it open for further modelling work with other grain radii. However, the low degree of ionisation in cold regions can be due to spontelectric CO when depleted from the gas phase. It would therefore be interesting to investigate how the models governing the physics and chemistry in dense molecular clouds, pre– and protostellar cores, low–mass star formation and planet forming disks are influenced if the spontelectric effect of CO is included.
5.6 References


[36] Encyclopedia Astronautica, \url{http://www.astronautix.com/props/n2osolid.htm}


Chapter 6

**Concluding Remarks and Outlook**

Contents of this chapter

6.1 Introduction ........................................................................................................ 206
6.2 Chapter 3 ........................................................................................................... 206
6.3 Chapter 4 ........................................................................................................... 210
6.4 Chapter 5 ........................................................................................................... 212
6.5 References ....................................................................................................... 215
6.1 Introduction

The general storyline of this thesis has been to study one of the solid state formation pathways of interstellar H$_2$O. From there, considering the initial low concentration of H$_2$O on an interstellar dust grain, the focus changed towards looking at how H$_2$O behaves on such model grains, and thus investigating how an interstellar dust grain ice mantle might build up. As time continues, the mantle grows rich with other molecules. The second most abundant molecule in such a mantle is CO. The multilayer of CO on a typical interstellar dust grain model and on various forms of H$_2$O was then studied with the focus of its inherent spontaneous electric field leading to a surface potential. The remainder of this brief chapter will highlight the conclusions of the individual chapters along with future work as there are yet more interesting experiments needed to further our understanding of the results presented in this thesis.

6.2 Chapter 3

Chapter 3 introduced one aspect of the mechanism of H$_2$O formation as discussed in [1] purely focussing on the O atom chemistry on SiO$_2$, porous amorphous solid water (p–ASW), compact solid amorphous water (c–ASW) and crystalline solid water (CSW). While these results are preliminary and considerable future work remains possible, a few conclusions can be drawn.

As has been shown through temperature programmed desorption (TPD) and reflection–absorption infrared spectroscopy (RAIRS), O$_3$ is formed on all surfaces studied (SiO$_2$, p–ASW, c–ASW and CSW) without an apparent preference of surface. O$_2$ is naturally also formed from the O atoms beam, however no evidence for H$_2$O$_2$ formation or reactive desorption of O$_2$ or O$_3$ was found to occur. The lack of reactive desorption could, however, be because of the background presence of O$_2$ in the main chamber from the beam source.

The RAIR spectra of O$_3$ formed after dosing the atomic beam for 50 minutes appear to be the same irrespective of the sample surface. The reason for the similar features could be one of three; O$_3$ forms islands on the investigated surfaces, O$_3$ has adsorbed to SiO$_2$ as 20 ML H$_2$O have not yet covered the entire SiO$_2$ surface or O$_3$ is formed in a matrix of O$_2$. Of these possible scenarios, O$_3$ in an O$_2$ matrix seems the most likely. In all
cases, four contributions to the O\textsubscript{3} feature were observed as shown in Table 6.1 along with the corresponding literature values [2]. And, from the TPD experiments of O\textsubscript{2}, a variety of binding energies were found as listed in Table 6.2.

<table>
<thead>
<tr>
<th></th>
<th>SiO\textsubscript{2} (± 1)</th>
<th>p–ASW (± 1)</th>
<th>c–ASW (± 1)</th>
<th>CSW (± 1)</th>
<th>Literature (± 2)</th>
</tr>
</thead>
<tbody>
<tr>
<td>[O\textsubscript{3}...O] / cm\textsuperscript{-1}</td>
<td>1031</td>
<td>1031</td>
<td>1032</td>
<td>1032</td>
<td>1032</td>
</tr>
<tr>
<td>O\textsubscript{3} (O–O) asymmetric stretch / cm\textsuperscript{-1}</td>
<td>1036</td>
<td>1037</td>
<td>1037</td>
<td>1037</td>
<td>1037</td>
</tr>
<tr>
<td>[O\textsubscript{3}...O\textsubscript{3}] / cm\textsuperscript{-1}</td>
<td>1045</td>
<td>1045</td>
<td>1045</td>
<td>1045</td>
<td>1042</td>
</tr>
</tbody>
</table>

Table 6.1: This table shows the overall results of all the RAIR spectra of O\textsubscript{3} and the interactions leading to the IR spectra. These values can be compared to literature values as stated in the last column.

<table>
<thead>
<tr>
<th></th>
<th>O\textsubscript{2} beam</th>
<th>O atomic beam</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>SiO\textsubscript{2}</td>
<td>SiO\textsubscript{2}</td>
</tr>
<tr>
<td>$E_{\text{des}}$ / kJ mol\textsuperscript{-1}</td>
<td>8.5 ± 0.1</td>
<td>6.7 ± 0.2</td>
</tr>
<tr>
<td>$v$ / molecules cm\textsuperscript{-2} s\textsuperscript{-1}</td>
<td>$4 \times 10^{30}\text{Hz}$</td>
<td>$4 \times 10^{27}\text{Hz}$</td>
</tr>
</tbody>
</table>

Table 6.2: This table shows the full range of TPD results of O\textsubscript{2} desorption from the different surface investigated (SiO\textsubscript{2}, p–ASW, c–ASW and CSW). The main body of the results is of O atomic beam dosing with O\textsubscript{2} molecular beam dosing results shown as a comparison.

As can be seen in Table 6.2, a spread of about 2 kJ mol\textsuperscript{-1} is determined in the values for the desorption energies when changing the deposition method and surface deposited onto. The reason for the discrepancy has been explained to be due to the energy transmitted to the film from the atoms and molecules in the beam and the release of energy during molecular O\textsubscript{2} (and O\textsubscript{3} to a lesser extent) formation. These energies could possibly also lead amorphisation of the CSW film as explained in Chapter 3.

TPD measurements on O\textsubscript{3} were also conducted however, individual TPD traces for O\textsubscript{3} gathered from the different surfaces show very little O\textsubscript{3} desorption. The cause for this has been explained as arising from interference of O\textsubscript{2} when desorbing from the cold finger. However, a cumulative TPD trace has been constructed by addition of all the O\textsubscript{3} TPD data. This trace yielded a desorption energy of 14.7 ± 0.5 kJ mol\textsuperscript{-1} which is in good agreement with literature value of 15.2 ± 0.5 kJ mol\textsuperscript{-1} [3, 4]. Further to this, a model has been built to show the possible extent of the O\textsubscript{2}:O\textsubscript{3} being about 1:0.20 in the
presented experiments while the simulated destruction of O\textsubscript{3} has been judged as not being the reason for the lack of O\textsubscript{3} signal in the TPD experiments. Changing the experimental method to avoid the crossover signal from O\textsubscript{2} and O\textsubscript{3} desorption would show the accuracy of the ratio obtained from this model.

The O atom beam has to be fully calibrated and characterised which means placing the quadrupole mass spectrometer (QMS) in line–of–sight with the beam. Then a direct measurement of the cracking fraction can be determined by initially having a pure O\textsubscript{2} beam and then turning on the plasma source. The direct measurement of \textit{m/z} 32 and 16 will lead to a more precise O atom cracking fraction form there, the power and flux will have to be varied to find the optimum working conditions. This while monitoring the live signal from the spectrophotometer will also show any impurities in the source chamber. With an accurate, and hopefully higher cracking fraction, the same experiments as discussed in \textbf{Chapter 3} will have to be done again for comparison if the beam characteristics have changed as a result of the calibration process. With the experiments discussed in mind, an improvement in the experimental procedure will have to be implemented. This improvement has to do with the experimental TPD results and the lack of \textit{m/z} 48 signal. As O\textsubscript{3} comes into contact with the filament of the QMS, it breaks down into \textit{m/z} 32 and 16 which can naturally be monitored with the QMS. However, a discernible difference in the \textit{m/z} 32 and 16 was not measured in these experiments due to desorption of O\textsubscript{2} from the sample mount and cold finger in the same temperature region as O\textsubscript{3} desorption occurs. Therefore, attention has to be given to the applied heating ramp during a TPD experiment in the attempt to raise the sample temperature to O\textsubscript{3} desorption before O\textsubscript{2} is desorbed from the sample mount and cold finger. This was not attempted in this work due to severe time constraints, however the result of this will give much clearer indication of how much O\textsubscript{3} is formed and if there is a difference in concentration when using different substrates.

O atom bombardment would also be interesting to investigate as a function of the sample temperature. The formation of O\textsubscript{2} and O\textsubscript{3} as presented can be considered to go through a mixture of Langmuir–Hinshelwood and Eley–Rideal type mechanisms without the reaction products desorbing form the surface. Increasing the temperature to, say 30 or 35 K, would mean a multilayer of O\textsubscript{2} cannot be deposited onto SiO\textsubscript{2}, however O\textsubscript{2} binding to the most favourable sites on the surface is still possible as seen in temperature programmed desorption experiments of sub–monolayer O\textsubscript{2} [5]. As has also
been shown in this thesis, O₃ desorption occurs at temperatures of 50 – 60 K. Increasing the temperature further to a point where the cold finger allows less O₂ to adsorb will push the O₃ formation further into the domain of the Eley–Rideal type mechanism, however this will also mean O₂ is unlikely to stick to the sample at any coverage. However, the work of He et al. [6] has shown that the binding energy of O atoms on H₂O and SiO₂ surfaces is of the order of about 13 – 15 kJ mol⁻¹ respectively meaning that O could possibly still be deposited onto the sample with O₂ in the gas–phase reacting to form solid state O₃.

When a full range of experiments with the O atomic beam on SiO₂, p–ASW, c–ASW and CSW have been done, further experiments including the H atomic beam source can be conducted. Characterising the H atomic beam the same way as done for the O atomic source and then combining the experiments will lead to a new way of looking at the H₂O formation pathway in the interstellar medium. Experiments investigating H₂O formation by use of H atoms have been done previously such as hydrogenation of O [7] and O₃ [8]. However, there is still room for further experiments to be done. Such experiments could involve looking at the ‘explosive desorption’ [9, 10], which as mentioned could possibly occur when H₂ forms in the bulk or near–surface of an ice. Therefore, bombarding a p–ASW film with H atoms might eventually release H₂O into the gas–phase. H atom bombardment of H₂O films could potentially also form H₂O₂. Further to this, with the H atomic beam, reactive scattering could become possible to detect if molecules such as OH are made when bombarding an O₂ or O₃ film. Detecting molecular desorption during beam dosing is also called molecular beam modulation spectrometry and can be done with the mass spectrometer in the current position leading to specular scattering. Desorption of molecules can either be due to the surface temperature or because of released energy when molecules are formed, the latter process would be similar to an Eley–Rideal type mechanism. Such experiments can yield information about surface retention times of molecules and thus their distribution of binding energies. Further to future experiments involving the atomic beam system is the addition of beam choppers. This will allow for a continuous or pulsed atomic beam as the chopper can be mounted on a z–shift and has been designed to produce a minimum pulse time of 10 μs.

An ozoniser is also available in the laboratory which can be linked to the UHV chamber to background dose pure films of O₃. This was initially attempted in this work (however
not mentioned) and a pure O₃ gas was created, however *en route* to the central chamber O₃ decomposed to O₂. Decreasing the amount of stainless steel surfaces could lead to a lesser degree of decomposition as stated in Janssen *et al.* [11].

6.3 Chapter 4

Chapter 4 introduced the idea of H₂O de–wetting from SiO₂ surfaces at cryogenic temperatures similar to what is found in the ISM. This was investigated through reflection–absorption infrared spectroscopy and showed that the energy associated with de–wetting to be close to 2 kJ mol⁻¹. De–wetting of the 0.5 ML H₂O coverage was not observed when depositing the film as compact amorphous solid water (c–ASW) or crystalline solid water (CSW). This result with the simple simulations presented show that the isolated H₂O molecules reactively accreted or deposited from the gas phase will instantaneously form clusters of H₂O irrelevant of the typical temperatures of an interstellar dust grain. This has the effect of increasing the monolayer formation time from the previous estimate of 10⁴ years [7]. For that reason bare dust grain surface will be left exposed for other molecules such as CO to adsorb to. Binding energies differ between dust grain surfaces and H₂O surfaces and sub–monolayer coverages of molecules are generally found to have higher binding energies when adsorbed to SiO₂ as compared to H₂O as shown for O₂, CO and CO₂ [12]. All in all, bare dust grain surfaces could provide an additional reason for the difference in observed and calculated abundances of molecules such as O₂ as the grains act as molecular sinks [13, 14]. Further to this, bombarding a 0.5 ML coverage of porous amorphous solid water film with O atoms possibly leads to a c–ASW film due to network reconnections in the molecular film. This means that H₂O formed on a dust grain surface at typical dust grain temperatures of 10 K can still become compact through atom bombardment and molecular formation leading to one possible explanation for the c–ASW form of H₂O on dust grains in the ISM [15].

To further investigate the H₂O de–wetting process, a variety of experiments can be performed. For continued experiments with a SiO₂ surface, CO could be used as a probe molecule. Firstly, obtaining an IR spectrum of, say 0.5 ML, CO on bare SiO₂ will provide a base to which other experiments can be compared. CO has been determined to not de–wet from a SiO₂ surface [5]. Then, dosing 0.5 ML H₂O followed by CO (assuming that CO initially adsorbs randomly to both SiO₂ and H₂O) will potentially
lead to time–resolved spectra of CO migrating from H$_2$O to SiO$_2$. From these experiments, and keeping the sample at about 20 K, dosing an increased coverage of H$_2$O followed by CO, while comparing the CO spectra to the CO–SiO$_2$ spectra, will eventually lead to CO having to adsorb to H$_2$O at great film thicknesses. At this point the IR spectrum of CO will change due to the difference between the CO–H$_2$O and CO–SiO$_2$ interactions. The amount of H$_2$O introduced onto the sample will be an indication of de–wetting ability of H$_2$O at these cryogenic temperatures.

Changing the surface for a silicate film with metallic centres, such as Fe$^{2+}$, to approach a better model of interstellar dust grains will also have an effect on a film of H$_2$O. In theory, the H$_2$O clusters formed on a pure SiO$_2$ film can move on the surface as isolated molecules do. Adding metal centres will have the effect of anchoring these H$_2$O clusters, possibly producing several smaller clusters formed at metal centres instead of roaming larger clusters as might be expected on SiO$_2$. Keeping the temperature low should minimise H$_2$O dissociation as H$_2$O dissociation on surfaces such as FeS has been noted as only occurring at elevated temperatures of hundreds of K [16]. The same experiments can also be attempted on a highly oriented pyrolitic graphite (HOPG) surface, however sub–monolayer coverages of H$_2$O seem to wet these surfaces, exhibiting non–zero order desorption kinetics [17].

Another experiment involving both a SiO$_2$ and a graphitic surface would be to dose a sub–monolayer of D$_2$O. If D$_2$O behaves the same way as H$_2$O, then monomers and dimmers of D$_2$O at about 2400 cm$^{-1}$ [18] could be observed as the molecular film de–wets. From such observations, an activation energy can be collected and compared to that of H$_2$O.

Also, to test if a c–ASW film was actually created when bombarding the H$_2$O film with O atoms, a thicker film is needed. As O$_2$ is formed, the excess reaction energy must be dissipated somehow and when the reaction takes place on a H$_2$O film, it is likely that the energy will be transmitted into the lattice. Conducting experiments as Collings et al. [19] will give a better idea of what is happening as the O atom beam bombards the H$_2$O film. Once again, CO can be used as a probe. Deposition of CO onto bare SiO$_2$ and its subsequent TPD spectrum will be the reference for such a test. Then, the same quantity of CO desorbed from p–ASW will show a variety of signals such as CO multilayer desorption, CO desorption from ASW pores, CO desorption as H$_2$O crystallises and co–
desorption of CO with H₂O [18]. The volcano desorption of CO as H₂O crystallises will be of interest in this set of experiments. The reason for this is that dosing a film of ASW and then bombarding this film with O atoms should close the pores. Following O atom bombardment CO will be dosed onto this H₂O film which will not be able to thermally diffuse into the H₂O pores which are now sealed. For that reason a volcano desorption of CO as c–ASW becomes CSW is not expected.

6.4 Chapter 5

Chapter 5 discussed the presence of the spontaneous electric (spontelectric) field present in solid N₂O films. Experiments conducted at Aarhus University have measured a surface potential of several V in multilayer films of this dipolar molecule. Believed to be due to dipole orientation and alignment in the film, RAIRS was used to analyse this new phenomenon further. Through the observations and measurements of the longitudinal optical and transverse optical (LO–TO) splitting of N₂O multilayers, it was seen that the peaks of these features shift with temperature. As discussed in Chapter 5, changes in the LO–TO splitting can be related to the dipole alignment, as the splitting contracts with increasing temperature, the alignment decreases. This is a trait also observed for spontelectric molecules (except for methyl formate). A greater contraction of the LO–TO splitting is observed when raising the deposition temperature as compared to annealing the film to the same temperature, this is also a characteristic of spontelectric materials. A model was also built from the experimental data of N₂O. This model, built from the surface potential measurements, recreates the difference in the LO–TO splitting as the deposition temperature changes which fits the presented RAIRS data very well. Through the use of this model, the surface potential was also calculated from the RAIRS data to give about $5.7 \pm 0.3 \times 10^7$ V m⁻¹ as compared to the measured $6.3 \pm 0.3 \times 10^7$ V m⁻¹ from Aarhus University. Next, experiments involving CO on SiO₂, p–ASW, c–ASW and CSW were done to bring the spontelectric effect into the astrophysical domain. RAIRS data show that multilayers of CO behaves in a similar fashion as N₂O with respect to its LO–TO splitting and temperature dependence. Through the model built from the N₂O data, CO was shown to exhibit a surface potential with values as stated in Table 6.3.
Table 6.3: This table shows the calculated values of the spontelectric effect of CO when deposited onto SiO$_2$, p–ASW, c–ASW and CSW.

<table>
<thead>
<tr>
<th>Molecular film below CO</th>
<th>Surface potential / V m$^{-1}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>SiO$_2$</td>
<td>$3.72 \pm 0.15 \times 10^7$</td>
</tr>
<tr>
<td>p–ASW</td>
<td>$3.70 \pm 0.15 \times 10^7$</td>
</tr>
<tr>
<td>c–ASW</td>
<td>$1.99 \pm 0.15 \times 10^7$</td>
</tr>
<tr>
<td>CSW</td>
<td>$2.83 \pm 0.15 \times 10^7$</td>
</tr>
</tbody>
</table>

Such a surface potential of CO has further been shown to create positive charges (a total of 5.75 on average with 12 ML) on an interstellar dust grain in dark molecular clouds. These charges build up as the CO layers accrete on the surface and acts in a way to attract electrons from the gas phase. As electrons are attracted so, in turn, will positive ions, thereby dragging charge out of the cloud environment.

To continue the study of spotelectrics with RAIRS will need to include working with methyl formate. As has been shown in Chapter 5, crystalline states of matter have more clearly defined IR features. Methyl formate crystallises at about 100 K and appears to have IR peaks splitting into two distinct features [20] which could be the LO–TO splitting. However, the spotelectric state of methyl formate is unstable at temperatures about 90 K as shown in Figure 6.1 [21, 22].

![Figure 6.1: This figure shows the surface potential measurements of methyl formate as the temperature increases. As can be seen, methyl formate behaves as a typical spotelectric material initially before changing behaviour at about 70 – 80 K. Above this temperature the surface potential increases along with the temperature until the Curie point is reached at about 90 K [21, 22].](image)
Figure 6.1 displays the behaviour of the surface potential as the deposition temperature is increased. Initially, the spontelectric effect decreases with increasing temperature as expected of a typical spontelectric material like N₂O. Then, an increase in the surface potential is observed until the field stops at the Curie point of about 90 K. If IR features are clean and defined enough, RAIRS spectra can possibly still be used to investigate the peculiar spontelectric behaviour of methyl formate in its amorphous state. Further to this, since methyl formate is no longer spontelectric at temperature above 100 K, the crystalline film will need to be investigated with respect to its LO–TO splitting. The reason for this is (as written in Chapter 5) that there should be no change in the splitting with temperature when the spontelectric effect is not present. The only cause for the splitting in methyl formate above 100 K should in theory be due to the intrinsic Berreman effect. This in itself would be a confirmation of using RAIRS to indirectly determine the spontelectric effect of dipolar molecules. A similar test would be to investigate a molecule without a permanent dipole moment which still exhibits an LO–TO splitting, such a molecule could be CO₂ [23]. The LO–TO splitting should behave in the same manner as crystalline methyl formate with respect to temperature.

Further work in the field of the spontelectric effect on the presented experimental equipment will involve the use of a Kelvin probe. As already mentioned, Bu et al. [24] have investigated p–ASW films and determined that a possible electric field is present. When fitted to the chamber initial test of the probe will be done by investigating a multilayer amount of N₂O and methyl formate. Hopefully, obtaining results similar to the ones reported from Aarhus University will lead to another way of directly investigating the spontelectric effect. Once this is done and assuming the Kelvin probe can be used as desired, tests of CO will be done to provide a more definite. Another method of indirectly investigating the spontelectric effect has been presented recently. Instead of using IR spectroscopy, vacuum ultraviolet (VUV) spectroscopy of CO films has shown similarities in UV band shifts with increasing temperature [25]. Future work in the area of VUV spectroscopy should therefore include studies of N₂O as shown in this thesis. If similar results are gathered for these VUV experiments, then spontelectric parameters could be presented and compared to the direct measurement of the surface potential and the indirectly determined values as obtained through RAIRS.
6.5 References


216